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Power management Guide



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Introduction



More than 30 years of technology innovation in power management directly resulting in value creation for our customers, from products to system solutions

When designing a power management system or sub-system, regardless of whether it is an energy generation or distribution system, a power supply or a LED driving circuit, an industrial SMPS or an electric vehicle power application, it must provide high efficiency and low standby power, as well as high power density, reliability and safety, while respecting specific cost constraints.

The key enablers for any such system are discrete and integrated power semiconductors, which play a crucial role in every step along the energy supply chain and, when applied in conjunction with advanced control technologies, can drive continuous improvement in energy savings for homeowners and communities, and ultimately for the entire planet.

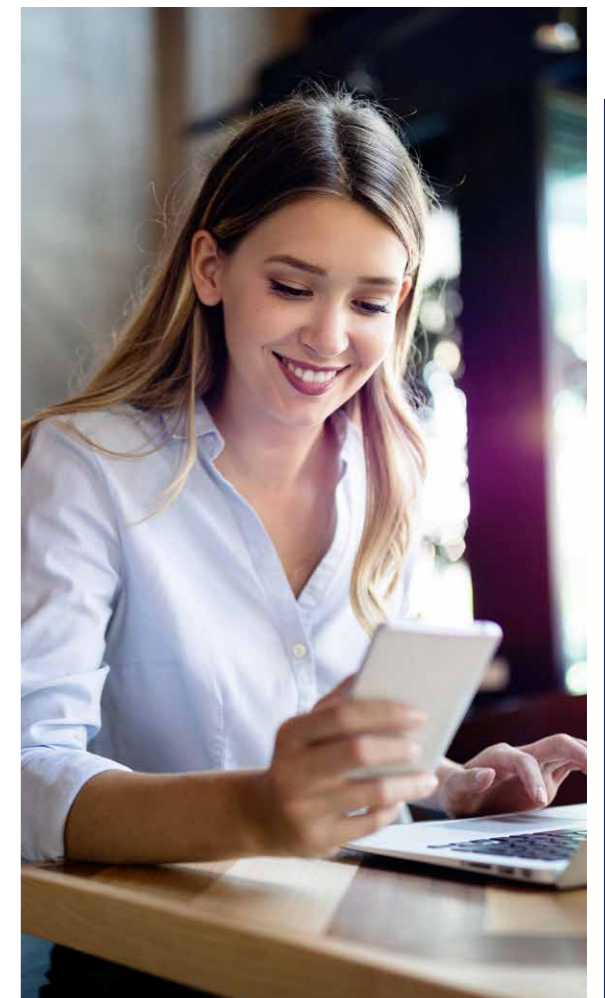
The technological innovation, which persists at the core of ST strategy for more than 30 years, is the reason why ST today can offer an extensive range of cutting-edge products for power and energy management. ST portfolio includes higher-efficiency power technologies such as:

- Silicon carbide power discretes
- GaN Power ICs
- HV and LV power MOSFET and IGBTs
- Customized power modules
- Diodes and Thyristors
- Protection devices and Filters
- AC-DC converters and controllers
- DC-DC converters
- Linear voltage regulators
- Analog ICs
- Battery management ICs
- STM32 microcontrollers
- MOSFET and IGBT gate drivers

Moreover, ST offers a variety of wireless and wired connectivity ICs as well as high-performance sensors to complement the latest smart power electronics applications with additional sensor-driven features and monitoring functions.

ST is also committed to the development of GaN power devices, which represent a major step forward in power electronics by providing high-frequency operation with increased efficiency and higher power density than silicon-based transistors.

Additionally, we provide a comprehensive range of reference designs and hardware and software evaluation and development tools, including the eDesignSuite tool that helps engineers design and optimize their high-efficiency power solutions.



Applications

ENERGY GENERATION AND DISTRIBUTION

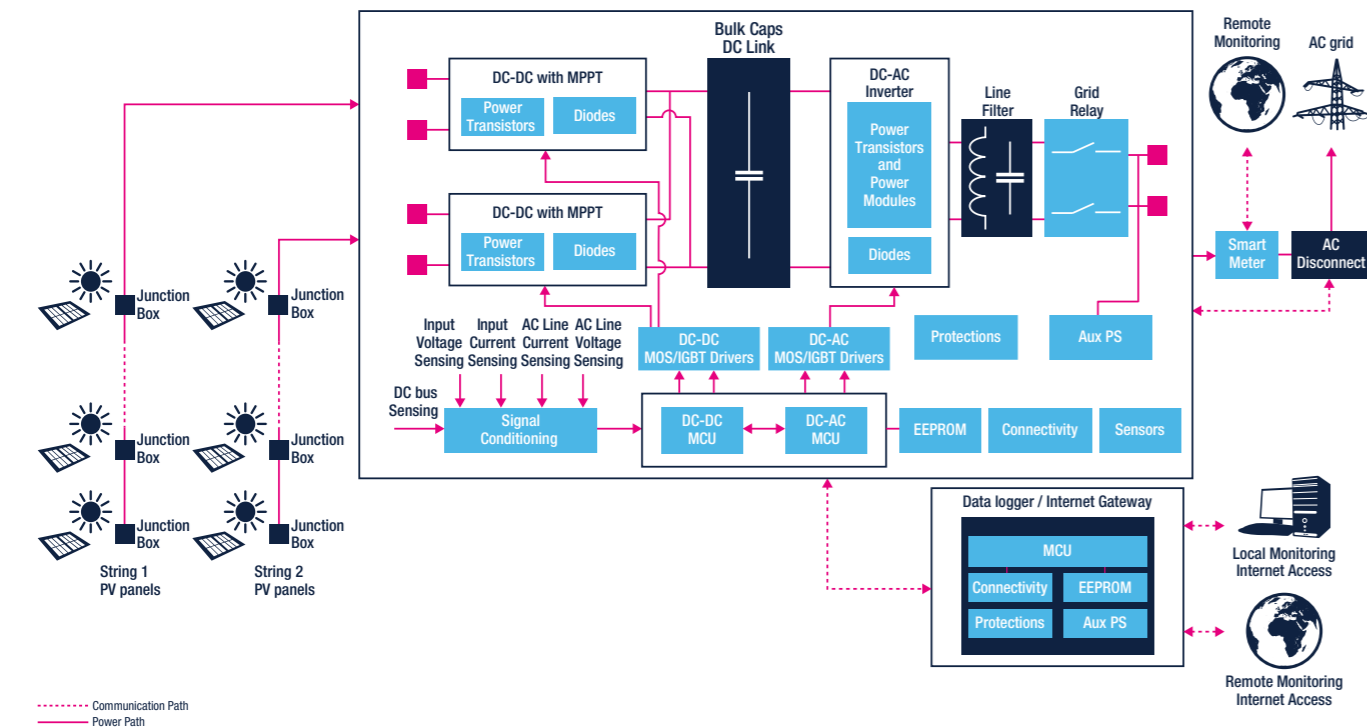
Solar Centralized Generation - Solar Inverters (String and Central)

String and central inverters are the most common power conversion systems used for grid-connected solar applications. They comprise a DC-DC conversion stage to adapt voltage levels and implement the Maximum Power Point tracking (MPPT) function to maximize energy transfer from the panel, and a DC-AC conversion stage to correctly shape current and voltage waveforms transferred to the AC grid. The inverter has an anti-islanding function that guarantees safety in case of AC disconnection. With power ranging from a few kilowatts for string and multi-string inverters to tens or hundreds of kilowatts for central inverter solutions, the trend is to use topologies with very high input voltages (up to 1500 V).

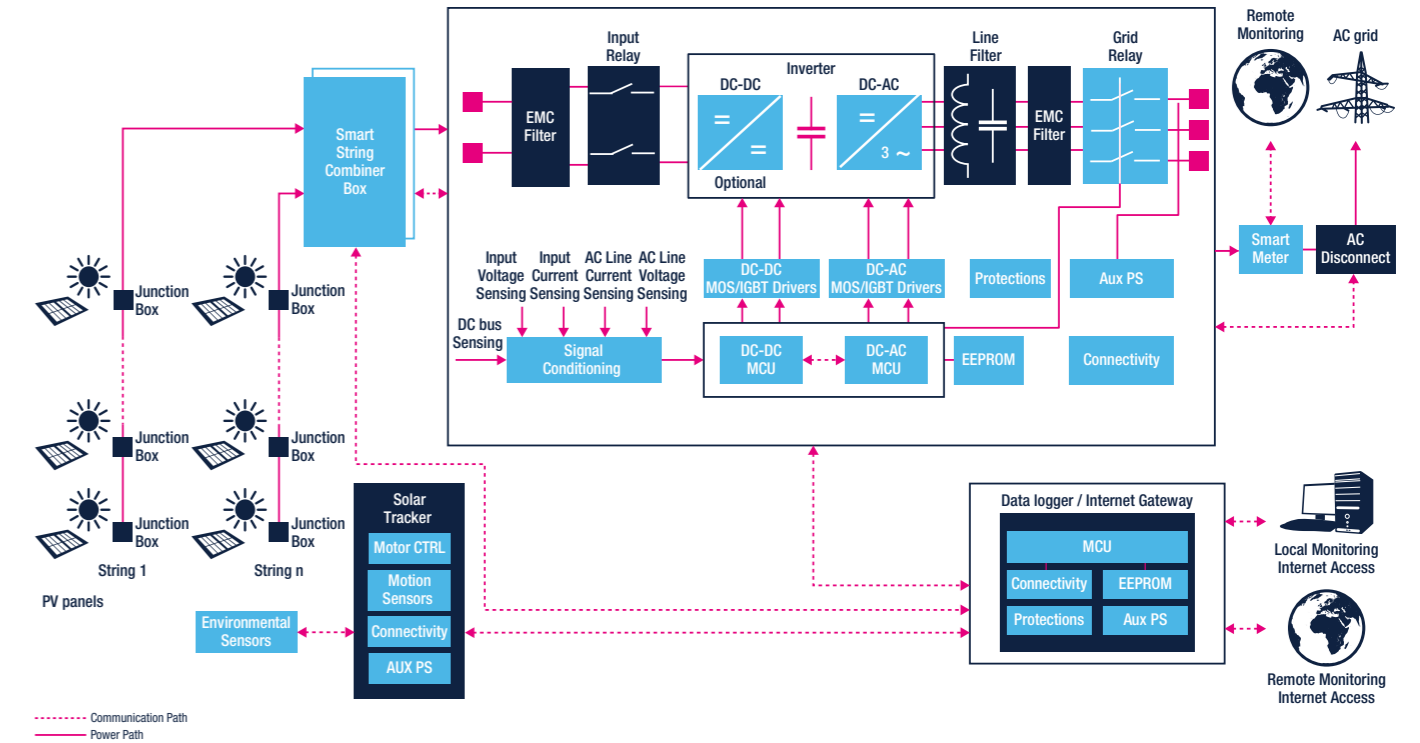


We offer a broad range of silicon-carbide (SiC) power MOSFETs - with the industry's highest operating junction temperature of 200°C - and trench-gate field-stop IGBTs, which are also integrated in our high-efficiency ACEPACK power modules. Together with galvanically-isolated gate drivers and high-performance STM32 microcontrollers, our solutions enable engineers to design high-efficiency string and central inverters. In addition, we have a range of wireless and wired connectivity solutions.

Typical Block Diagram for String Inverter



Typical Block Diagram for Central Inverter



ST product offering for String and Central Solar Inverter

	Power MOSFETs	IGBTs	Power Modules	Diodes & Discretes
Inverter Power Stage DC-DC and DC-AC	600 V MDmesh DM9 ST*60N*DM9 600 V-650 V MDmesh DM6 ST*60DM6, ST*65DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 V MDmesh M9 ST*65N*M9 650 V MDmesh M5 ST*65M5 1200 V MDmesh K5 ST*N120K5 650 V - 1200V - 1700V SiC MOSFETs SCT*65G3AG, SCT*N65G2, SCT*120G3AG, SCT*N120G2, SCT*N120, SCT*N170	600 V V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2 1200 V H series STG*H120DF2 1200 V M series STG*M120DF3	ACEPACK Power Modules A1P50S65M2 A1P25S12M3 A1P35S12M3 A2P75S12M3 A2F12M12W2-F1 A1F25M12W2-F1 A2U12M12W2-F2 Thyristors SCRs Thyristors SCRs for Grid Relay TN6050HP-12WY, TM8050H-8W	600 V Ultrafast STTH*06 STTH*R06 1200 V Ultrafast STTH*12 100 V Power Schottky STPS*100 SiC Diodes STPSC*065 STPSC*H12 TVS for Power MOSFET & IGBT Protection SMA4F, SMA6F, SMB15F series
Inverter Driving & Control stage	MCUs STM32F334 STM32G4 STM32H7 STM32F3 STM32F4 STM32F7	MOSFET and IGBT Gate Drivers HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* Multiple LS Gate Drivers PM8834 LDO L78xx, LD1117, LD39200, ST730/2 DC-DC L6983, L6982, L6981	Protections TVS for Power Rail Surge Protection SMAJ, SM6T, SM15T, SMC30J series ESD and High Speed Port series for Ethernet and USB Protection	Connectivity Zigbee, Thread STM32WB Bluetooth Low Energy BlueNRG, STM32WB Power Line Transceivers ST8500, ST7580 RS-422 and RS-485 ST3485*, STR485* Isolated Interfaces for wired connectivity STIS062x
Data Logger/Internet Gateway	MCUs STM32F0 STM32G0 STM32F1 STM32F3	EEPROM Standard Serial EEPROM	Protections ESD and High Speed Port series for Ethernet and USB Protection	Isolated Interfaces for wired connectivity STIS062x
Solar Tracker	Motor CTRL 3-phase Field Oriented Control (FOC)	Motion Sensors Accelerometer IIS3DHH, IIS2DH, IIS2ICLX Magnetometer-IIS2MDC eCompass-ISM303DAC 6 axis IMU-ISM330DLC, ISM330DHCX	Environmental Sensors Pressure - LPS22HH Pressure water proof - LPS33W Temperature - STTS22H Humidity - HTS221	Connectivity Bluetooth Low Energy BlueNRG, STM32WB

Note: * is used as a wildcard character for related part number

1 samples available in Q4 2022

Solar Distributed Generation - Microinverter

In residential photovoltaic systems, Microinverters are often used as an alternative to string inverters to perform DC to AC power conversion at the panel level, helping maximize energy yield and mitigate problems related to partial shading, dirt, or single panel failures. A microinverter consists of a DC-DC converter implementing maximum power point tracking MPPT, and a DC-AC inverter to shape current and voltage for injection into the AC grid. Data (including voltage, current and power generated) from all the microinverters in the installation are collected by a concentrator and dispatched to a local or remote monitoring and control access point.

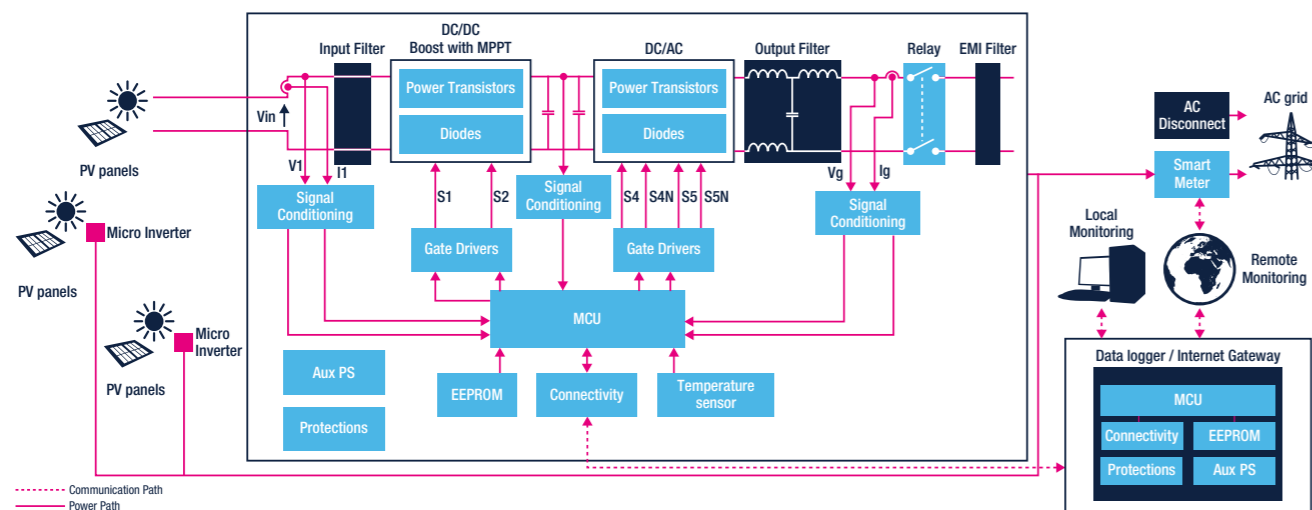
Our solution includes MDmesh and STripFET power MOSFETs, high-voltage, galvanically isolated gate drivers, high-voltage silicon carbide (SiC) diodes, together with high-performance STM32 microcontrollers featuring dedicated peripherals to help implement complex power conversion control algorithms. A range of wireless and wired connectivity solutions including multi-standard power line modems complete the solution.

ST product offering for Microinverter

	Power MOSFETs	Diodes	Protections	Signal Conditioning
Microinverter Power Stage	60 V-100 V STripFET F7 ST*N6F7, ST*N8F7, ST*N10F7 600 V MDmesh DM9 ST*60N*DM9 600 V-650 V MDmesh DM6 ST*60DM6, ST*65DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 V MDmesh M9 ST*65N*M9 600 V MDmesh M6 ST*60M6 650 V MDmesh M5 ST*65M5 800 V MDmesh K6 ST*80*K6 800 V-900 V MDmesh K5 ST*80K5, ST*90K5 650 V SiC MOSFETs SCT*65G3AG, SCT*N65G2	600 V Ultrafast STTH*R06 1200 V Ultrafast STTH*S12 100 V Power Schottky STPS*100 SiC Diodes STPSC*065 STPSC*H12	TVS for Power MOSFET and Power Rail Surge Protection SMAJ, SM6T, SM15T series Thyristors SCRs & Triacs Thyristors SCRs & Triacs for Grid Relay TN815-800B, TN1515-600B, T1635H-8G, T2550-12G	Precision Op Amps (<50 MHz) TSZ*, TSV*, TS9*, LMV* Current Sensing TSC*
	MCUs	MOSFET and IGBT Gate Drivers	Sensors	EEPROM
Microinverter Driving & Control stage	STM32F334 STM32G4 STM32H7 STM32F3 STM32F4 STM32F7	HV HB Gate Drivers L638*, L639*, L649* Isolated Gate Drivers STGAP* Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1	Pressure - LPS22HH Pressure water proof - LPS33W Temperature - STTS22H Humidity - HTS221 Protections TVS for Power Rail Surge Protection SMAJ, SM6T, SM15T, SMC30J series	Standard Serial EEPROM Connectivity Zigbee, Thread STM32WB ¹ Bluetooth Low Energy BlueNRG, STM32WB Power Line Transceivers ST8500, ST7580
	MCUs	EEPROM	Protections	Protections
Data Logger/Internet Gateway	STM32F0 STM32G0	Standard Serial EEPROM	ESD and High Speed Port (HSP) series for Dataline ESD and EOS Protection	Isolated Interfaces for wired connectivity STIS062x

Note: * is used as a wildcard character for related part number 1 for Data Logger/Internet Gateway only

Typical Block Diagram



Solar Distributed Generation - Power Optimizer

In architectures based on the use of power optimizers, the maximum power point tracking (MPPT) function is performed at the level of photovoltaic panels, individually operating each one at its optimal I-V point which ensures maximum power generation. This results in an improved energy yield of the overall solar system compared to traditional string or central inverter based architectures.

Power optimizers can help minimize system design constraints as well as improve reliability and safety by helping ensure compliance with the latest NEC 2017 regulations that require rapid shut-down in the event of grid disconnection, while reducing maintenance costs.

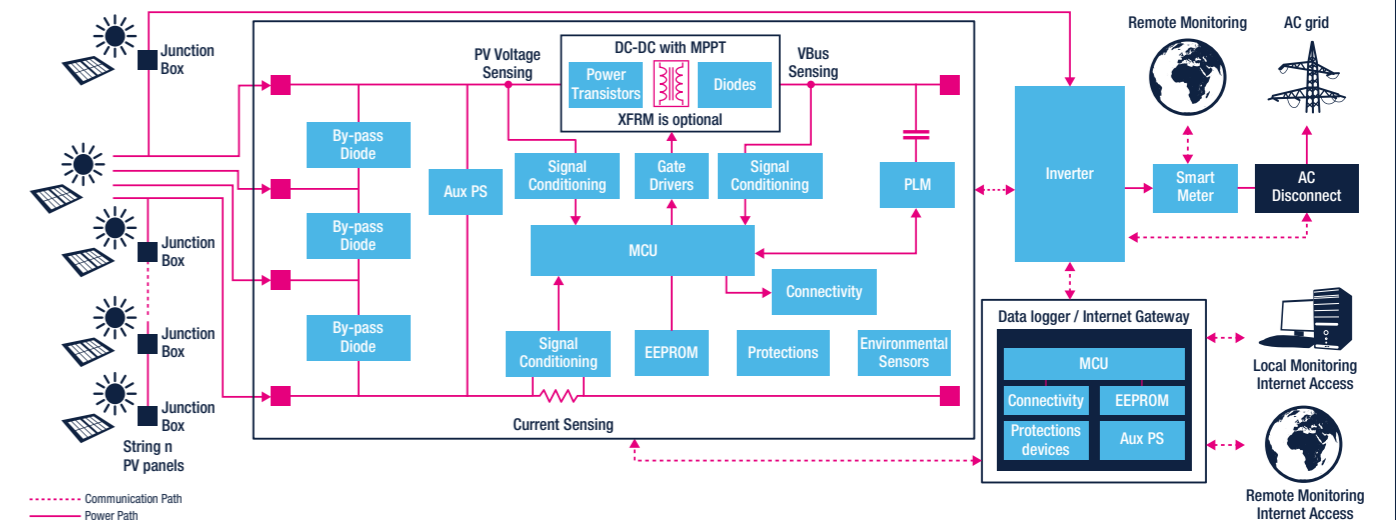
We provide high-performance STM32 microcontrollers and high-efficiency STripFET F7 LV Power MOSFETs, Diodes, SiC MOSFETs and trench gate field-stop IGBTs, galvanically-isolated gate drivers, and power line communication solutions to help achieve superior efficiency and reliability for power optimizer based architectures.

ST product offering for Power Optimizer

	MCUs	Power MOSFETs	Gate Drivers	By Pass Diodes	Diodes	Protections	Signal Conditioning
Power Optimizer	STM32F334 STM32F0 STM32G0 STM32F3 STM32G4	60 V to 100 V STripFET F7 ST*N6F7 ST*N8F7 ST*N10F7	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP*	30 V to 45 V Power Schottky STPS*30 STPS*45 45 V FERD FERD*45	100 V to 200 V Power Schottky STPS*100 STPS*200 100 V FERD FERD*100	TVS for Power MOSFET & IGBT Protection SMAJ, SM6T, SM15T, SMC30J series	Precision Op Amps (<50 MHz) TSZ*, TSV*, TS9*, LMV* Current Sensing TSC*
	MCUs	Power MOSFETs	IGBTs	Diodes	Protections	Signal Conditioning	
Inverter	STM32F334 STM32G4 STM32H7 STM32F3 STM32F4 STM32F7	650 V - 1200V SiC MOSFETs SCT*65G3AG SCT*N65G2 SCT*120G3AG SCT*N120G2 SCT*N120	Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1	600 V V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2 1200 V H series STG*H120DF2 1200 V M series STG*M120DF3	600 V Ultrafast STTH*R06 SiC Diodes STPSC*065 STPSC*H12	TVS for Power Rail Surge Protection SMAJ, SM6T, SM15T, SMC30J series ESD Protection for I/O interfaces	Zigbee, Thread STM32WB ¹ Bluetooth Low Energy BlueNRG STM32WB Power Line Transceivers ST8500, ST7580 Isolated Interfaces for wired connectivity STIS062x
	MCUs	EEPROM	Protections	Protections	Signal Conditioning		
Data Logger/Internet Gateway	STM32F0 STM32G0	Standard Serial EEPROM	ESD and High Speed Port series for Dataline ESD and EOS Protection	ESD and High Speed Port series for Dataline ESD and EOS Protection	ESD and High Speed Port series for Dataline ESD and EOS Protection	ESD and High Speed Port series for Dataline ESD and EOS Protection	ESD and High Speed Port series for Dataline ESD and EOS Protection

Note: * is used as a wildcard character for related part number 1 for Data Logger/Internet Gateway only

Typical Block Diagram



Energy Distribution - Home & Commercial Battery Storage Systems

The adoption of energy storage devices, whose reserve capacity can be used for balancing purposes, peak-load shaving, or to shift loads, is increasingly widespread in energy distribution networks.

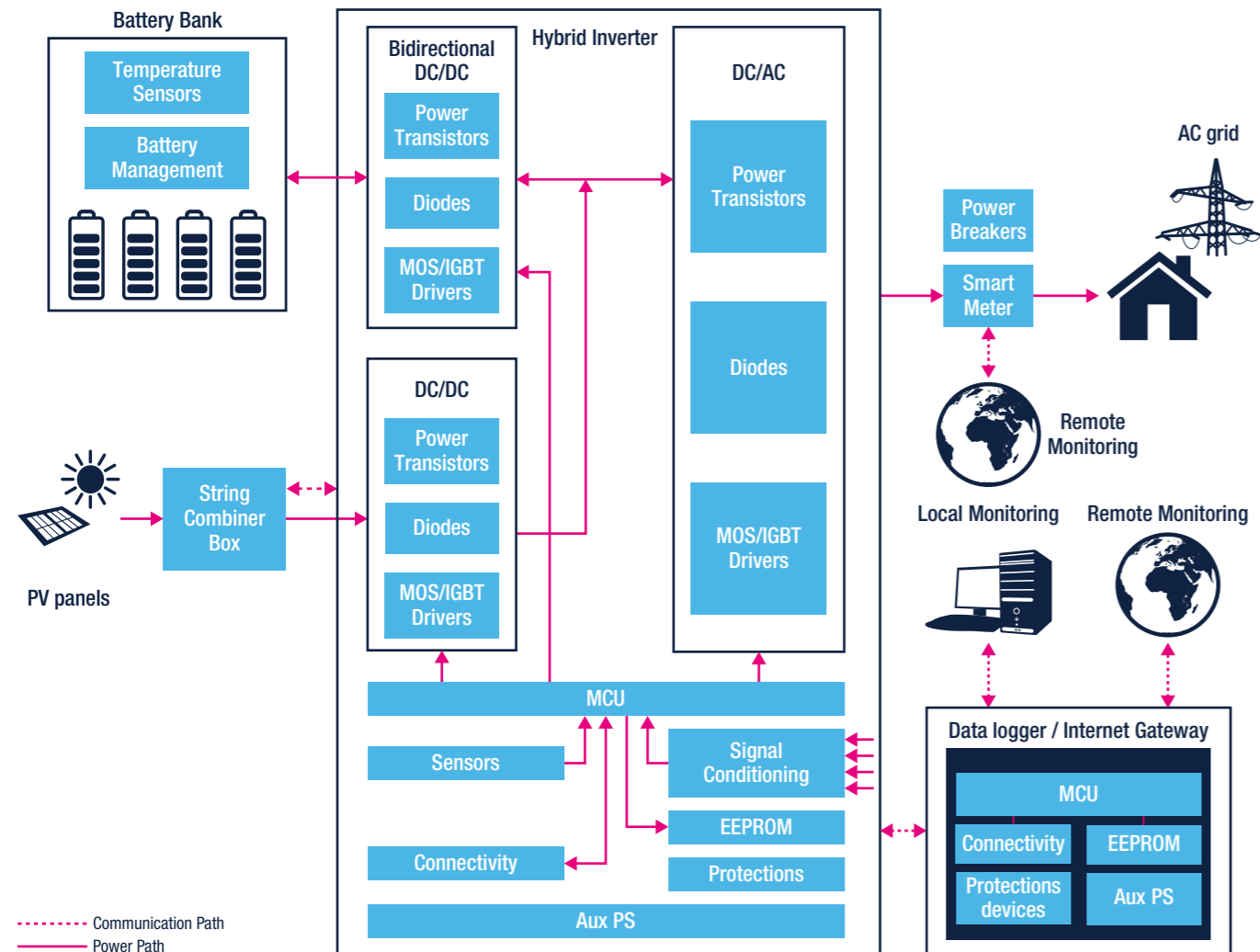
Two use cases are particularly important: in residential or commercial buildings to help reduce consumer electricity bills by reducing energy consumption from the grid during peak hours, and to help avoid problems with stability and voltage drop associated with the fast-charging requirements of an increasing number of electric vehicles (EV).

By interacting with the grid, batteries, and potentially solar panels, power converters at the heart of these systems must operate with high-efficiency and superior reliability over time.

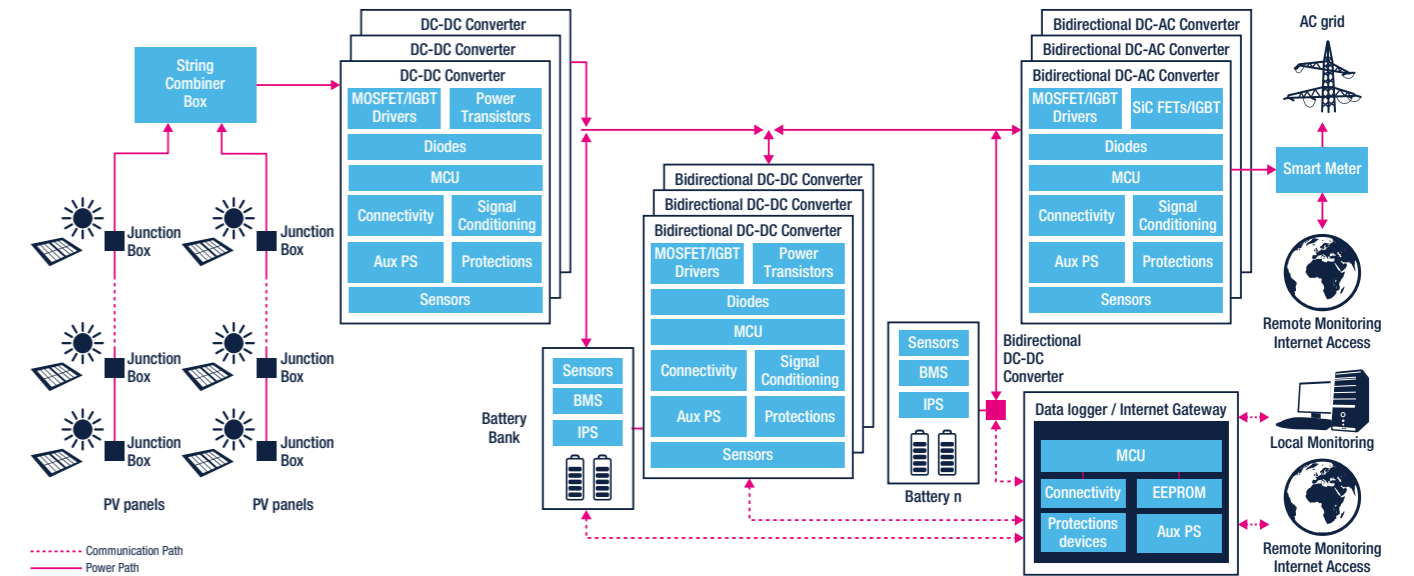
We provide a range of power discretes, including silicon carbide (SiC) and silicon power transistors, ACEPACK power modules, silicon carbide and silicon diodes, isolated gate drivers and high-performance STM32 microcontrollers, as well as energy metering ICs for high-efficiency commercial battery storage systems.



Typical Block Diagram - Home Battery Storage System



Typical Block Diagram - Commercial Battery Storage System



ST product offering for Home & Commercial Battery Storage Systems

	Power MOSFETs	IGBTs	Power Modules	MOSFET and IGBT Gate Drivers	Diodes & Discretes
DC-DC Converter & Bidirectional DC-DC Converter	40 V-100 V STripFET F7 ¹ ST*N4F7, ST*N6F7, ST*N8F7, ST*N10F7		ACEPACK Power Modules A1P50S65M2 A1P25S12M3 A1P35S12M3 A2P75S12M3	HV HB Gate Drivers L649*	600 V Ultrafast STTH*06 STTH*R06
Power Stage	600 V MDmesh DM9 ST*60N*DM9		A2F12M12W2-F1 A1F25M12W2-F1 ³ A2U12M12W2F1	Isolated Gate Drivers STGAP*	800 V to 1200 V Ultrafast STTH*08 STTH*10 STTH*12
DC-AC Converter	600 V-650 V MDmesh DM6 ST*60DM6, ST*65DM6	600 V V series STG*V60DF	Thyristors SCRs	Multiple LS Gate Drivers PM8834	SiC Diodes STPSC*065 STPSC*H12
Power Stage	600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2	650 V HB series STG*H65DFB	Thyristors SCRs for Power Breakers TS110-8 X0115	Single LS Gate Drivers PM88*1	TVS for Power MOSFET & IGBT Protection and for Power Rail Surge Protection SMA4F, SMA6F, SMB15F, series
	650 V MDmesh M9 ST*65N*M9	650 V HB2 series STG*H65DFB2			
	600 V-650 V MDmesh M6 ST*60M6, ST*65M6	650 V M series STG*M65DF2		LDO	
	800 V MDmesh K6 ST*80*K6	1200 V H series STG*H120DF2		LD1117xx, ST730/2, L78xx	
	800 V to 1200 V MDmesh K5 ST*80K5, ST*9*K5 ST*105K5, ST*120K5	1200 V M series STG*M120DF3		DC-DC Converters	
	650 V to 1700V SiC MOSFETs SCT*65G3AG, , SCT*N65G2, SCT*120G3AG, SCT*N120G2, SCT*N120, SCT*N170			L6983, L6982, L6981	
		Signal Conditioning	EEPROM	Sensors	Connectivity
System Control Stage	MCUs STM32F334 STM32G4 STM32H7 STM32F3 STM32F4 STM32F7	Precision Op Amps (<50 MHz) TS2*, TSV*, TS9*, LMV* Current Sensing TSC*	Standard Serial EEPROM	Pressure - LPS22HH Pressure water proof - LPS33W Temperature - STTS22H Humidity - HTS221	Power Line Transceivers ST8500, ST7580 RS-485 and RS-232 STR485*, ST3232*
			Protections	BMS	Isolated Interfaces for wired connectivity STIS062x
			TVS for Power Rail Surge Protection SMAJ, SM6T, SM15T and ESD series	L9961, L9963E, L9963T	
				IPS	
				IPS2050H, IPS2050H-32, IPS1025H, IPS1025H-32, IPS4260L	
Data Logger / Internet Gateway	MCUs STM32F0 STM32G0 STM32F1 STM32F3	ESD and High Speed Port series for Dataline ESD and EOS Protection	Standard Serial EEPROM	Connectivity Power Line Transceivers ST8500, ST7580 Bluetooth Low Energy BlueNRG, STM32WB RS-485 and RS-232 STR485*, ST3232* Sub-1GHz RF Transceivers ² S2-LP, SPIRIT1 Sub-1GHz Wireless MCU ² STM32WL Zigbee, Thread, STM32WB Isolated Interfaces for wired connectivity STIS062x	

Note: * is used as a wildcard character for related part number 1 only for bidirectional dc-dc converter 2 only for commercial battery storage systems 3 samples available in Q4 2022

POWER SUPPLIES

Auxiliary SMPS

Appliances and equipment often require a switch-mode power supply (SMPS) that works separately from the main power supply to support auxiliary functions like standby operation. Power ratings can vary from a few watts to tens of watts for these auxiliary supplies, which can be either isolated or non-isolated. To ensure good performance, engineers must choose the power topology including fixed frequency or quasi-resonant flyback, that best meets the efficiency, size, safety, and cost requirements. ST offers a wide portfolio of highly-integrated high-voltage converters for applications up to 100 W, with an extremely low total standby consumption (down to less than 4 mW) and breakdown voltages as high as 1050 V. In addition to PWM switching controllers, power MOSFETs, and diodes, we offer an extensive set of evaluation and development tools, as well as reference designs to help engineers develop high-efficiency and compact auxiliary power supply solutions.

Isolated Auxiliary SMPS

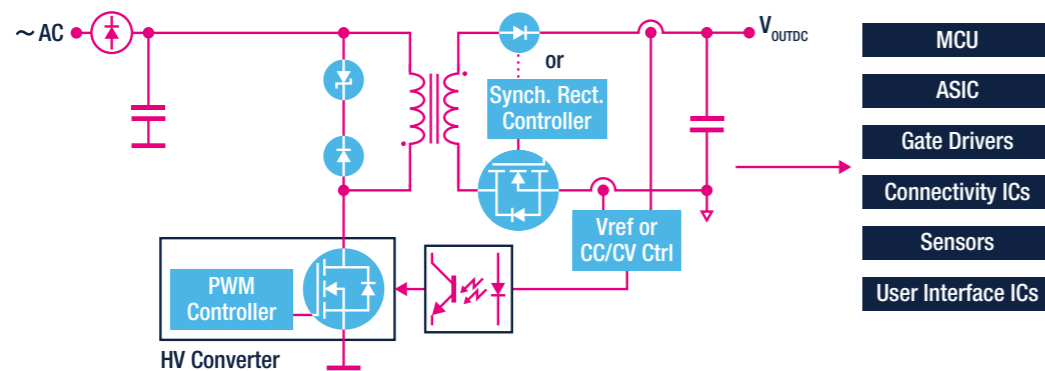
ST helps the designers of high-power-density and cost-effective isolated auxiliary power supplies with higher switching frequency solutions to minimize transformer and output capacitor size. In the 20 to 100 W power range, the need to meet increasingly tight efficiency and standby requirements for auxiliary power supplies has pushed the use of quasi-resonant topologies in place of more mainstream fixed-frequency-based designs. The power stage is managed by a high-voltage converter.

ST recommended products for Isolated Auxiliary SMPS

	HV converters	Offline controllers	HV Power MOSFETs	MOSFET Protection	Voltage Ref CC/CV Ctrl	Output diodes	Synch Rect	LDO
Isolated flyback	PSR-CV	VIPer*5 VIPer*7 VIPer*8 VIPerGaN50 VIPerGaN65 VIPerGaN100	VIPerOP VIPer*1 VIPer*6 VIPer122 VIPer222 ALTAIR*	HVLED001*	Power MOSFET Protection SMAJ, SM6T, SM15T series Reverse blocking diodes 600 V Ultrafast STTH*06 800 V to 1200 V Ultrafast STTH*08 STTH*10 STTH*12	Schottky, FERD STPS* FERD*45 FERD*50 FERD*60 FER*100	SR Controllers SRK1000*, SRK1001 LV Power MOSFETs 40 V-100 V STripFET F7 ST*N4F7, ST*N6F7, ST*N8F7, ST*N10F7	Low Dropout (LDO) Linear Regulators LDF, LDFM, LDK220, LDK320, LDL212, ST730, ST732
				STCH03 L6566B L6566BH L6565				

Note: * is used as a wildcard character for related part number

Typical configuration for Isolated Auxiliary Power Supply up to 100 W



Main application boards and reference designs



STEVAL-VP26K01F
Three outputs, isolated SSR flyback converter with extended input voltage range for Smart Meter and Power Line Communication



STEVAL-VP318L1F
15 V/1.2 A Isolated SSR Flyback converter



EVAL-STCH03-45W
45 W/12 V QR flyback with adaptive synchronous rectification



EVLVIPGAN50FL
15 V - 50 W QR flyback

Non-Isolated Auxiliary SMPS

In a number of applications, the reference of the secondary circuit is connected to the same reference as the primary; that is, the AC mains. In such cases, an off-line non-isolated auxiliary power supply can be used to provide a regulated DC voltage using an inductor or low-cost transformer, with simplified isolation, as an energy transfer element by modulating the power supply's duty-cycle.

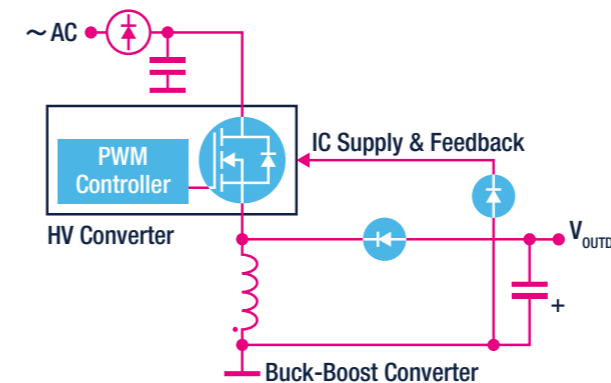
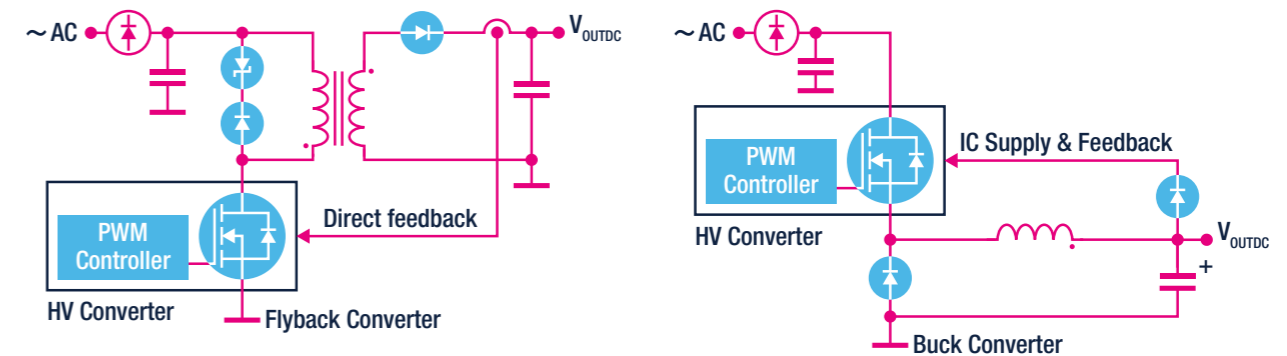
A buck (step-down) topology can be used to generate a positive output with respect to the common terminal and a buck-boost when the output voltage needs to be negative. A non-isolated flyback converter is the alternative when a higher output power is required.

ST recommended products for Non-Isolated Auxiliary SMPS

	HV converters	VIPer Protection	Reverse blocking diodes	Output diodes	LDO
Buck	VIPerOP VIPer*1 VIPer*6 VIPer122 VIPer222	SMAJ, SM6T, SM15T series	600 V Ultrafast STTH*06 800 V to 1200 V Ultrafast STTH*08 STTH*10	600 V Ultrafast STTH*06	Low Dropout (LDO) Linear Regulators LDF, LDFM, LDK220, LDK320, LDL212, ST730, ST732
Buck-boost				Schottky, FERD STPS* FERD*45, FERD*50, FERD*60, FER*100	
Non-isolated flyback				600 V Ultrafast STTH*06 800 V to 1200 V Ultrafast STTH*08 STTH*10 STTH*12	

Note: * is used as a wildcard character for related part number

Typical configurations for Non-Isolated Auxiliary Power Supply



Main application boards



STEVAL-VP12201B
15 V/200 mA buck converter



STEVAL-VP319X1B
5 V/600 mA buck converter



STEVAL-VP22201B
5 V/0.36 A buck converter



STEVAL-ISA196V1
5 V/1.2 A non-isolated flyback converter

Smart Chargers and Adapters

USB Type-C® PD Adapters and Quick Chargers

The new slim and reversible USB Type-C connector with USB Power Delivery (PD) feature provides up to 240 W (48 V, 5 A) enabling a faster and more efficient charging solution.

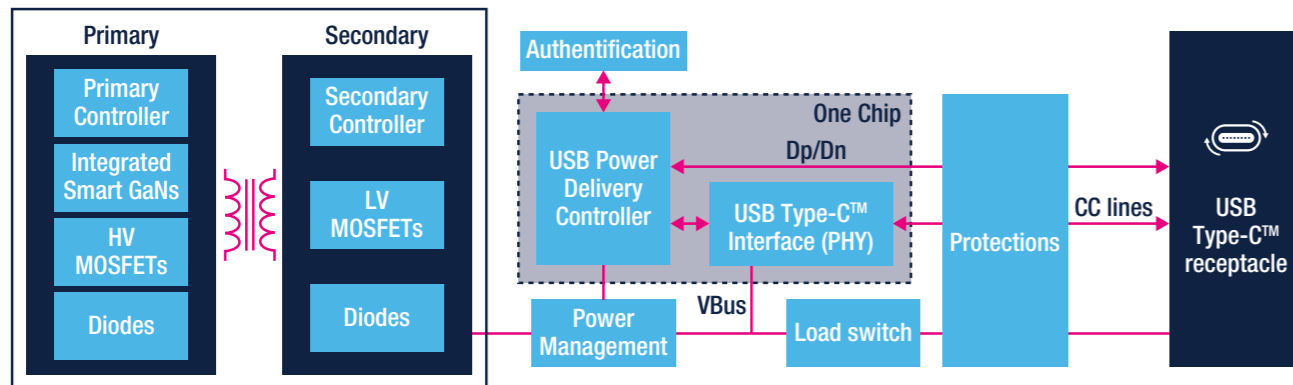
Designers of USB Type-C and Power Delivery compliant adapters and wall chargers can benefit from the ST-ONE, the world's most integrated digital controller, the MasterGaN series, an advanced power system-in package integrating a gate driver and two e-mode GaN transistors in half-bridge configuration, from standalone controllers, from STM32 microcontrollers and their associated protocol stack, as well as a specifically developed range of protection devices. Customers can also choose from the VIPerGaN series, which can provide up to 100 W power. The VIPerGaN HV converter series embeds an innovative and advanced quasi resonant PWM controller and a 650 V HEMT GaN-FET with highly efficient performance.

ST recommended products for USB Type-C Power Delivery Smart Chargers and Adapters

Power Stage Primary Side				Power Stage Secondary Side				
Primary Controller	Integrated Smart GaNs	HV MOSFET	Diodes	Fully integrated controller	Secondary Controller	LV MOSFET	Diodes	
PFC L656* Isolation Stage VIPerGaN50 VIPerGaN65 VIPerGaN100 STCH03 L6599*,L6699	MASTERGAN1 MASTERGAN2 MASTERGAN3 MASTERGAN4 MASTERGAN5	600 V-650 V MDmesh M6 ST*60M6, ST*65M6 650 V MDmesh M9 ST*65N*M9 650 V MDmesh M5 ST*65M5	600 V Ultrafast for TM STTH*L06, STTH*06	ST-ONE	SR Analog Controllers SRK1000, SRK1001 for Flyback SRK2000A, SRK2001, SRK2001A for LLC	100 V STRipFET F7 ST*N10F7	Output Diodes for Flyback Schottky STPS*, FERD FERD*45, FERD*50, FERD*60, FERD*100 Output Diodes for LLC Schottky STPS*, FERD FERD*45, FERD*50, FERD*60, FERD*100	
Type-C and USB-PD Controllers				Protections				
Programmable Solutions				V _{rm}	High surge current compact protection (V _{BUS})	Single and multi lines protection for MCUs Communication Channel (CC) and Side Band Use (SBU)	Type C Port protection Over voltage protection for USB-C and PD 3.0 controllers	LDO/ DC-DC
Fully integrated controller	MCUs	Type-C Controller/ interface	Standalone Solutions					
ST-ONE	STM32G0, STM32G4, STM32L5	STUSB1602A	STUSB1600 STUSB1700 STUSB4500L STUSB4500 STUSB4700 STUSB4710 STUSB4761	20 V	ESDA25P35-1U1M ESDA24P140-1U3M	ESDL20-1BF4 ESDA25W	TCPP01-M12 TCPP02-M18 TCPP03-M20	STPD01 ST715 LDK320 ST730/2
	STM32F0 STM32F3		15 V	ESDA17P100-1U2M ESDA15P50-1U1M	ESDA17P20-1U1M	Load Switch		
			9 V	ESDA13P70-1U1M	ESDA6V1L ESD051-1F4			STELPD01
			5 V	ESDA7P120-1U1M				

Note: * is used as a wildcard character for related part number

Typical configuration



Main application boards and reference designs



EVALMASTERGAN*
High power density half-bridge high voltage driver with two 650 V enhanced mode GaN HEMT



EVLONE65W
65 W USB Type-C Power Delivery reference design with integrated GaN



EVLVIPGAN65PD
65 W ACF USB PD adapter reference design with GaN

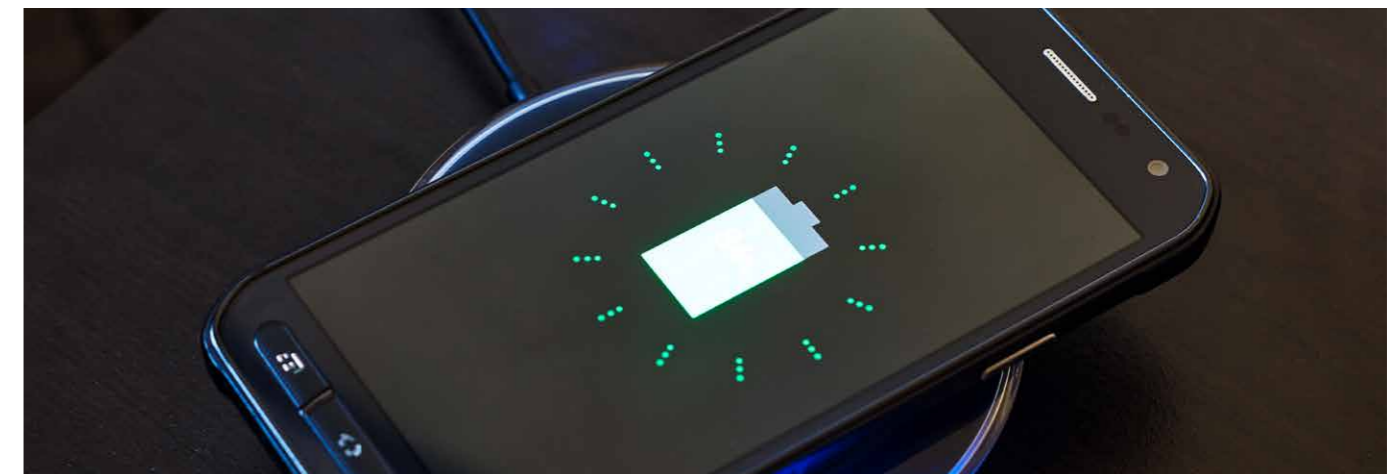
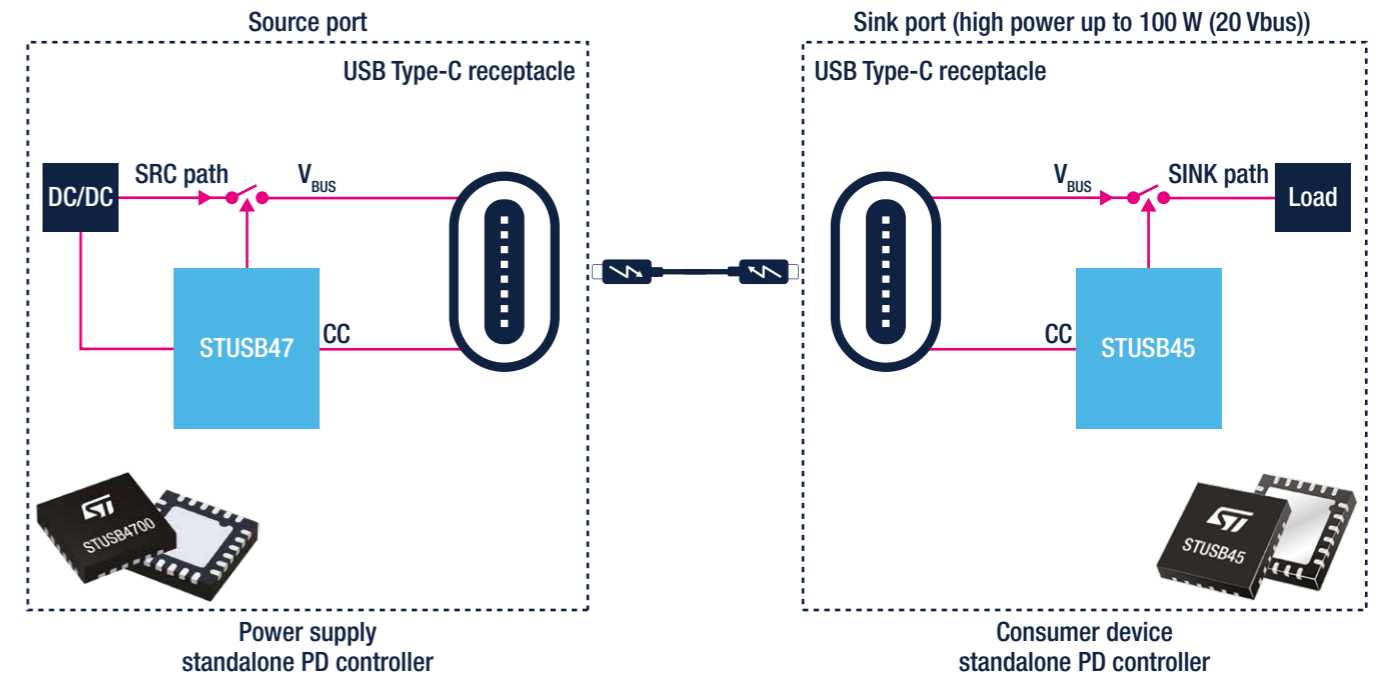


STEVAL-USBPD27S
27 W USB Type-C Power Delivery 3.1 adapter with PPS fetature



STEVAL-2STPD01
USB Type-C Power Delivery dual port adapter

Typical block diagram with Certified Source and Sink Standalone Controllers



Main application boards and reference designs



STEVAL-ISC004V1
STUSB4710A USB Power Delivery evaluation board (with on-board DC-DC)



STEVAL-ISC005V1
STUSB4500 USB Power Delivery evaluation board



EVAL-SCS001/2V1
SINK USB-PD reference design (EVAL-SCS001V1: migration from DC barrel) (EVAL-SCS002V1: migration from USB micro-B)



X-NUCLEO-SRC1M1
USB Type-C Power Delivery Source expansion board based on TCPP02-M18



X-NUCLEO-SNK1M1
USB Type-C™ Power Delivery SINK expansion board based on TCPP01-M12



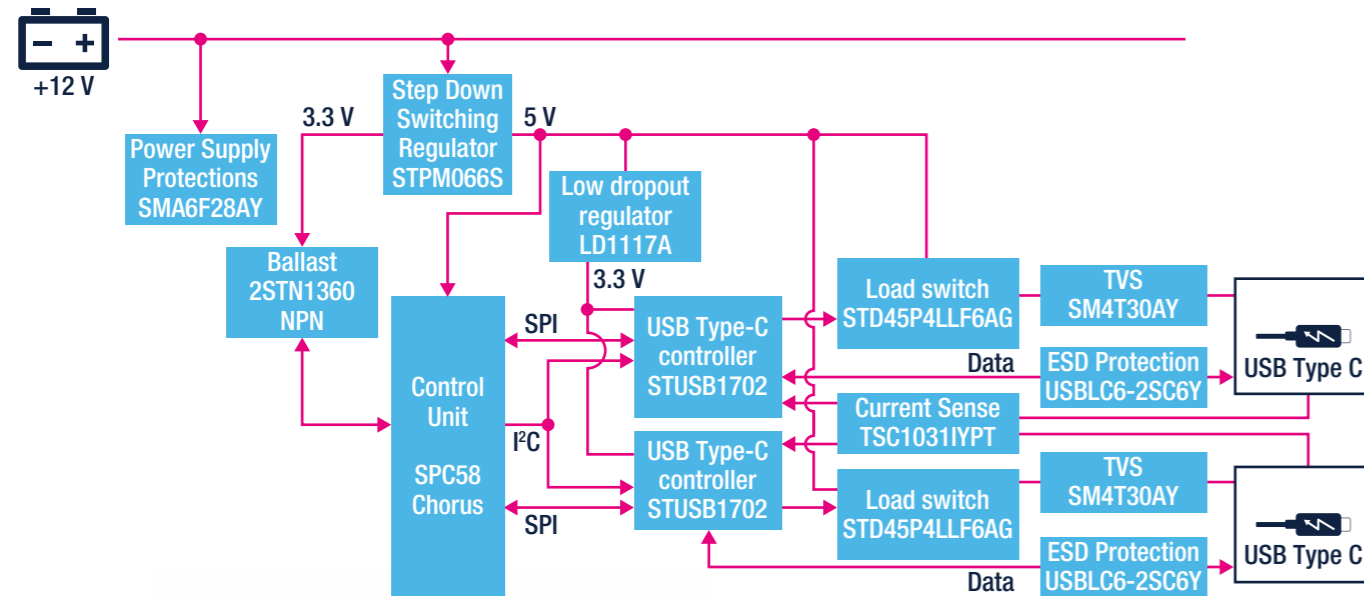
X-NUCLEO-DRP1M1
USB Type-C Power Delivery Dual Role Power expansion board based on TCPP03-M20

Automotive-grade USB Type-C and Power Delivery solution

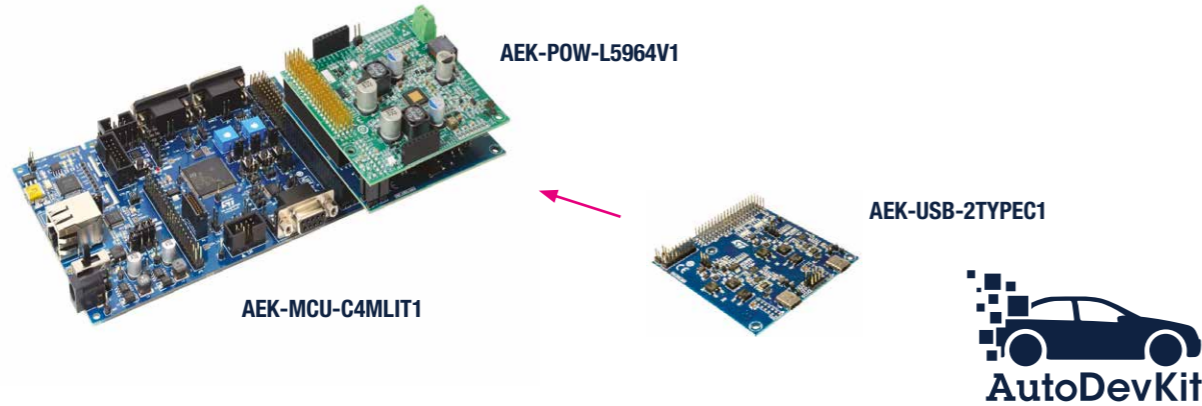
The USB Type-C and USB Power Delivery specifications allow smarter connectivity with fewer cables, less connectors and universal chargers.

The Type-C connector supports all the features of previous standards, and ports can be configured to only supply power in a Provider role, only sink power in a Consumer role, or be able to switch between both in a Dual role. Both data and power roles can be independently and dynamically swapped using the USB Power Delivery protocol. Most of the automotive applications require support for the Provider role only. When a USB device is connected, the Provider and the device (Consumer) negotiate a contract for the power objects through configuration channels.

Typical Block Diagram for Automotive grade USB Power Delivery



Complete USB Power Delivery version 3.0 including software stack available in AutoDevKit.



Digitally controlled dual-channel DC-DC suitable for USB Power Delivery 3.0

KEY FEATURES

- Dual independent channel up to 3 A each
- Compatible with both 12 V and 24 V input
- Combined channels for up to 100W
- Digitally selectable fixed output voltages: 3.3 - 5 - 9 - 15 - 20 V
- PPS-V: PWM programmable output voltages with 20 mV steps
- PPS-I: PWM programmable output current with 50 mA steps
- More details available on AN5362

Adapters for Tablets, Notebook and All-in-One (AIO) Computers

Power AC-DC adapters for notebooks, tablets and AIO need to be small, thin, lightweight, and provide excellent EMI performance, as well as ultra-low, highly efficient standby power, regardless of the load conditions.

A typical high-efficiency design includes a flyback or an active clamp flyback stage with synchronous rectification, and for higher power, a Power Factor Corrector (PFC) working in Transition Mode (TM) followed by a flyback, forward, or half-bridge LLC resonant stage with synchronous rectification.

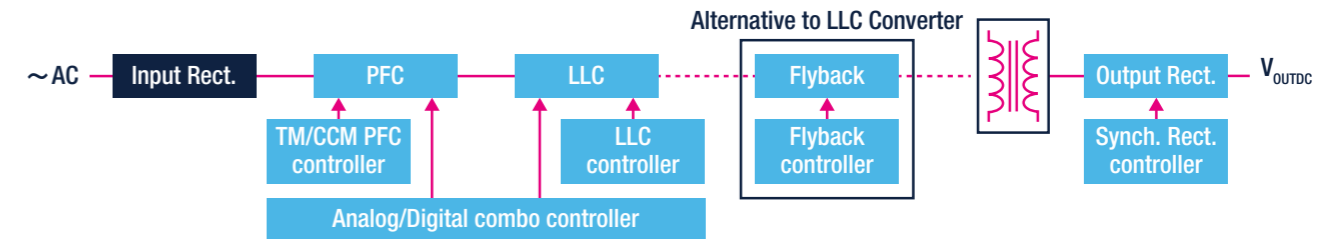
ST has recently introduced GaN Power ICs and offers a broad range of high-voltage MDmesh and low-voltage STripFET power MOSFETs, as well as standard and field-effect rectifiers (FERD). Our offering also includes a range of PFC, PWM primary controllers, synchronous rectification controllers, and single-chip analog and digital combo controllers.

ST recommended products for Tablets, Notebook and AIO Adapters

	Controllers	Power MOSFETs	Diodes	
PFC Block	TM Analog Controllers L6562A*, L6563*, L6564* CCM Analog Controllers L4985, L4986, L4981*, L4984D	650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 650 V MDmesh M5 ST*65M5	600 V Ultrafast for TM STTH*L06, STTH*06, STTH15AC06* 600 V Ultrafast for CCM STTH*R06, STTH*T06	
	Converters & Controllers	GaN Power ICs	Diodes & Protections	Voltage Reference, CC/CV Ctrl
Isolation Stage	Fully Integrated Controller for Active Clamp Flyback (ACF) ST-ONE HV Converters for Flyback SSR: VIPer*5, VIPer*7, VIPer*8 PSR: VIPer0P, VIPer*1, VIPer122, VIPer222, VIPer*6, ALTAIR* Flyback Controllers STCH03, L6566A, L6566B, L6565 PFC & LLC Combo Controllers STCMB1, STNRG011, STNRG011A LLC Analog Controllers L6599*, L6699 SR Analog Controllers SRK1000, SRK1001 for Flyback SRK2000A, SRK2001, SRK2001A for LLC	High Voltage GaN Converters VIPerGaN50, VIPerGaN65, VIPerGaN100 Integrated Smart GaNs 600 V MASTERGAN*	Output Diodes for Flyback Schottky, FERD, STPS*, FERD*45, FERD*50, FERD*60, FERD*100 Clamping Diodes for Flyback 600 V to 1000 V Ultrafast STTH*06, STTH*08, STTH*10 Output Diodes for LLC Schottky, FERD STPS* FERD*45, FERD*50, FERD*60, FERD*100 MOSFET protection for Flyback SM6T, SM15T series	Voltage Reference T*431, T*432 Voltage and Current Ctrl TSM*, SEA05* Post Regulation DC-DC Converters ST1S*, ST1S40, ST1S50 Low Dropout (LDO) Linear Regulators ST715 LDK320 ST715 ST730 ST732

Note: * is used as a wildcard character for related part number

Typical Block Diagram with PFC Front-End



Main application boards and reference designs



EVLMG1-250WLLC
250 W Resonant DC-DC Converter based on LLC analog controller and integrated smart GaNs



EVLSTNRG011-150
12 V - 150 W power supply based on TM PFC and HB LLC digital combo controller



EVLCMB1-AIO210W
12 V - 210 W adapter based on TM PFC and HB LLC analog combo controller



EVL400W-80PL
12 V - 400 W adapter based on CCM PFC and HB LLC analog controller

Note: EU CoC ver. 5 Tier 2 and EuP lot 6 Tier 2 compliance ensured

Wireless Charging

Wireless chargers, are expected to become ubiquitous in hotels, airports, cafes and other public places as they enable topping charging of portable and wearable devices without any cables.

In a wireless battery charging system, power is transferred by electromagnetic induction (inductive power transfer) between a transmitting pad (TX) and a battery-powered device (RX) such as a smartphone, smartwatch, or sports gear.

The power transmitter unit controls the current in the transmitting coil to transfer the correct amount of power as required by the receiver unit, which continuously provides this information to the transmitter by modulating the transmitter carrier frequency through controlled resistive or capacitive load insertion. Generating the correct amount of power guarantees the highest level of end-to-end energy efficiency and helps limit the device's operating temperature.

ST has a wide range of wireless charger IC solutions, including transmitters and receivers providing low standby power, accurate foreign object detection (FOD) and reverse charging features. In order to prevent unwanted damage to any NFC Cards that might be close to the wireless charging source during operation, it is recommended to add an NFC Reader. The NFC Reader is able to detect the presence of the NFC Card or Tag (ST Reader ICs can detect Type A, B, F, or V NFC Cards), and therefore instruct the operating system to stop transmitting power.

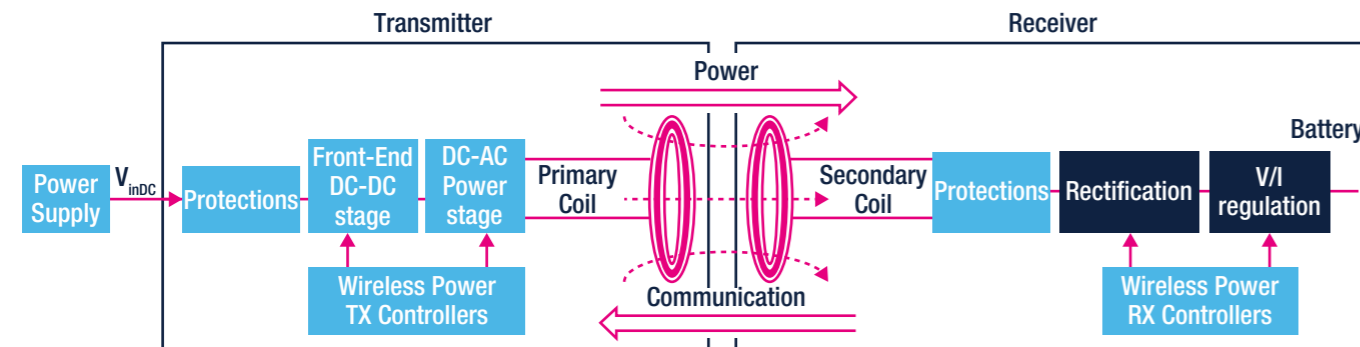
ST also offers evaluation and development tools and reference designs to help develop high-efficiency and compact wireless chargers that are Qi compliant for both Baseline Power Profile (BPP) and Extended Power Profile (EPP). Moreover, easy to use reference designs and evaluation boards enables customization with ST Super Charge protocol for personal electronics, industrial and medical applications.

ST recommended products for Wireless Charging

	Wireless charging ICs	Battery Charger ICs	MCUs	Power MOSFETs	Protections	Diodes	NFC reader
Transmitter	STWBC86 STWBC2-HP		STM32G0 STM32F334 STM32G4	STL10N3LLH5, STL8DN6LF3, ST*N2VH5, STL8DN1OLF3, STL6N3LLH6, STL10N3LLH5	TVS SMAJ, SM6T, SM15T series USB Port Protection TCPP01-M12	STPS*L30 STPS*45/60/100 FERD*45/60/100	ST25R3911B ST25R3912 ST25R3916B
Receiver	STWLC38 STWLC86 STWLC98	STBC02			ESDALC14V2-1U2	BAT30F4, BAR46	

Note: * is used as a wildcard character for related part number

Typical Block Diagram



Main application boards and reference designs

Receivers

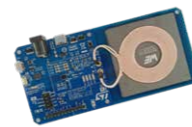


STEVAL-WLC38RX1
Qi-based wireless power receiver evaluation board for applications up to 5W BPP and 15W EPP



STDES-ISB38WA2
Qi-based wireless power receiver reference design for wearable applications up to 2.5 W

Transmitters



STEVAL-WBC86TX
Qi wireless power transmitter for Baseline Power Profile (BPP) applications up to 5 W

NFC Readers



ST25R3911B-DISCO
ST25R3911B based NFC Reader discovery board



X-NUCLEO-NFC08A1
ST25R3916B based Nucleo expansion board

1 available in Q1 2023

2 available in Q2 2023

Desktop PC Power Supply

The requirements for the standard ATX PC power market are small form factor with better performance.

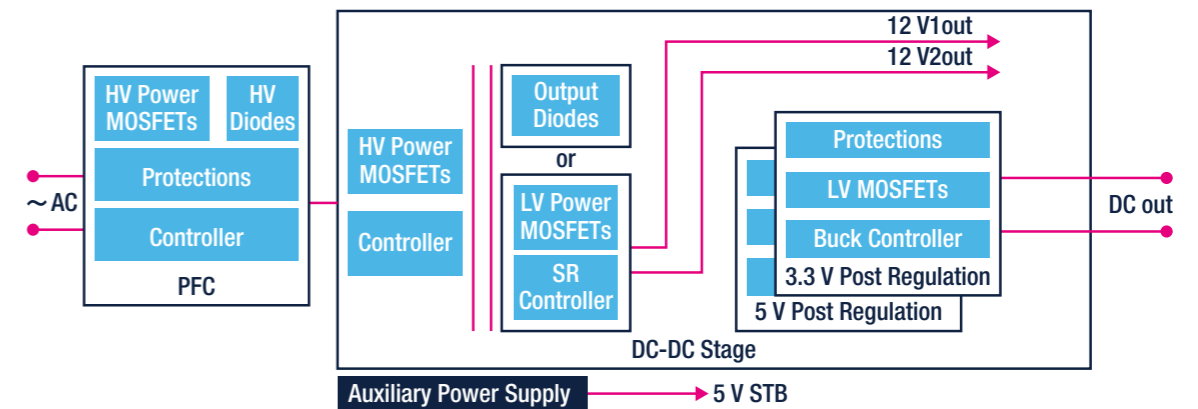
An intelligent control scheme that enables adaption to load variation to minimize power consumption, together with optimized power semiconductors, are key to meeting market demands. Smart analog and digital controllers such as the STCMB1 and the STNRG011, GaN Power ICs such as the MASTERGAN series and the GaN Drivers, high-voltage MDmesh Power MOSFETs, low-voltage STripFET Power MOSFETs, and SiC diodes (STPSC*) help designers develop the best PC power supply solutions to improve efficiency. ST DC-DC converters guarantee high power density for the post-regulation.

ST recommended products for Desktop PC's Power Supply

	Controllers	Power MOSFETs	Diodes & Discretes	Opamp V/I Sensing
PFC Block	TM Analog Controllers L6562A*, L6563*, L6564* CCM Analog Controllers L4985, L4986, L4981*, L4984D MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STNRG388A	650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 650 V MDmesh M5 ST*65M5	600 V Ultrafast for TM STTH*L06, STTH*06, STTH15AC06* 600 V Ultrafast for CCM STTH*R06, STTH*T06 SiC Diodes STPSC*065 TVS for Power Rail Surge Protection SMAJ40CA-TR	Precision Op Amps (<50 MHz) TSZ*, TSV*, TS9*, LMV* MOSFET and IGBT Gate Drivers Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1
Isolation DC-DC Stage	PFC & LLC Combo Controllers STCMB1, STNRG011, STNRG011A LLC Analog Controllers L6599*, L6699 Asymmetrical HB Controllers L6591 MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STNRG388A SR Analog Controllers SRK2000A, SRK2001, SRK2001A for LLC	600 V MDmesh DM9 ST*60N*DM9 600 V-650 V MDmesh DM6 ST*60DM6, ST*65DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 40 V-100 V STripFET F7 ST*N4F7, ST*N6F7, ST*N8F7, ST*N10F7	Output Diodes Schottky, FERD STPS*, FERD*45, FERD*50, FERD*60, FERD*100 Protections TVS for Power MOSFET and Power Rail Surge Protection SMAJ, SM6T, SM15T series LDO Low Dropout (LDO) Linear Regulators LDF, LDFM, LDK320, LDL212, LD39200, LD117	eFuses STEF01 STEF05-STEF05S STEF12-STEF12S STEF12H60M MOSFET and IGBT Gate Drivers Integrated smart GaNs 600 V MASTERGAN* HV HB Gate Drivers for GaNs STDRIVEG600 HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* SR Multiple LS Gate Drivers PM8834
Post Regulation	L6726A, L673*, PM6680	STL90N3LLH6	Voltage Reference T*431, T*432, TS33*	

Note: * is used as a wildcard character for related part number

Typical configuration



Main application boards and reference designs



EVL011A150ADP
12 V - 150 W power supply based on TM PFC and HB LLC digital combo controller



EVL4986-350W
Low-THD 350W CCM-PFC pre-regulator



EVL4985-350W
Low-THD 350W CCM-PFC pre-regulator



EVL400W-80PL
12 V - 400 W adapter based on CCM-PFC and HB LLC analog controller

Server & Telecom Power

AC-DC PSU & DC-DC power distribution

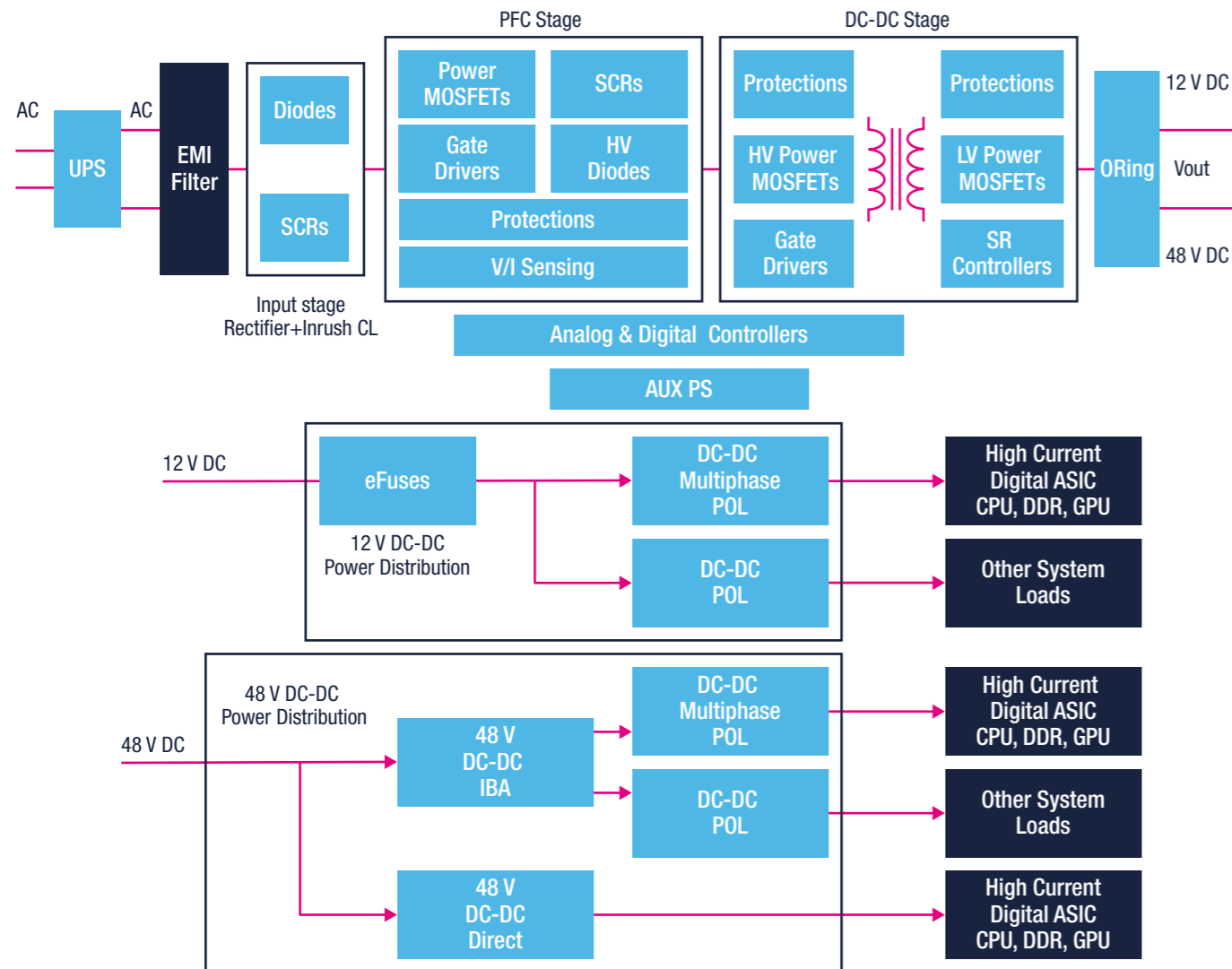
Data centers house thousands of servers usually built in very dense network farms. Data center power requirements are constantly increasing and traditional power systems are no longer sufficient to meet this growing demand. The power distribution chain, from the front-end AC-DC stage to the back-end DC-DC power distribution, needs to deliver the best performance in terms of efficiency, power density, and the ability to interface with the digital world.

In telecom system power, the use of complex digital ASICs for managing growing data traffic is pushing the power envelope higher. Telecom power management systems have to be highly energy-efficient and very dense to deliver the required high levels of power, while maintaining reasonable power consumption.

ST offers extensive product and solution coverage to ensure the most optimized power design across the entire distribution chain. Our digital and analog controllers combined with MOSFETs and drivers are key ingredients for implementing the most efficient and most dense AC-DC power delivery. On the back-end DC-DC power distribution, ST offers advanced solutions for Point-of-Load conversion and a recently developed innovative DC-DC conversion from a 48 V DC supply.



Typical Block Diagram for Server PSU



ST product offering for Server and Telecom AC-DC PSU

Input Stage (Rect. & inrush current limiter)	Controllers	SCRs	Diodes	MOSFET and IGBT Gate Drivers
		High Temp. SCR TN*015H-6, TM8050H-8, TN*050H-12	Bridge Rectifier Diodes STBR*08, STBR*12	
PFC Block	CCM Analog Controllers L4985, L4986, L4981*, L4984D	Power MOSFETs 650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2 650 V MDmesh M5 ST*65M5 650 V SiC MOSFETs SCT**65G3AG, SCT*N65G2	Diodes & Protections 600 V Ultrafast for CCM STTH*R06 STTH*T06 SiC Diodes STPSC*065	HV HB Gate Drivers L649*
	MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STNRG388A		TVS for Power MOSFET and Power Rail Surge Protection SMAJ, SM6T, SM15T, series	Isolated Gate Drivers STGAP*
			V/I Sensing Isolated Sigma-Delta ADC ISOSD61, ISOSD61L Precision Op Amps (<50 MHz) TSZ*, TSV*, TS9*, LMV*	Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1
Isolation DC-DC Stage	LLC Analog Controllers L6599A, L6699 Asym. HB Analog Controllers L6591	Power MOSFETs 600 V MDmesh DM9 ST*60N*DM9 600 V-650 V MDmesh DM6 ST*60DM6, ST*65DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2-EP SR 60 V-100 V StripFET F7 ST*N6F7, ST*N8F7, ST*N10F7	Diodes & Protections Output Diodes for LLC Schottky, FERD STPS*	HV HB Gate Drivers for GaNs STDRIVEG600
	MCUs & Digital Controllers STM32F334, STM32G4, STNRG388A SR Analog Controllers SRK2000A, SRK2001, SRK2001A		FERD*45, FERD*50, FERD*60 TVS for Power MOSFET and Power Rail Surge Protection SMAJ, SM6T, SM15T, series	HV HB Gate Drivers L649*
			LDO Low Dropout (LDO) Linear Regulators LDF, LDFM, LD39050, LD39100, LD39200, LDL112, LDL212, LD59100, LD57100	Isolated Gate Drivers STGAP*
			DC-DC L3751	SR Multiple LS Gate Drivers PM8834 SR HV HB Gate Drivers L649*
			eFuses	STEF01 STEF05-STEF05S STEF12-STEF12S STEF12H60M

Note: * is used as a wildcard character for related part number

Main application boards and reference designs



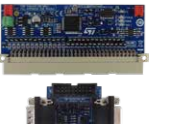
STEVAL-ISA147V3
500 W fully digital AC-DC power supply (D-SMPS)



STEVAL-ISA172V2
2 kW fully digital AC-DC power supply (D-SMPS)



STEVAL-DPSLLCK1
3 kW Full Bridge LLC resonant digital power supply



STEVAL-DPSG474
Digital Power Control Board



STDES-3KWTLCP
3 kW telecom rectifier reference design with Totem-Pole PFC and LLC Converter



STEVAL-DPSTPFC1
3.6 kW PFC Totem-Pole with digital inrush current limiter



STEVAL-SCR002V1
Inrush current limiter for 1 kW AC/DC

Power Distribution for Modern Data Center

To support the evolution and expansion of cloud services, the internet of things, mobile apps, and new generation of telecommunication infrastructure, the demand for data centers performance is growing exponentially with more powerful CPUs, and this segment is expanding in artificial intelligence and machine learning.

In the newest architecture, a 48 V DC rail is generated from the AC-DC power supply unit, which is then converted to provide the number of DC rails needed to supply the various loads and circuits in the server. This conversion must meet stringent efficiency targets requiring innovative architectures like those developed by ST.

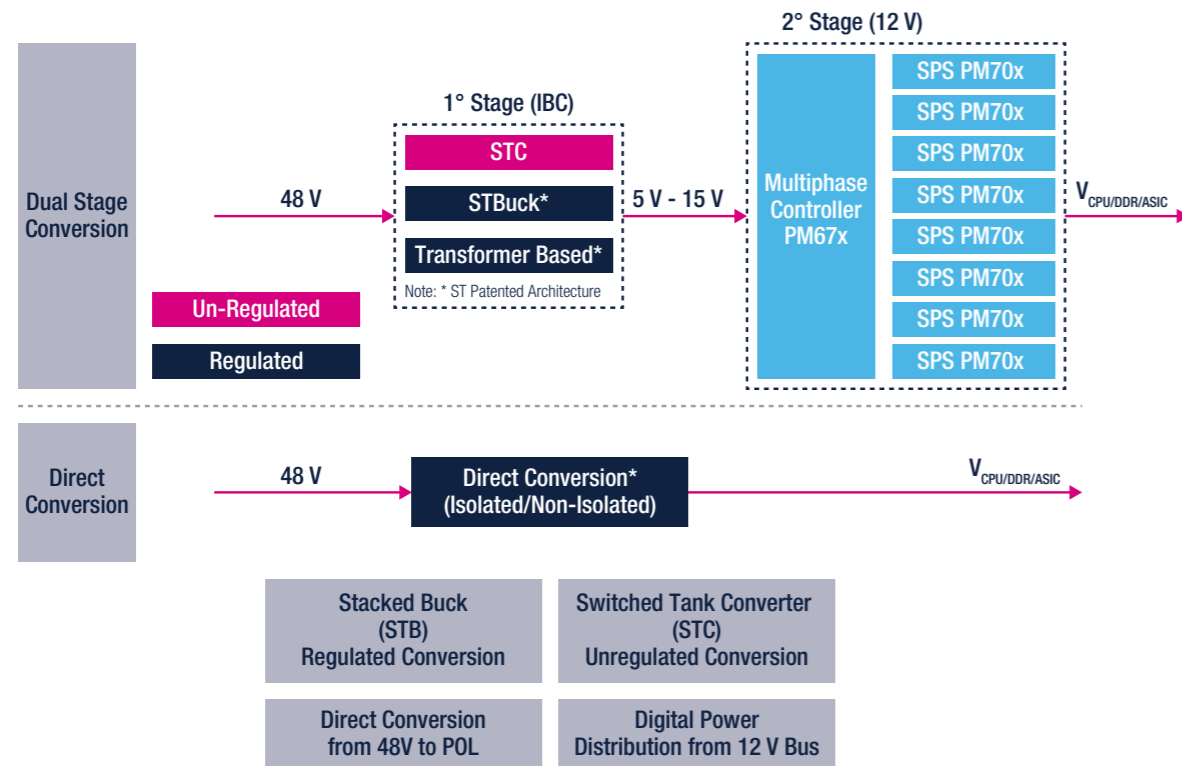
We offer a wide range of high-efficiency regulated and unregulated DC-DC conversion solutions, including STB, STC, HSTC for 48 to 12 V intermediate bus conversion.

Moreover, we offer 12 V to Point of Load conversion, including multi-phase digital controller and Smart Power Stages (SPS) to support the most recent INTEL and AMD CPU specifications.

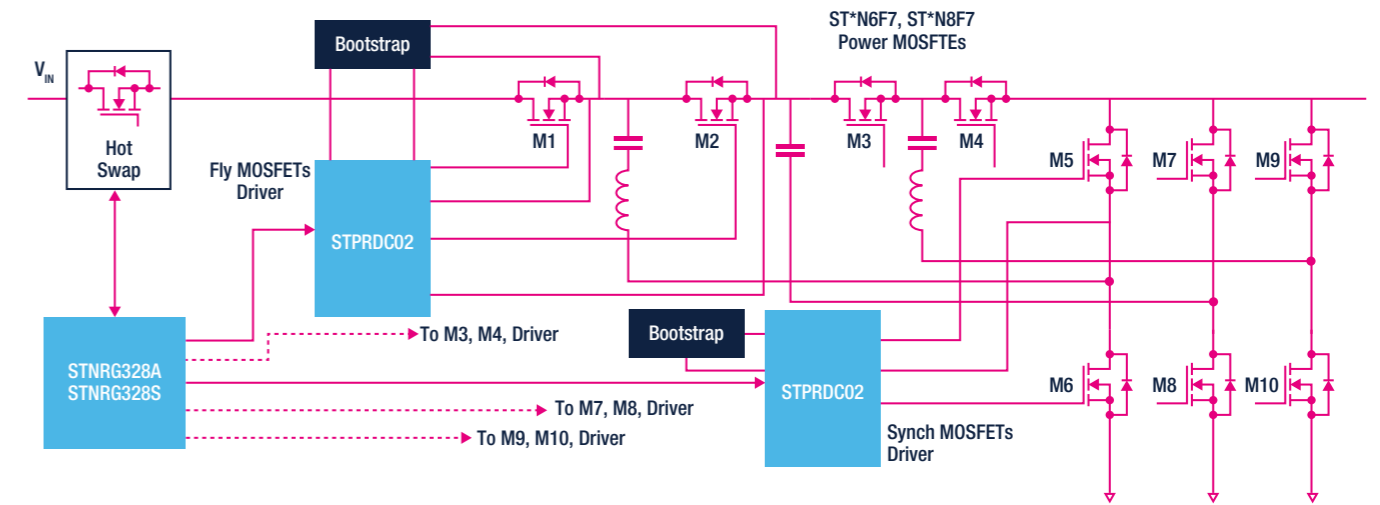
Finally, ST offers direct conversion solutions, from 48 V to point-of-load, based on the Power Stamp Alliance (PSA) products.



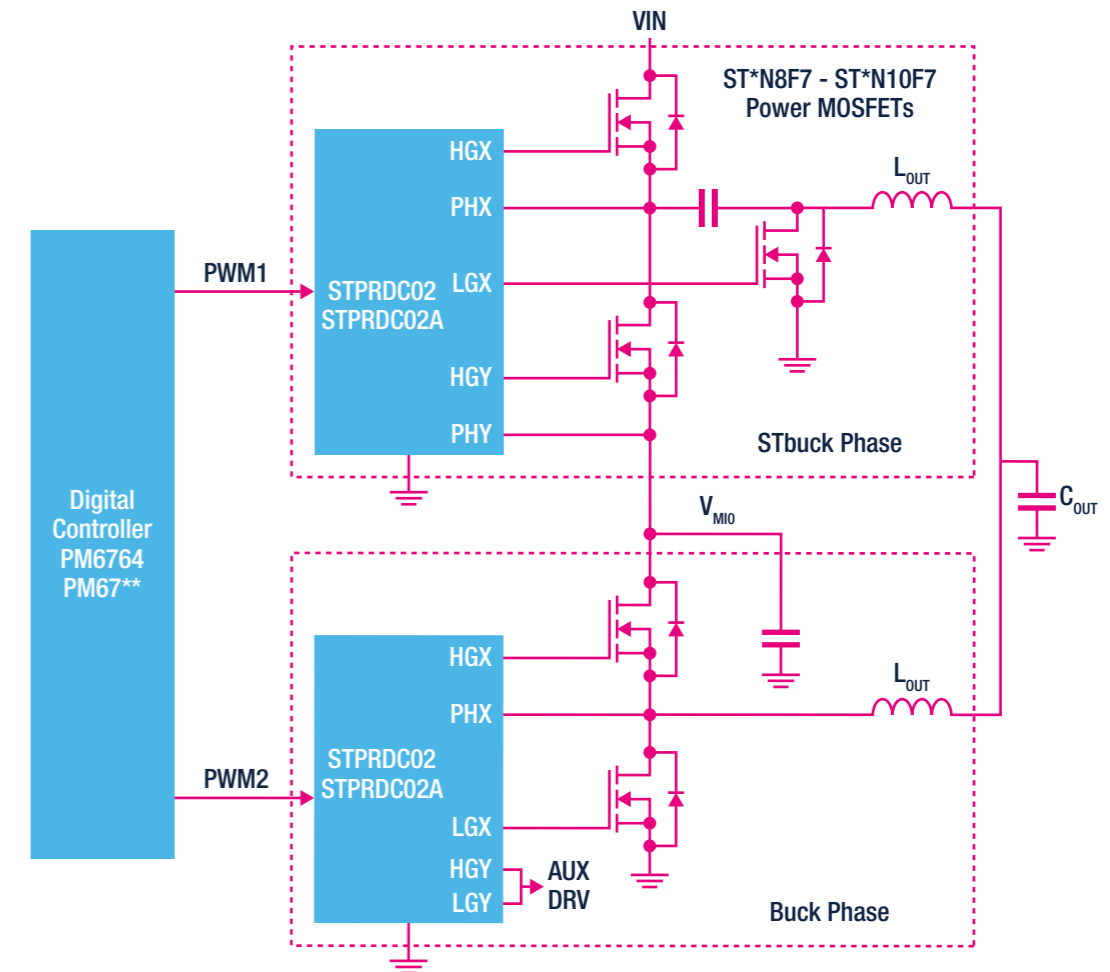
Power Delivery for Modern Data Center



Typical Configuration for Switched-Tank Converter (STC) System - 48 V to 12 V non isolated unregulated IBC

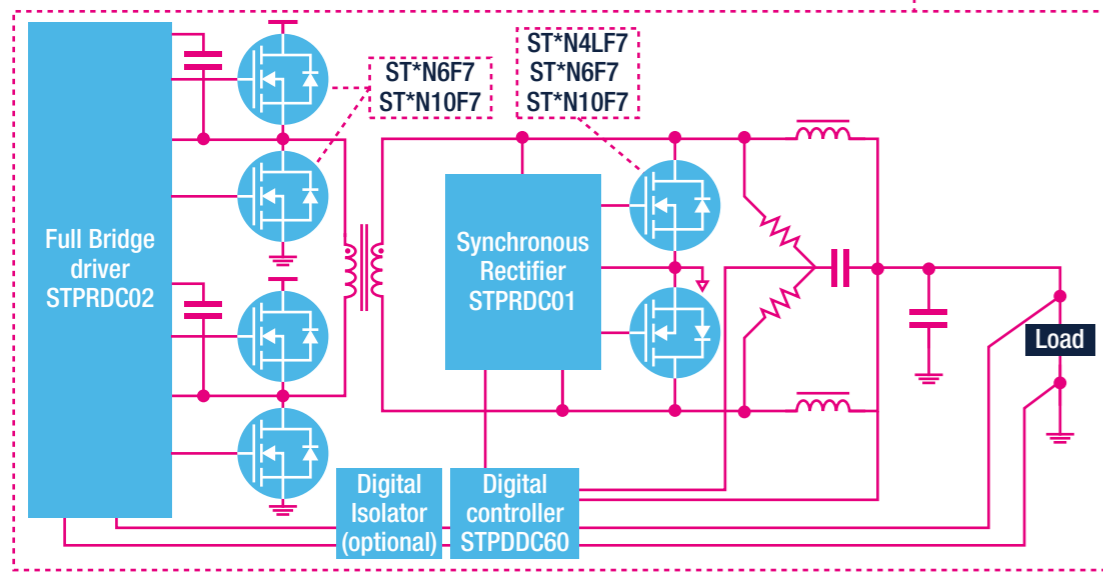
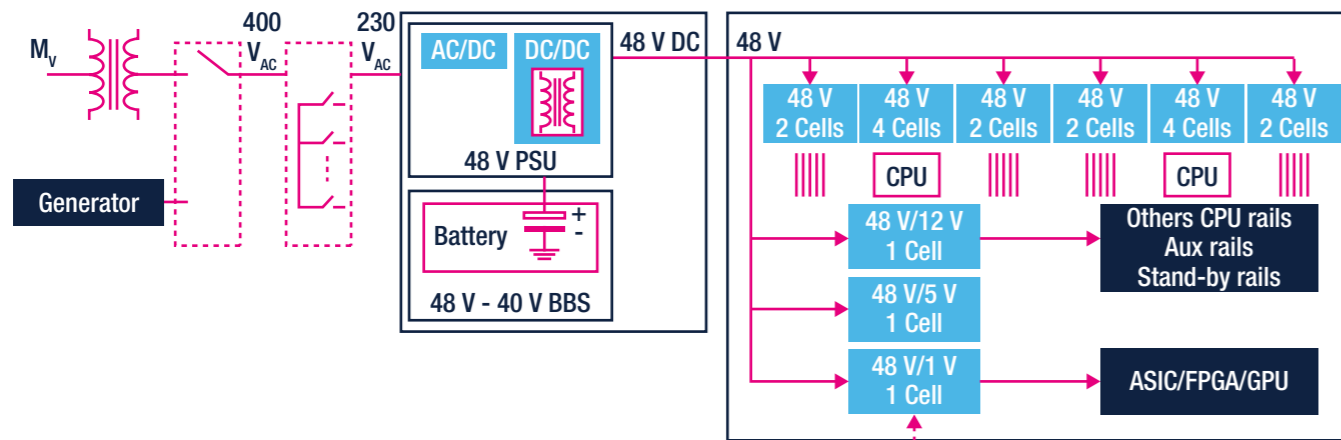


Typical Configuration for STBUCK - 48 V to 12 V non isolated regulated IBC



Note: * is used as a wildcard character for related part number

Typical Configuration for 48 V Isolated Direct Conversion



Note: * is used as a wildcard character for related part number

SSD Power Management

Solid State Drives (SSD) serve the same function as Hard Disk Drives, but they have a different set of internal components; they have no moving parts and data is stored in flash memory. SSDs can access data faster than HDDs and have several other advantages such as better performance and robustness and lower power consumption. SSDs are widely used in desktop and notebook computers, as well as for storage in data centers.

ST offers state-of-the-art products for SSD system architecture, including Power Management ICs featuring protections and communication bus. Our portfolio of high-quality components allows the design of solutions that meet the most demanding requirements of both consumer SSD and enterprise-grade SSDs.

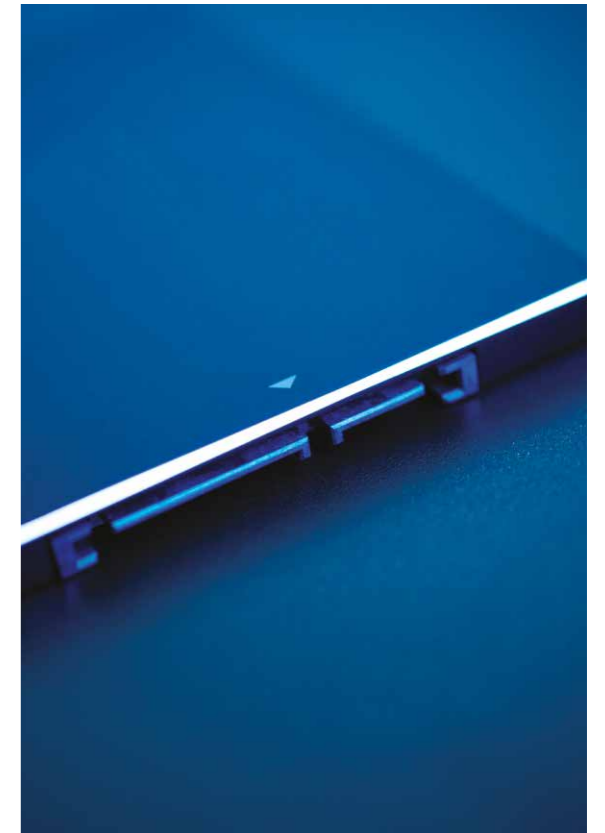
The ST device family is ideal for designing advanced power management solutions for microcontroller, DDR, Flash memory, on SSD server and consumer applications.

The IC series features multiple Buck and LDOs with programmable outputs and supports conversions from a wide range of input voltage buses like 12 V, 5 V and 3.3 V.

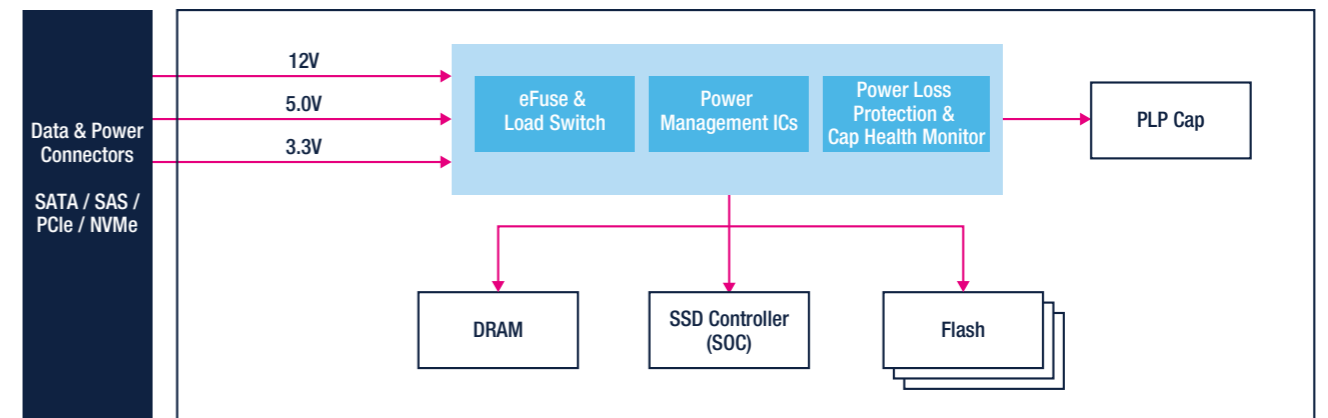
Electronic fuses (eFuses) for 3.3, 5 and 12 V located at the power connector minimize system down-time by protecting the SSD and the host from failures.

High switching frequency eases the design of compact applications, while specific control techniques ensure best-in-class efficiency at heavy and light load operation.

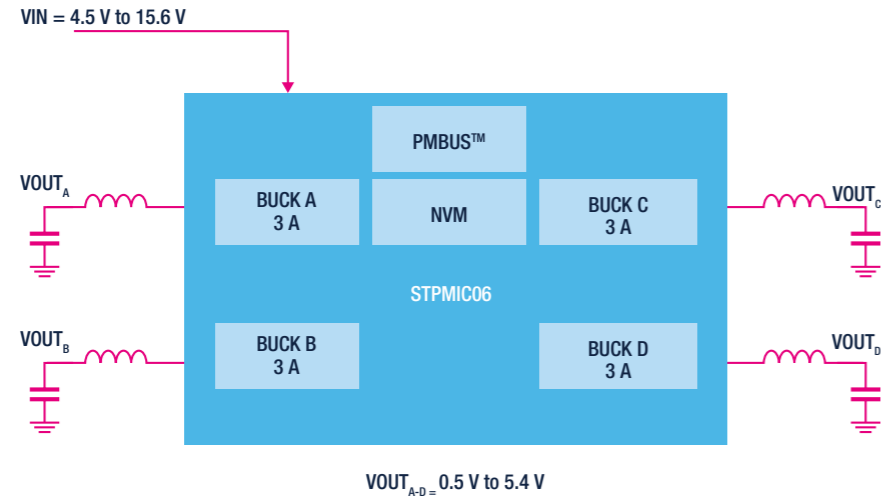
Full programmability via high speed serial interfaces like I²C and PMBus[®] allows configurability for different application requirements.



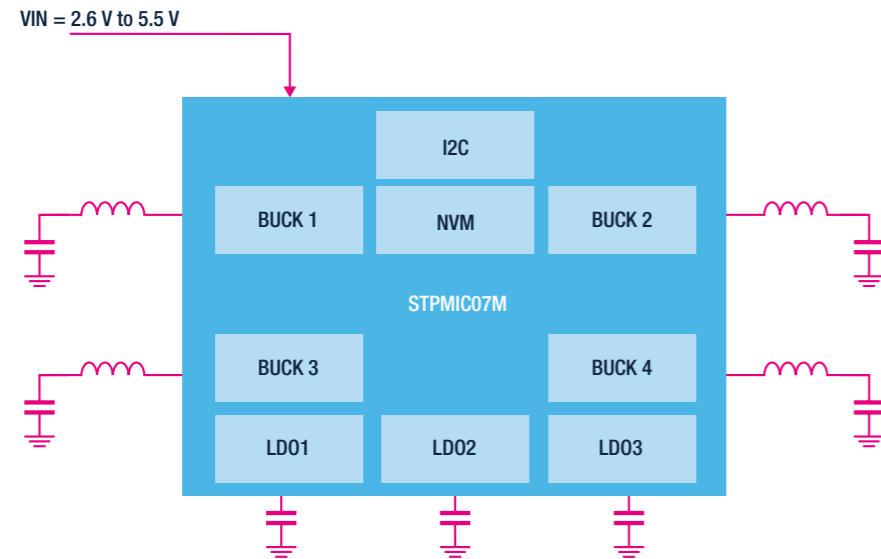
Typical Block Diagram for SSD Power Management



STPMIC06



STPMIC07M



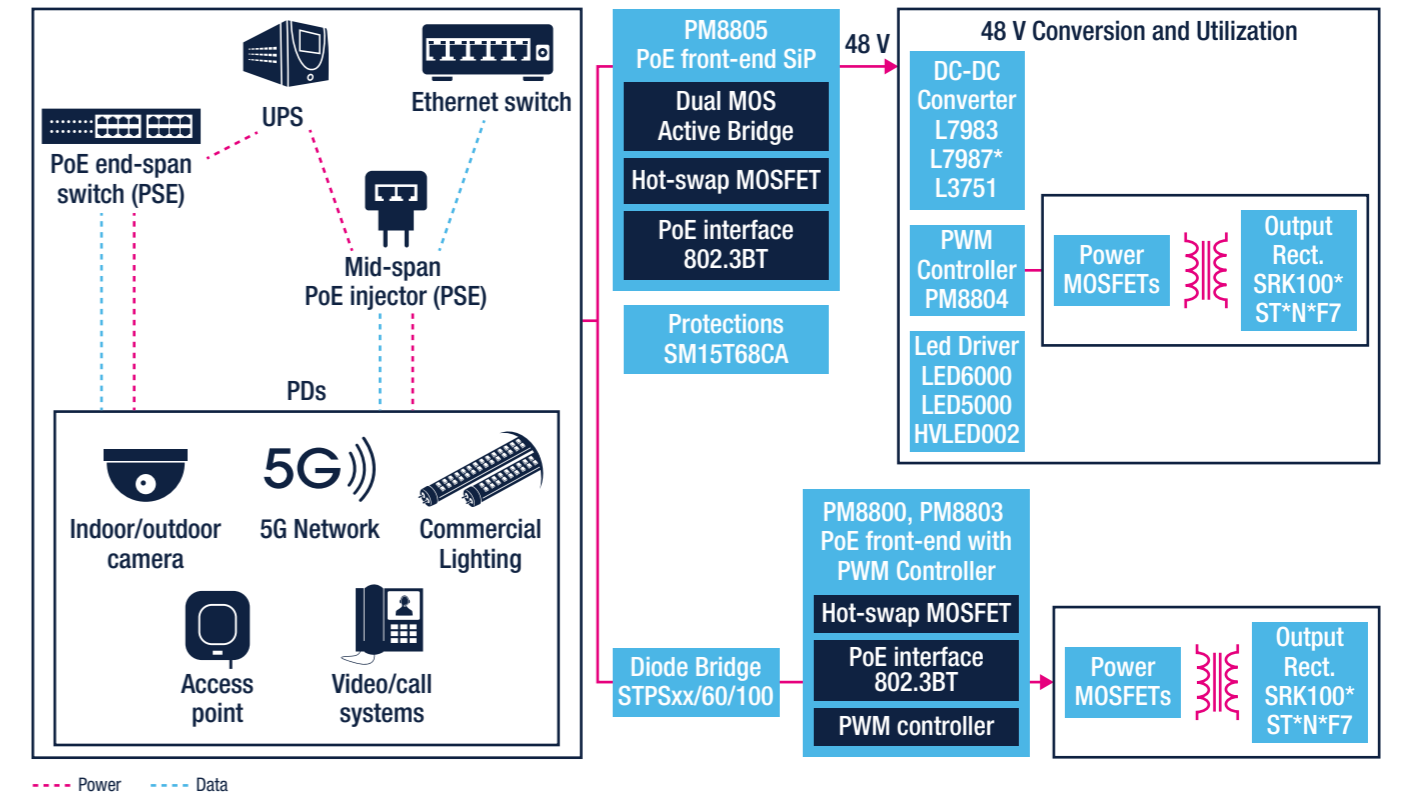
Power over Ethernet (PoE)

Power over Ethernet (PoE) is a widely adopted technology used to transfer power and supply the powered device (PD), including wireless access points, VoIP phones over an RJ-45 cable also carrying data as described in the IEEE 802.3 standard, and its evolutions including IEEE 802.3bt, IEEE 802.3at, and IEEE 802.3af.






We offer a range of products for complete interface with all the functions required by the communication standard, including detection and classification, as well as protection features such as under-voltage lockout (UVLO) and in-rush current limitation. In addition, these products can control hot-swap power MOSFETs that can greatly simplify the development of IEEE 802.3 compliant solutions for powered devices (PD).



Typical block diagram for PoE Power Management



Main application boards and reference designs

 <p>STEVAL-POE001V1 Power Over Ethernet (PoE) - IEEE 802.3bt compliant interface</p>	 <p>STEVAL-POE002V1 5 V/8 A, synchronous flyback converter, Power over Ethernet (PoE) IEEE 802.3bt compliant reference design</p>	 <p>STEVAL-POE003V1 5 V/20 A, active clamp forward converter, Power Over Ethernet (PoE) - IEEE 802.3bt compliant reference design</p>
 <p>STEVAL-POE005V1 12 V/8 A, active clamp forward converter, Power Over Ethernet (PoE) IEEE 802.3bt compliant reference design</p>	 <p>STEVAL-POE006V1 3.3 V/20 A, active clamp forward converter, Power Over Ethernet (PoE) IEEE 802.3bt compliant reference design</p>	

Note: * is used as a wildcard character for related part number

LED TV Power Supply

Beyond their outstanding image quality, new-generation televisions have a very thin design, are highly power-efficient and feature a stand-by power mode. Power Supply Units (PSUs) play a key role in ensuring TVs meet market requirements and have an elegant form factor.

To achieve these stringent requirements, PSUs typically have a Power Factor Corrector (PFC) stage and use advanced topologies like half-bridge LLC (HB-LLC) resonant.

ST offers a broad portfolio of high-voltage MDmesh and low-voltage STRipFET power MOSFETs, field-effect rectifier diodes (FERD), Schottky and Ultrafast diodes, a full range of protection ICs, as well as dedicated analog and digital switching controllers, which negate the necessity of auxiliary power by consuming very low power at no load. In addition, STM32 microcontrollers enable developers to exploit the full potential of digital PSU implementations.

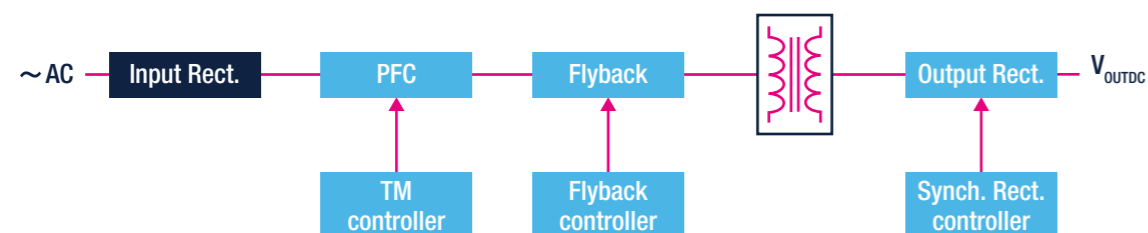


ST recommended products for LED TV Power Supply

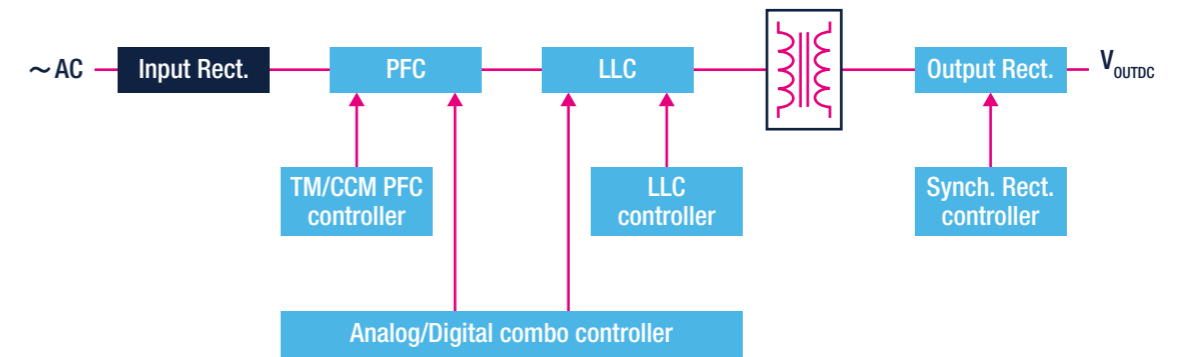
	SCR			
Input Rectifier	High Temp. SCR TN*015H-6, TM8050H-8, TN*050H-12			
PFC Block	Controllers	Power MOSFETs	Diodes	Opamp V/I Sensing
PFC Block	TM Analog Controllers L6562A*, L6563*, L6564* CCM Analog Controllers L4985, L4986, L4981*, L4984D MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STNRG388A	650 V MDmbesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 650 V MDmesh M5 ST*65M5	600 V Ultrafast for TM STTH*L06 STTH*06 STTH15AC06* 600 V Ultrafast for CCM STTH*R06 STTH*T06 SiC Diodes STPSC*065	Precision Op Amps (<50 MHz) TSZ*, TSV*, TS9*, LMV*
				MOSFET and IGBT Gate Drivers
Isolation Stage	Controllers	GaN Power ICs	Diodes & Protections	MOSFET and IGBT Gate Drivers
	Flyback Controllers L6566A, L6566B, L6565, L6668, STCH03 PFC & LLC Combo Controllers STCMB1, STNRG011, STNRG011A LLC Analog Controllers L6599*, L6699 Asymmetrical HB Controllers L6591 MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STNRG388A SR Analog Controllers SRK1000, SRK1001 for Flyback SRK2000A, SRK2001, SRK2001A for LLC	Integrated Smart GaNs 600 V MASTERGAN HV HB Gate Drivers for GaNs STDRIVEG600 Power MOSFETs 600 V MDmesh DM9 ST*60N*DM9 600 V MDmesh DM6 ST*60DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 60 V-100 V STRipFET F7 ST*N6F7, ST*N8F7, ST*N10F7	Output Diodes for Flyback Schottky, FERD, Ultrafast STPS*, FERD*, STTH* Clamping Diodes for Flyback 600 V to 1000 V Ultrafast STTH*06, STTH*08, STTH*10 Output Diodes for LLC Schottky, FERD STPS* FERD*45, FERD*50, FERD*60, FERD*100 MOSFET Protection for Flyback SMAJ, SM6T, SM15T series	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* SR Multiple LS Gate Drivers PM8834 SR HV HB Gate Drivers L649* Isolated Interfaces for wired connectivity STIS062x
			Voltage Reference	Post Regulation
			T*431, T*432	DC-DC Converters ST1S12, ST1S3*, ST1S4*, ST1S50 Low Dropout (LDO) Linear Regulators LD1117xx, ST730/2, L78xx, LD39100

Note: * is used as a wildcard character for related part number

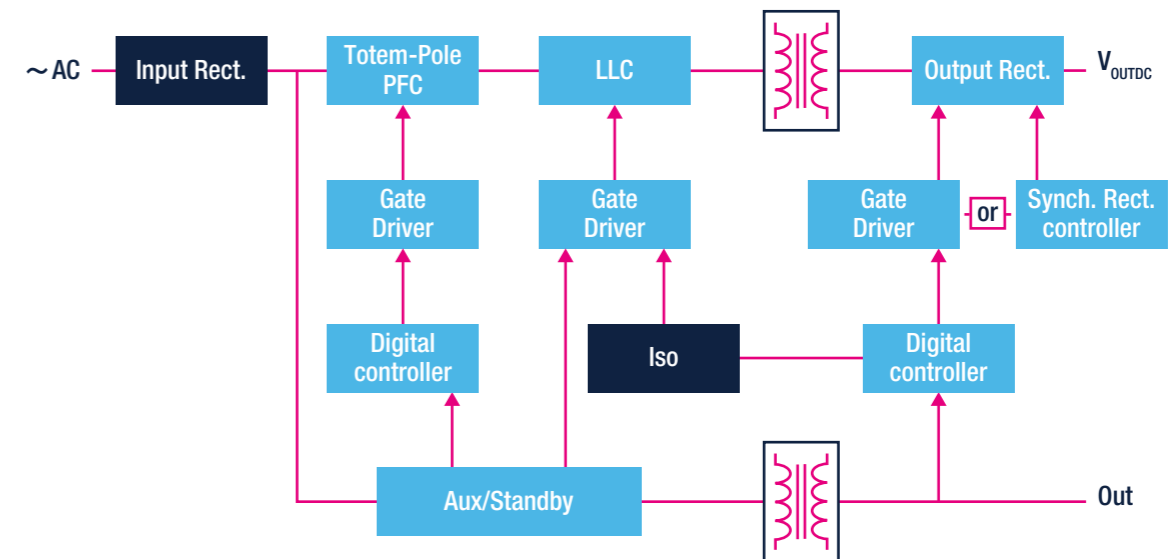
Typical Block Diagram for Analog Control Solutions for Small Panel Size



Typical Block Diagram: Analog Control Solutions with no Aux supply, for Small/Medium Panel Size



Typical Block Diagram for Digital Control Solutions for Medium/Large Panel Size



Main application boards and reference designs



EVLMG1-250WLLC

250 W Resonant DC-DC Converter based on LLC analog controller and GaN



STEVAL-NRG011TV

200 W power supply based on STNRG011 digital combo for LED TV



STEVAL-DPSTPFC1

3.6 kW PFC Totem-Pole with digital inrush current limiter



EVLCMB1-90WADP

19 V - 90 W adapter based on TM PFC and HB LLC analog combo controller



EVLSTNRG011-150

12 V - 150 W power supply based on TM PFC and HB LLC digital combo controller



EVL400W-80PL

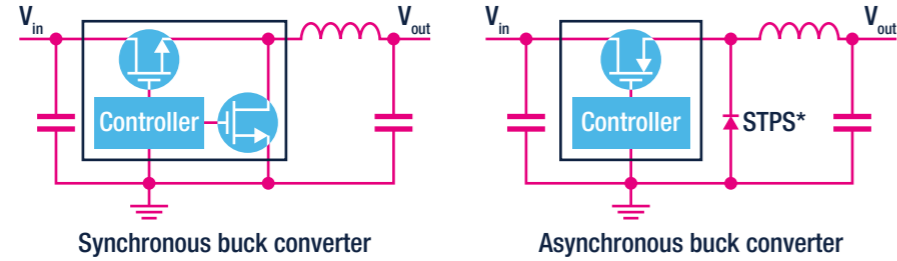
12 V - 400 W adapter based on CCM PFC and HB LLC analog controller

DC-DC Conversion

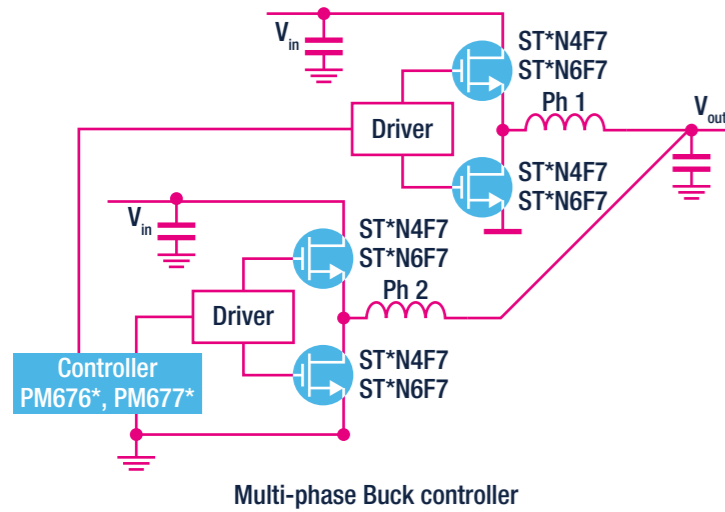
A DC-DC switching converter is used to locally supply any component or part of a system with the desired DC voltage and current. Depending on the application's relationship between the input and output voltage, engineers have to choose the best power topology: buck, boost, buck-boost or inverting, with or without synchronous rectification. In addition, they can decide to use an implementation based on monolithic ICs, or with discrete power switches and controllers, or even an advanced digital implementation. Whatever the choice, the right semiconductor products are key to meeting the specific efficiency and size design targets.

ST broad product portfolio includes highly-integrated DC-DC converters and PWM controllers, power MOSFETs and rectifiers, protection ICs, and linear voltage regulators to address a wide range of topologies and power requirements. We also provide a comprehensive range of hardware and software evaluation and development tools, including eDesignSuite, which that helps engineers design high-efficiency DC-DC converters.

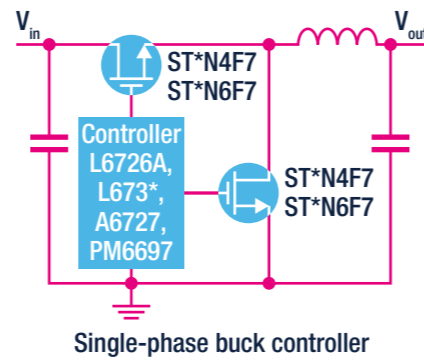
Typical buck configuration: up to 61 Vin/3 A Iout



Typical multi-phase configuration: up to 12 Vin, very high output current

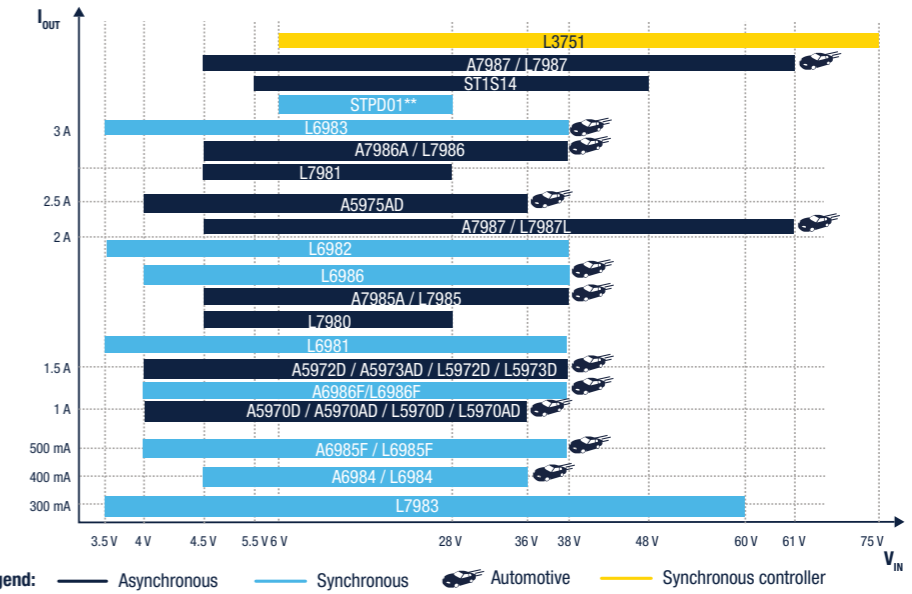


Typical single phase discrete configuration: up to 18 Vin, high output current



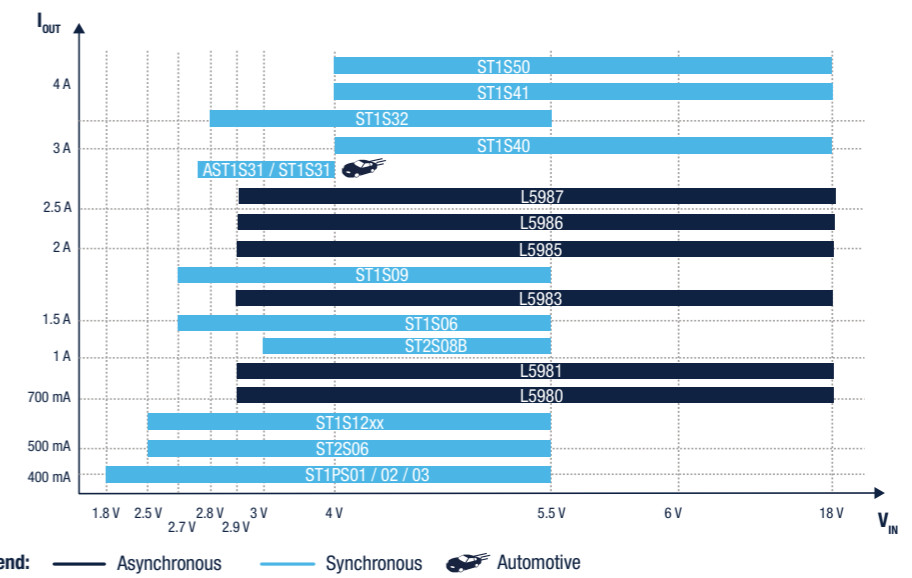
ST product offering for Switching Converters (DC-DC)

Pre-regulation (>24 V)



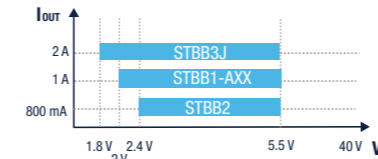
Note: * under development, ** for USB PD, up to 60 W output power (20 V, 3 A)

Post-Regulation (<24 V)

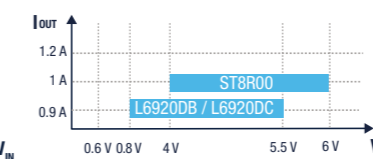


Note: * under development

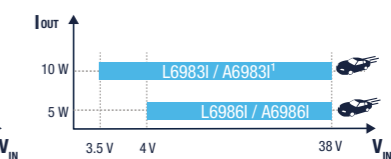
Buck-Boost



Boost



IsoBuck



Note: † available in Q2 2023

Main application boards and reference designs



STEVAL-L7983ADJ

Synch. buck up to 60 Vin, 12 Vout - 0.3 A Iout



STEVAL-L6986IV1

38 V, 5 W synchronous iso-buck converter



STEVAL-1PS03A

Synch. Buck with Load Switch, 5.5 Vin, Dynamic Voltage Selection up to 3.3 V - 400 mA

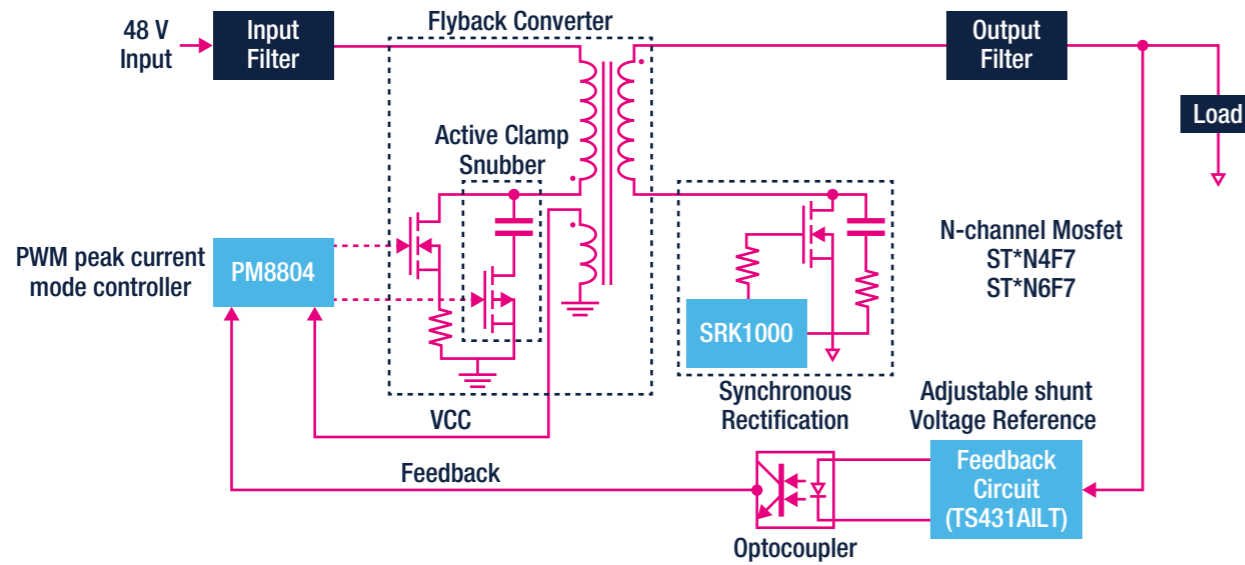


STEVAL-L3751V12

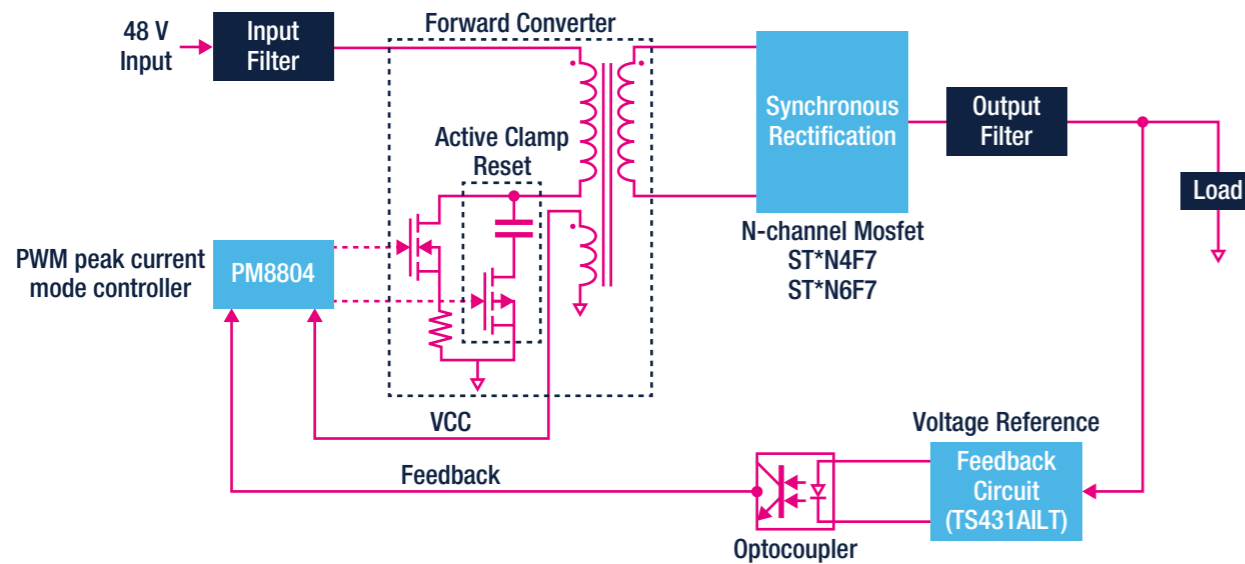
75 V 15 A DC-DC converter buck regulator

Note: * is used as a wildcard character for related part number

Typical 48 Vin, up to 65 W Pout, Synchronous Flyback configuration



Typical 48 Vin, > 65 W Pout, Active Clamp Forward configuration

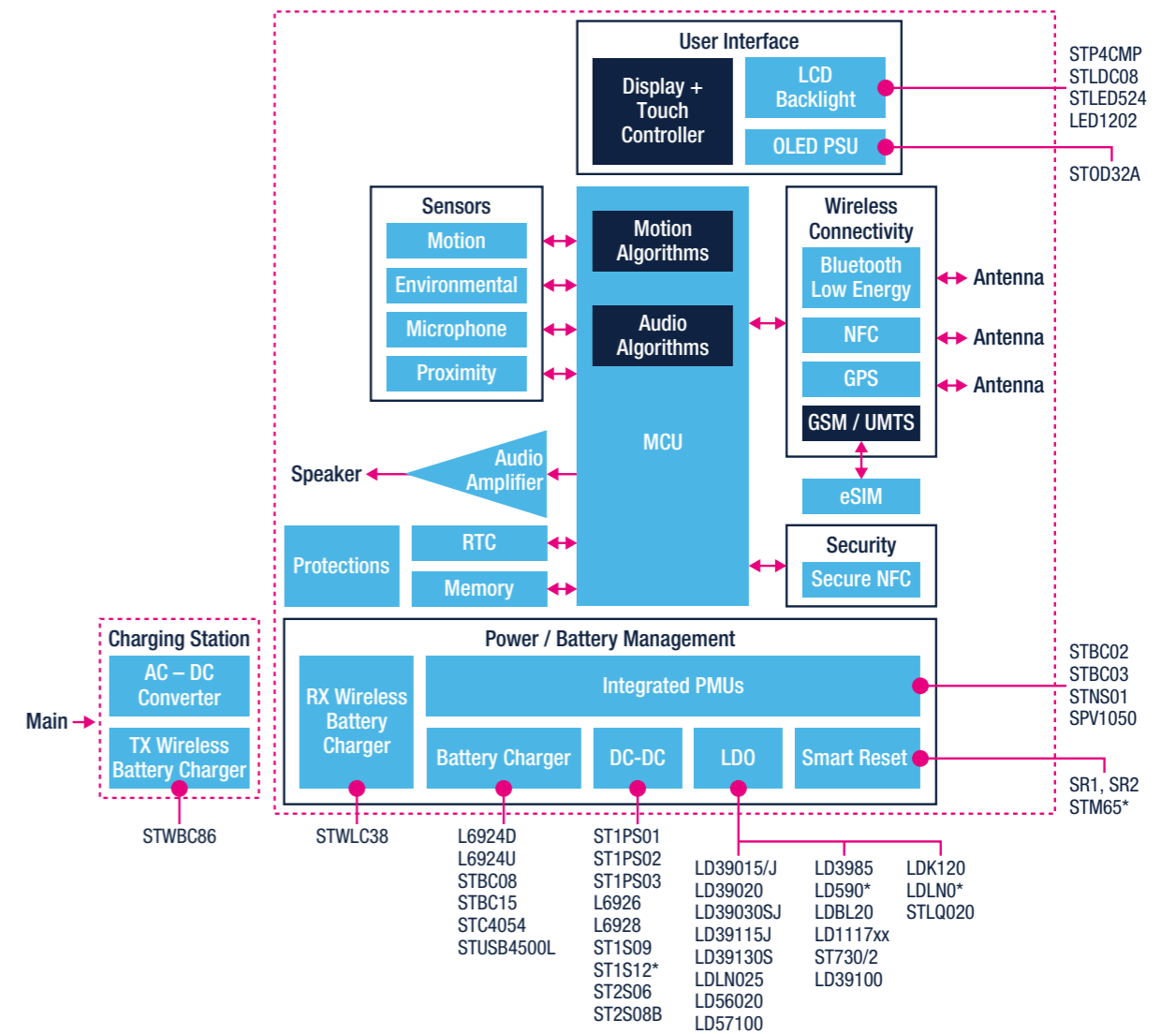


WEARABLE DEVICES - POWER MANAGEMENT

Wearable devices, by their very nature, must be compact and comfortable for the user. They need to deliver precise information about user states and conditions, have low power consumption, and the right level of performance to make them convenient and easy to use. ST products for wearable devices are designed to meet the needs of the most demanding systems with a portfolio covering smart watches, fitness trackers, heart-rate monitors, sports equipment, and a variety of other wearable devices. Our portfolio includes digital processing, sensors, connectivity, security, and power management solutions that can make the difference in a challenging and competitive market.

Specifically for power management, ST provides a range of solutions to allow very small form factor with outstanding efficiency performance and longer battery life.

Typical Block Diagram of a Smart Watch



Main evaluation boards



STEVAL-ISA203V1

- Input Voltage range: 42 - 56 V DC
- Switching Frequency - 250 kHz
- Output:
- Power - 60 W
- Voltage - 12 V DC
- Current - 5 A
- Peak Efficiency > 94%



STEVAL-ISA204V1

- Input Voltage range: 42 - 56 V DC
- Switching Frequency - 250 kHz
- Output:
- Power - 100 W
- Voltage - 5 V DC
- Current - up to 20 A
- Peak Efficiency > 94%

Note: * is used as a wildcard character for related part number

Main application boards and reference designs



STEVAL-1PS01AJR/DJR/EJR

Evaluation board based on the ST1PS01 400 mA nano-quiescent synchronous step-down converter with digital voltage selection



STEVAL-1PS02B

Evaluation board based on the ST1PS2 400 mA nano-quiescent synchronous step-down converter with digital voltage selection and AUX switch



STEVAL-1PS03A

Evaluation board based on ST1PS03AQR 400 mA nano-quiescent synchronous step-down converter with load switch



STEVAL-LDO001V1

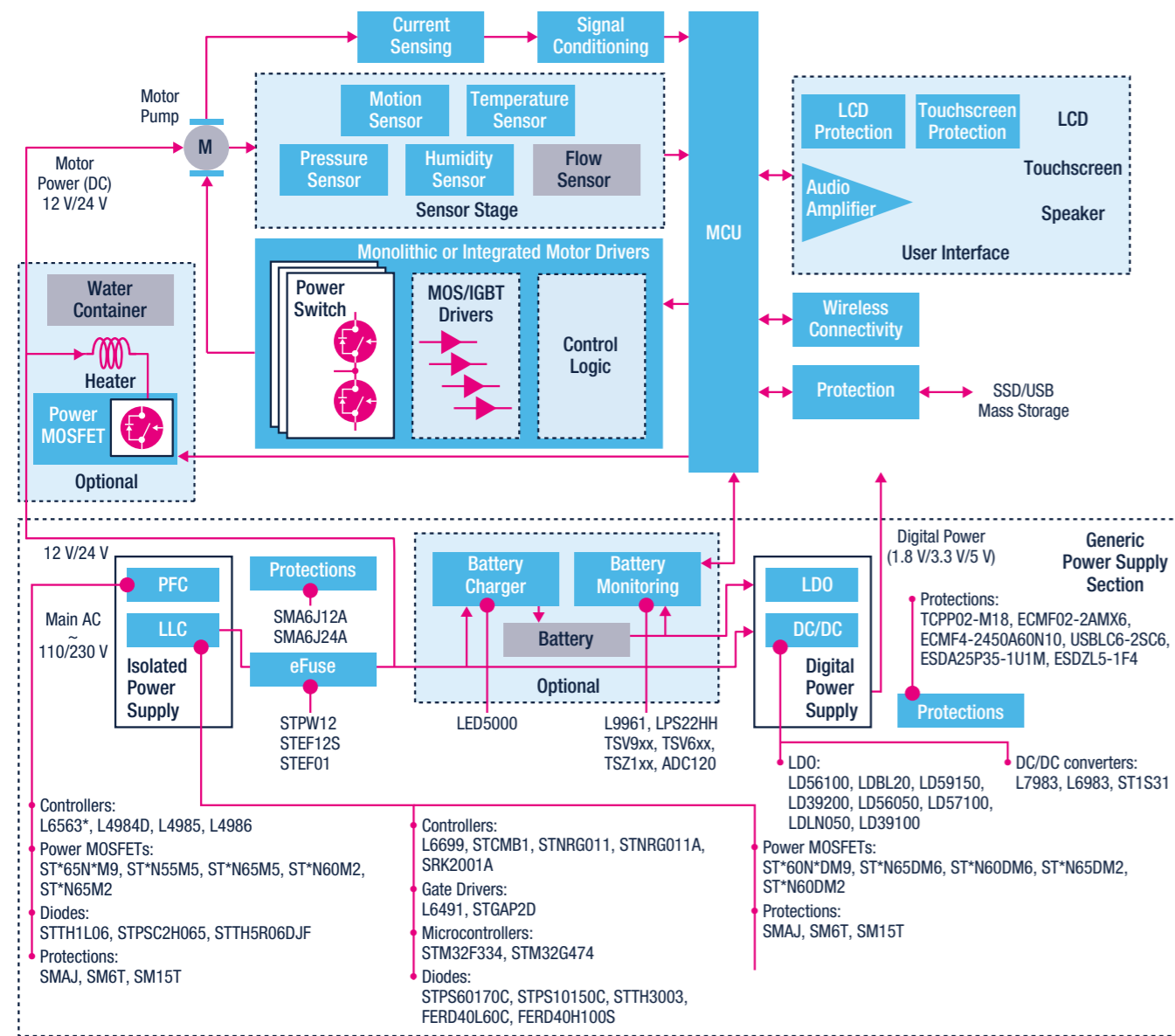
Quad high performance LDO evaluation board based on LDL20, LDLN025, LD39130S and STLQ020

Note: * is used as a wildcard character for related part number

MEDICAL POWER SUPPLY

The mission critical nature of medical devices demands high quality, reliable, and safe products. Our goal is to consistently deliver products that meet this criteria and help our customers meet this goal. Medical power supplies are a crucial part of the equipment, usually you with open frame, enclosed, fanless, and configurable models, as well as wall-mount adapters and DC-DC modules. Often, the backup battery is part of the power supply to guarantee continuity of operation when the main supply is interrupted.

Typical Block Diagram of a Medical Power Supply for Artificial Ventilators



Main application boards and reference designs



EVL6563S-100W
100 W transition-mode PFC pre-regulator



EVLSTNRG011-150
12 V - 150 W power supply based on TM PFC and HB LLC digital combo controller



STEVAL-L7983ADJ
12 V/0.3 A step down DC/DC converter (VIN = 12 to 60 V)

Note: * is used as a wildcard character for related part number



LED LIGHTING AND CONTROLS

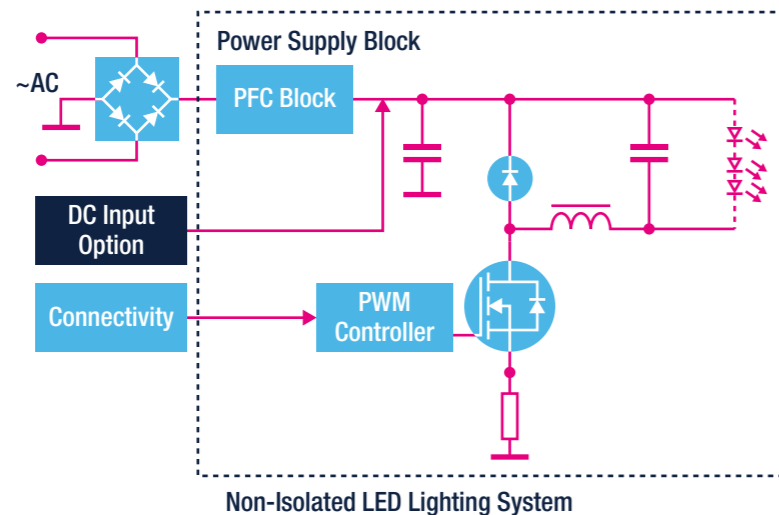
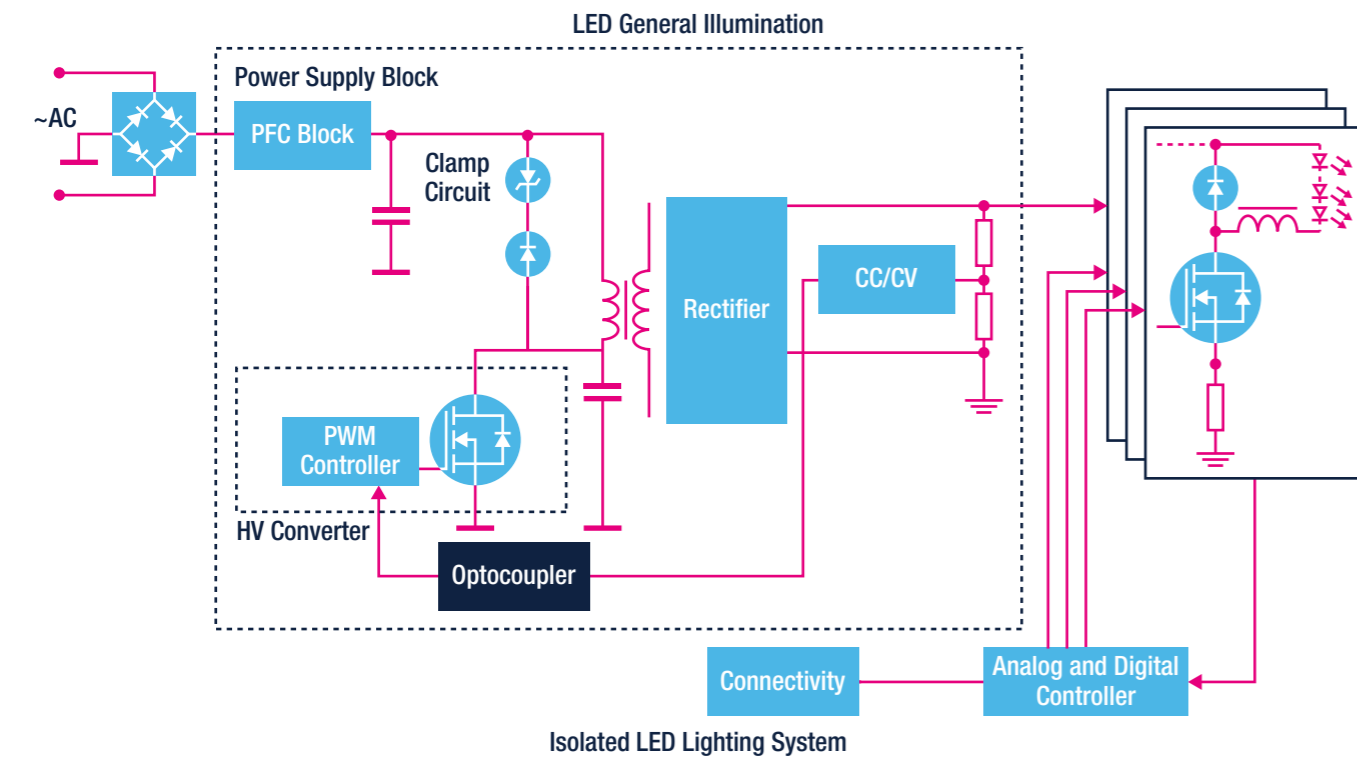
LED General Illumination

LED lamps and bulbs can have a number of different form-factors, depending on the specific use, size, and dimensions of the application, including retrofit bulbs, high-bay lights, low-bay lights and emergency lights. Driving a string of LEDs involves AC-DC and DC-DC conversion designed using non-isolated, isolated, single stage or multi-stage topologies, which must ensure high efficiency and reliability at a competitive cost point.

Modern applications include a range of connectivity features to implement remote monitoring and control, making LED lighting a pillar of smart home, smart building and smart city environments. ST portfolio includes a variety of RF transceivers, wireless MCUs, network processor ICs and fully certified modules for key wireless connectivity technologies. Our embedded software for BLE Mesh enables mesh networking of connected smart lighting end products.

For the LED driving stage, we have a range of pulse-width modulation (PWM) and power factor correction (PFC) controllers, power MOSFETs and diodes, as well as a comprehensive set of hardware evaluation and development tools, including reference designs to help developers design high-efficiency LED lighting solutions.

Typical Block Diagram



ST product offering for LED General Illumination

	Controllers	Power MOSFETs	Diodes	MOSFET and IGBT Gate Drivers
PFC Block	TM Analog Controllers L6562*, L6563*, L6564* CCM Analog Controllers L4985, L4986, L4981*, L4984D MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STLUX, STNRG388A	650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 800 V MDmesh K6 ST*80*K6 800 V to 1200 V MDmesh K5 ST*80K5, ST*9*K5, ST*105K5, ST*120K5 650 V SiC MOSFETs SCT**65G3AG, SCT*N65G2	600 V Ultrafast for TM STTH*L06, STTH*06, STTH15AC06* 600 V Ultrafast for CCM STTH*R06, STTH*T06 SiC Diodes STPSC*065	Single LS Gate Drivers PM88*1 Multiple LS Gate Drivers PM8834
Isolation Stage	Controllers & Converters Offline LED Drivers HVLED101, HVLED001A/B, HVLED007, HVLED8* HV Converters VIPer0P, VIPer*1, VIPer*6, VIPer122, VIPer222, VIPer*5, VIPer*7, VIPer*8 LLC Analog Controllers L6599*, L6699 PFC & LLC/LCC Combo Controllers STCMB1, STNRG011, STNRG011A, STNRG012 MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STM8S, STLUX, STNRG388A SR Analog Controllers SRK1000, SRK1001 for Flyback SRK2000A, SRK2001, SRK2001A for LLC	Power MOSFETs 600 V MDmesh DM9 ST*60N*DM9 600 V MDmesh DM6 ST*60DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 950 V MDmesh DK5 ST*95DK5 650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 800 V MDmesh K6 ST*80*K6 800 V to 950 V MDmesh K5 ST*80K5, ST*9*K5 60 V-100 V STripFET F7 ST*N6F7, ST*N8F7, ST*N10F7 Integrated Smart GaNs 600 V MASTERGAN*	Diodes & Discretes Clamping Diodes for Flyback 600 V to 1000 V Ultrafast STTH*06, STTH*08, STTH*10 Output Diodes for Flyback Schottky, FERD, Ultrafast STPS*, FERD*, STTH* Output Diodes for LLC/LCC Schottky, FERD STPS* FERD*45, FERD*50, FERD*60, FERD*100 MOSFET Protection for Flyback SMAJ, SM6T, SM15T series SCR protection switch TNx015H-6"	Voltage Reference, CC/CV Ctrl Voltage Reference T*431, T*432 Voltage and Current Ctrl TSM*, SEA05* Signal Conditioning TSB*, TSX*, TSV* MOSFET and IGBT Gate Drivers HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* Multiple LS Gate Drivers PM8834
Multiple strings management	Offline LED Drivers HVLED002 MCUs & Digital Controllers STM32F0, STM32G0, STM32F334, STM32G4, STM8S, STLUX, STNRG388A	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 STripFET F7 ST*N4F7, ST*N6F7, ST*N10F7	Schottky Diodes STPS* FERD Diodes FERD* ≥ 200 V Ultrafast Diodes STTH* DC-DC LED Drivers LED5000, LED6000, ST1CC40, LED2000, LED2001	HV HB Gate Drivers L649*, L6395 Single LS Gate Drivers PM88*1 Multiple LS Gate Drivers PM8834
Wireless Connectivity	Bluetooth Low Energy (BLE MESH) BLE 5.2 SoC BlueNRG-1, BlueNRG-2 BlueNRG-LP, BlueNRG-LPS BLE Network Processor BlueNRG-2N Baluns BALF-NRG-0*D3, BALF-NRG-02J5 Dual core MCUs BLE 5.2 STM32WB IPD (Integrated Passive Device) MLPF-WB55-01E3, MLPF-WB55-02E3		2.4 GHz Multi Standard (ZigBee, Thread, 802.15.4) BlueNRG Modules BlueNRG-M0 BlueNRG-M2 STM32 Wireless Module STM32WB5MMG	Sub-1GHz Sub-1GHz Wireless MCU STM32WL Sub-1GHz Transceivers S2-LP, SPIRIT1 MCUs STM32F0, STM32G0, STM32L0 Baluns BALF-SPI-0*D3, BALF-SPI2-0*D3

Main application boards



EVLHVLED007W35F

35 W LED driver with very low THD, based on Transition Mode Flyback converter (CVout)



EVAL-PSR01B-35W

35 W LED Driver with very high efficiency based on QR flyback converter with PSR (CVout)



EVAL-SSR01B-35W

35 W LED Driver with very high efficiency based on QR flyback converter with SSR (CC /CV)



EVAL-IBD002-35W

35 W Inverse buck with LED current control and with Analog/PWM dimming



STEVAL-LLL012V1

Smart LED driver with high power factor using BLE Mesh network for indoor lighting



STEVAL-ILL078V1

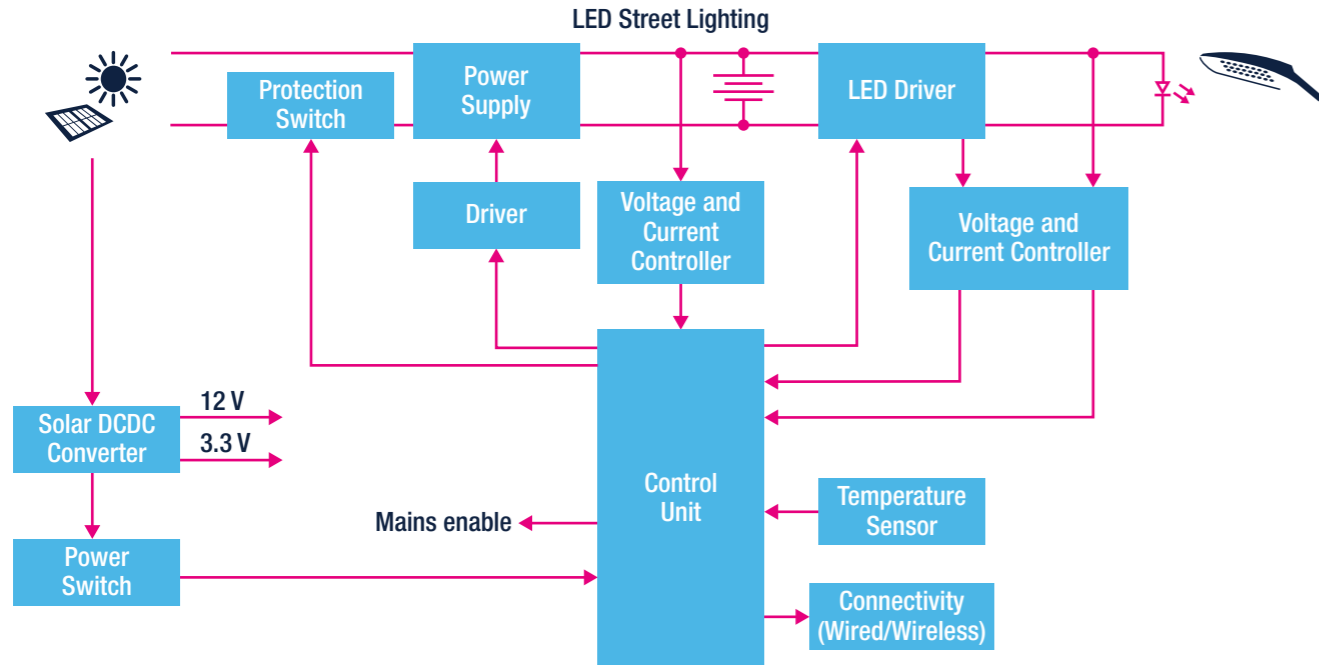
1A, up to 60 V Vin, buck LED driver with digital dimming

LED Street Lighting

Street lighting installations have evolved from basic energy-hungry illumination spots to central devices enabling a set of services, such as presence and traffic-level monitoring and incident-detection surveillance, while optimizing illumination levels to specific road and weather conditions to support administrations in transforming cities in smart cities.

We have a broad range of wired and wireless connectivity, power management, and LED driving solutions. A range of high-performance and low-power STM32 microcontrollers, together with presence, proximity, camera, and environmental sensors, as well as MEMS microphones, enable design of advanced street lighting systems.

Typical Block Diagram



ST product offering for LED Street Lighting

	Controllers	Power MOSFETs	Diodes & Protections	MOSFET and IGBT Gate Drivers
Power Supply	TM PFC Analog Controllers L6562*, L6563*, L6564* CCM PFC Analog Controllers L4985, L4986, L4981*, L4984D Offline LED drivers HVLED101, HVLED001B, HVLED001A, HVLED007 PFC & LLC/LCC Combo Controllers STCMB1, STNRG011, STNRG011A, STNRG012 LLC/LCC Controllers L6599A*, L6699 MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STLUX, STNRG388A SR Analog Controllers SRK1000, SRK1001 for Flyback SRK2000A, SRK2001, SRK2001A for LLC	600 V MDmesh DM9 ST*60N*DM9 600 V MDmesh DM6 ST*60DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 800 V MDmesh K6 ST*80*K6 950 V MDmesh DK5 ST*95DK5 800 V to 1050 V MDmesh K5 ST*80K5, ST*9*K5, ST*105K5 650 V SiC MOSFETs SCT**65G3AG, SCT*N65G2 60 V-100 V STripFET F7 ST*N6F7, ST*N8F7, ST*N10F7	600 V Ultrafast for TM PFC STTH*L06, STTH*06, STTH15AC06* 600 V Ultrafast for CCM PFC STTH*R06, STTH*T06 SiC Diodes STPSC*065 Output Diodes for Flyback Schottky, FERD, Ultrafast STPS*, FERD*, STTH* Clamping Diodes for Flyback 600 V to 1000 V Ultrafast STTH*06, STTH*08, STTH*10 Output Diodes for LLC/LCC Schottky, FERD STPS*, FERD*45, FERD*50, FERD*60, FERD*100 MOSFET Protection for Flyback SMAJ, SM6T, SM15T series SCR protection switch TNx015H-6	HV HB Gate Drivers for GaNs STDRIVE6600 Single LS Gate Drivers PM88*1 Multiple LS Gate Drivers PM8834 HV HB Gate Drivers L649* Isolated Gate Drivers STGAP*
	GaN Power ICs Integrated Smart GaNs 600 V MASTERGAN*	Voltage Reference, CC/CV Ctrl Voltage Reference T*431, T*432 Voltage and Current Ctrl TSM*, SEA05*	Signal Conditioning TSB*, TSX*, TSV*	
LED Driver	Offline LED drivers HVLED002	DC-DC Buck LED Drivers LED5000, LED6000, ST1CC40, LED2000, LED2001	DC-DC Boost LED Drivers LED6001, LED7707, LED7708	LED Array Drivers STP04/08/16/24, STCS*, LED8102S
Sensing, Processing, Control, LED Bypass	Temperature Sensors STLM20 STTS751 LM135Z	Control Unit MCUs STM32F0, STM32G0	Protection Switch 60 V-100 V STripFET F7 ST*N6F7, ST*N8F7, ST*N10F7	Diodes & Discretes LBP01
	Wired - Power Line Communication Power Line Transceivers ST7570, ST7580	Wireless - Sub-1GHz Sub-1GHz Wireless MCU STM32WL Sub-1GHz Transceivers S2-LP, SPIRIT1 MCUs STM32F0, STM32G0, STM32L0 Balun BALF-SPI-0*D3, BALF-SPI2-0*D3	Wireless - Sigfox Sub-1GHz Wireless MCU STM32WL Sub-1GHz Transceivers S2-LP MCUs STM32L0, STM32L4 Baluns BALF-SPI2-01D3 Secure MCUs STSAFE-A100	Wireless - LoRa LoRa Wireless MCU STM32WL Embedded Software I-CUBE-LRWAN Secure MCUs STSAFE-A100

Note: * is used as a wildcard character for related part number

Main application boards



EVLIMG4-500WIBUCK
High power inverse buck for dimmable LED application with GaN



EVL012V
200 W LED Driver (CC/CV) with digital combo controller



STEVAL-LLL004V1
75 W AC-DC digitally controlled non isolated constant current LED driver



EVL80WLED-STCH03
80 W - 1 A primary side current loop control LED driver based on QR flyback converter



EVL150W-HVSL
150 V - 1 A LED driver featuring TM PFC and LCC resonant converter with analog combo controller



EVL6699-HVSL
150 V - 1 A LED driver featuring TM PFC and LCC resonant converter with L6699



STEVAL-ILL066V2
100 W LED street lighting with DALI2.0 communication interface using the STLUX385A digital controller



STEVAL-ILL053V2
48 V - 130 W high efficiency converter with PFC for LED street lighting



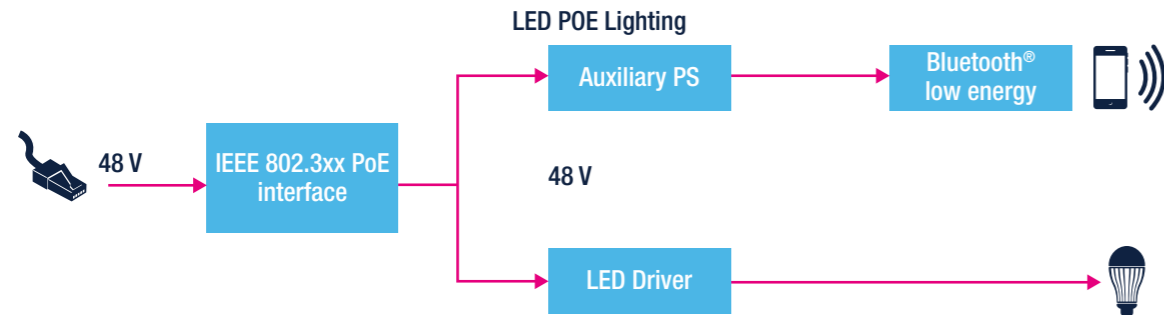
LED POE Lighting

Power over Ethernet (PoE) is a widely adopted technology used to supply a powered device (PD) over an RJ-45 cable while carrying data. Described in the IEEE 802.3 standard and its enhancements including IEEE 802.3bt, IEEE 802.3at and IEEE 802.3af, this technology is becoming attractive for LED lighting.

We have a range of products providing a complete interface with all the functions required by the communication standard, including detection and classification, protection features such as under-voltage lockout (UVLO) and in-rush current limitation, as well as the control of hot-swap power MOSFETs that can greatly simplify the development of IEEE 802.3 compliant solutions for powered devices (PD). We also have high-efficiency and optimized DC-DC conversion solutions for supplying LEDs.



Typical Block Diagram



ST product offering for LED PoE Lighting

PoE Interface	Protections	Auxiliary Power Supply	LED Driver		Bluetooth LE
IEEE 802.3bt PM8805	TVS for Power Rail Surge Protection SMAJ, SM15T	Buck Converter L7983 L7987L	Buck	60 V-100 V StripFET F7 ST*N6F7, ST*N8F7, ST*N10F7	Bluetooth Low Energy SoC, Wireless MCUs, Modules BlueNRG-*, STM32WB*
IEEE 802.3at PM8803			LED6000, LED5000	Schottky Diodes STPS*	
IEEE 802.3af PM8800A			Inverse Buck HVLED002		

Note: * is used as a wildcard character for related part number

Lighting Controls

Lighting controls have evolved from simple triac dimmers to more sophisticated architectures, including light sensors, digital and PWM dimmers, DALI network-based systems, and wireless programming solutions.

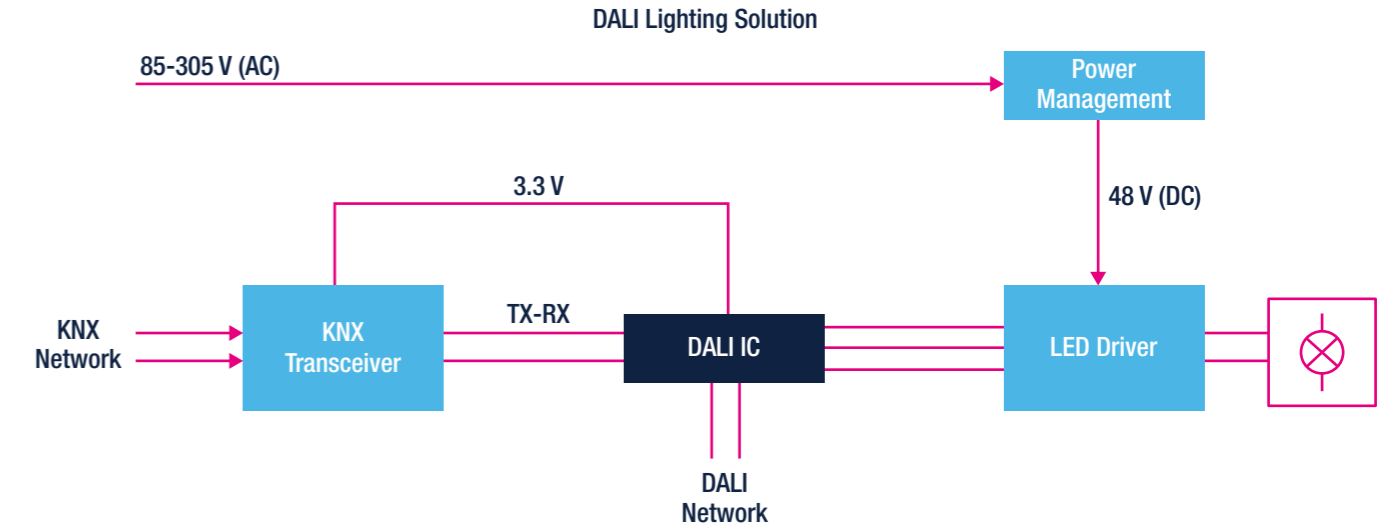
ST long-term partnerships with major lighting suppliers combined with our leadership in discrete and integrated power devices enable us to offer high efficiency and cost-optimized solutions for all types of lighting applications and their control, both wired (e.g. Powerline) or wireless (RF), for industrial, residential, commercial, and architectural lighting applications.

DALI Lighting Solution

Digital Addressable Lighting Interface (DALI) is a trademark for a network-based technology used to effectively control lighting in building automation. Originally defined in IEC 60929 standards, it has been updated for IEC 62386, which includes LED device types.

We provide a range of analog and digital controllers, including the STLUX family and the STM32 microcontrollers to implement the AC-DC and DC-DC power converter and run the DALI protocol.

Typical Block Diagram for DALI Lighting System



ST product offering for Lighting Controls

LED Driver		Power Management	KNX Transceiver
Digital Controllers STLUX	MCUs STM32F1, STM32L1, STM8	Refer to LED General Illumination section	TVS Protection on KNX Bus SMAJ40CA-TR
Development Tools STSW-STLUXLIB02, STSW-STLUXSMED02	Embedded Software STSW-DALI002, STSW-DALI001, STSW-STM8025		STKNX

Main application boards



STEVAL-POEL45W1
45 W PoE powered LED lighting with BLE control



STEVAL-ILL078V1
1 A, up to 60V Vin, buck LED driver board based on the LED6000



STEVAL-ILL056V1
3 A Buck LED driver board based on the LED5000

Main application boards



STEVAL-ILL066V2
100 W LED street lighting evaluation board with DALI2.0 communication interface using the STLUX385A digital controller



STEVAL-ILM001V1
Plug-in hardware module for the STM8S-DISCOVERY interface for DALI communication



EVALKITSTKNX
Miniature transceiver STKNX evaluation and development kit

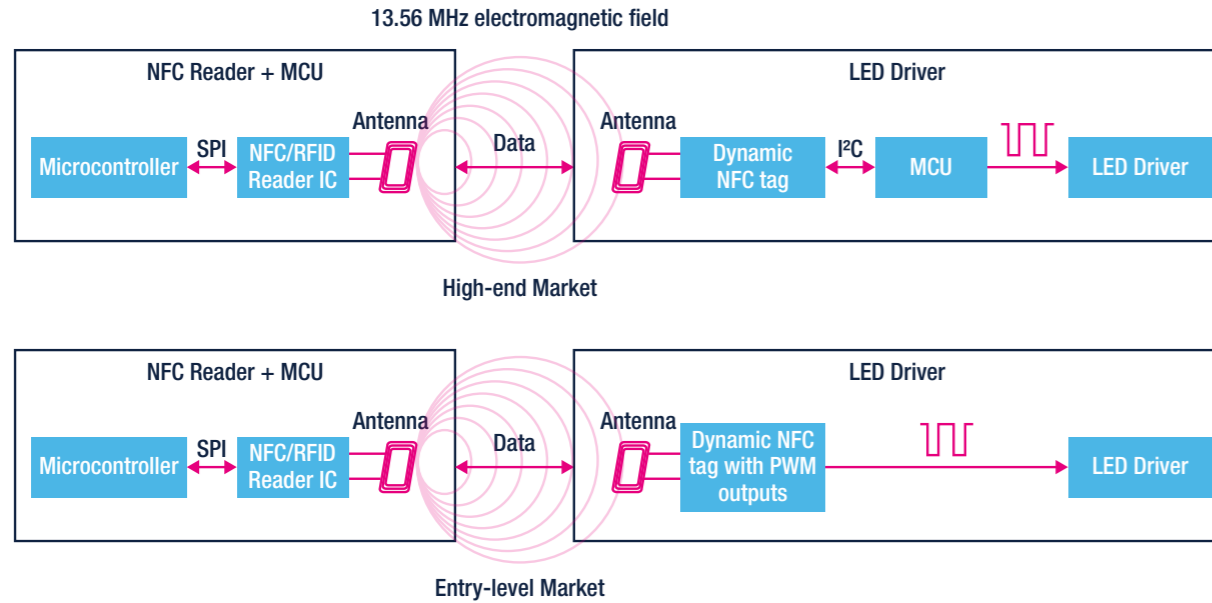
LED Wireless Programming

Today's smart LED bulbs let users control features including brightness and color. These properties are controlled through the driver and can be programmed and modified at any time during manufacturing, distribution, installation, or maintenance.

The use of NFC technology enables wireless programming using a smartphone, tablet, or portable RFID/NFC reader, without having to power up the LED driver and brings enhanced flexibility and energy savings in addition to reducing development time and cost.

STMicroelectronics offers optimized and complete LED driver programming solutions with its comprehensive NFC portfolio, fully addressing the lighting market and featuring all the functions needed for wireless LED programming.

Typical Block Diagram of LED Wireless Programming



ST product offering for LED Wireless Programming

	NFC/RFID Reader IC	Protections	Microcontrollers
NFC Reader + MCU	ST25R	Antenna Protection Reader: ESDZV18-1BF4 Tag: USBULC6-2M6	STM8S STM32F0, STM32G0
	Dynamic NFC Tag		MCUs and Digital Controllers
LED Driver for high-end market	ST25DV-I2C Series		STM8S STM32F0, STM32G0 STM32F3, STM32F334, STM32G4 STLUX
	Dynamic NFC Tag with PWM Output		LED Driver
LED Driver for entry-level market	ST25DV-PWM Series		HVLED101, HVLED001*, HVLED002 LED600*, LED5000, LED2000 STP04/08/16/24, LED12/16/24*, LED8102S

Note: * is used as a wildcard character for related part number

Main application boards



ST25R3911B-DISCO
Discovery kit for ST25R3911B high performance HF reader/NFC



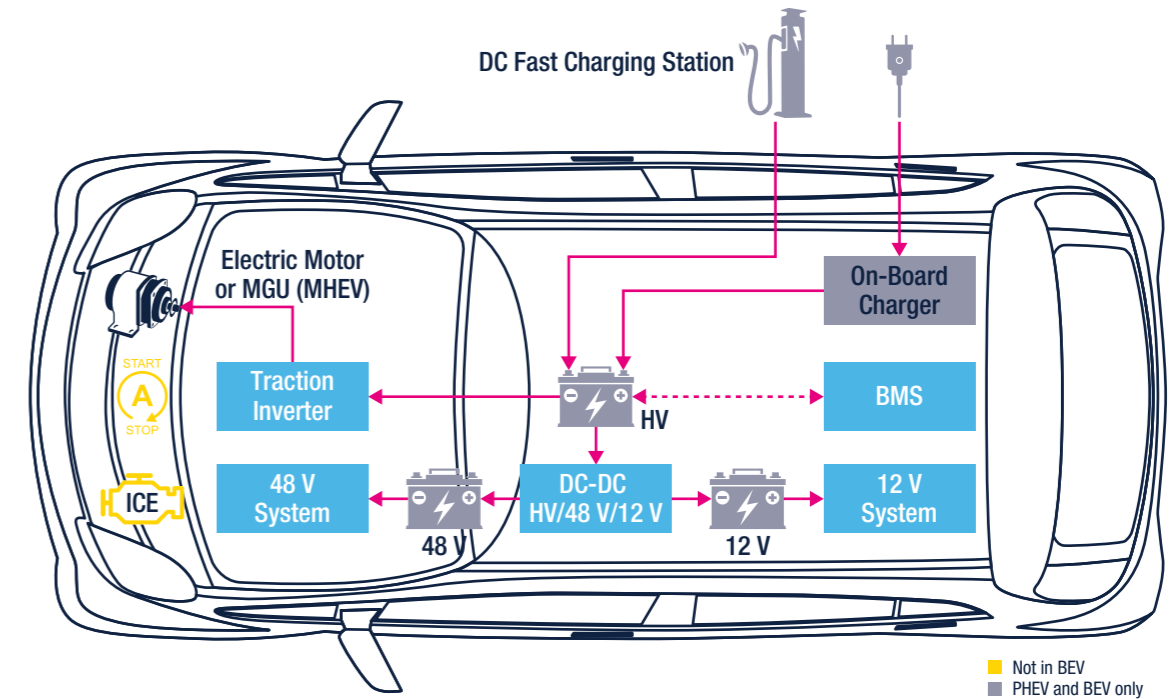
ST25DV-PWM-eSET
Discovery kit for the ST25DV-PWM NFC/RFID tag IC



ST25DV64KC-DISCO
Discovery kit for the ST25DV64KC dynamic NFC/RFID tag

ELECTRO-MOBILITY

Key applications



■ Not in BEV
■ PHEV and BEV only

Solutions

ST key products and solutions for Electro-Mobility applications include:

SiC MOSFETs and Diodes	Transceivers	Signal Conditioning	Power Management	32-bit Automotive Microcontrollers
Power MOSFETs and IGBTs	Power Diodes and thyristors	EOS and ESD Protection	BCD Integrated and Isolated Drivers	
HW & SF Development Tools – Sample Kits, Evaluation Kits, Product Selectors				



FIND OUT MORE

www.st.com/electro-mobility

Battery Management System (BMS)
Charging Station
DC-DC Converter
Small Electric Vehicles
Electric Traction (Main Inverter)
Mild Hybrid 48 V Systems

On Board Charger (OBC)
Acoustic Vehicle Alerting System (AVAS)
HV Battery Disconnect & Fire-off System
Vehicle Control Unit (VCU)

Main Traction Inverter

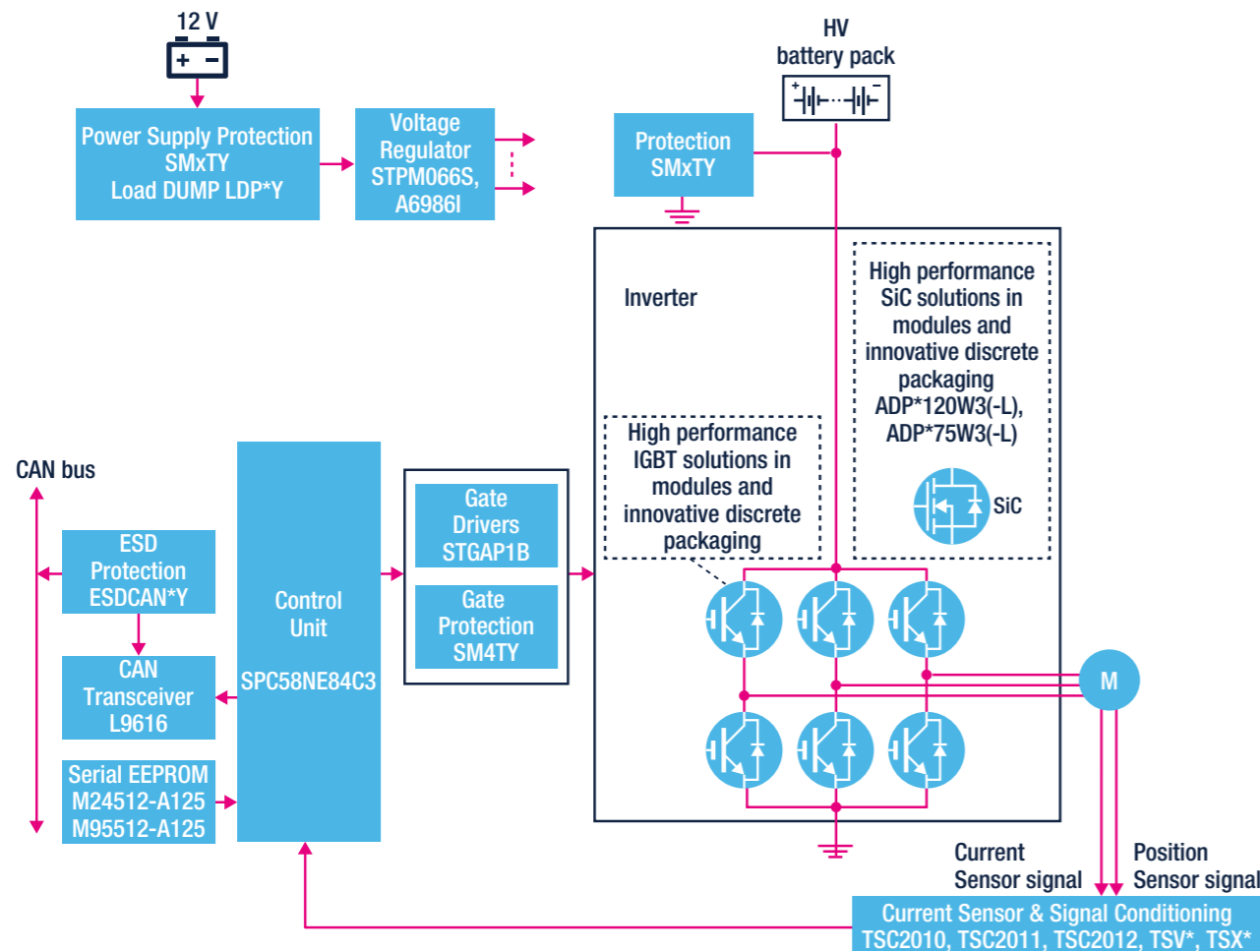
The traction inverter converts energy from the vehicle battery to drive the electrical engine. This key component has a direct impact on vehicle road performance, driving range, and reliability, which also depends on inverter weight and size.

Subject to all the possible stress found in a road vehicle from heat and vibrations, these converters must be able to handle high power and current along with the associated Electro Magnetic Compatibility (EMC) challenges, as well as provide fail-safe operation to ensure reliability and safety for the driver and passengers.

To help developers increase inverter power efficiency and reduce size and weight, ST has a wide portfolio of discrete semiconductors, including AEC-Q101 qualified silicon and silicon carbide (SiC) MOSFETs and diodes, as well as IGBTs. These are complemented by AEC-Q100 qualified galvanically isolated IGBT and MOSFET gate drivers and SPC5 32-bit automotive microcontrollers for implementing scalable, cost-effective, and energy-efficient solutions. Furthermore, ST offers a compact and high-power-density solutions with the 750V and 1200V ACEPACK DRIVE power modules based on SiC Gen3 technology.



Typical Block Diagram - Main Inverter



Note: * is used as a wildcard character for related part number



FIND OUT MORE

www.st.com/main-inverter-electric-traction

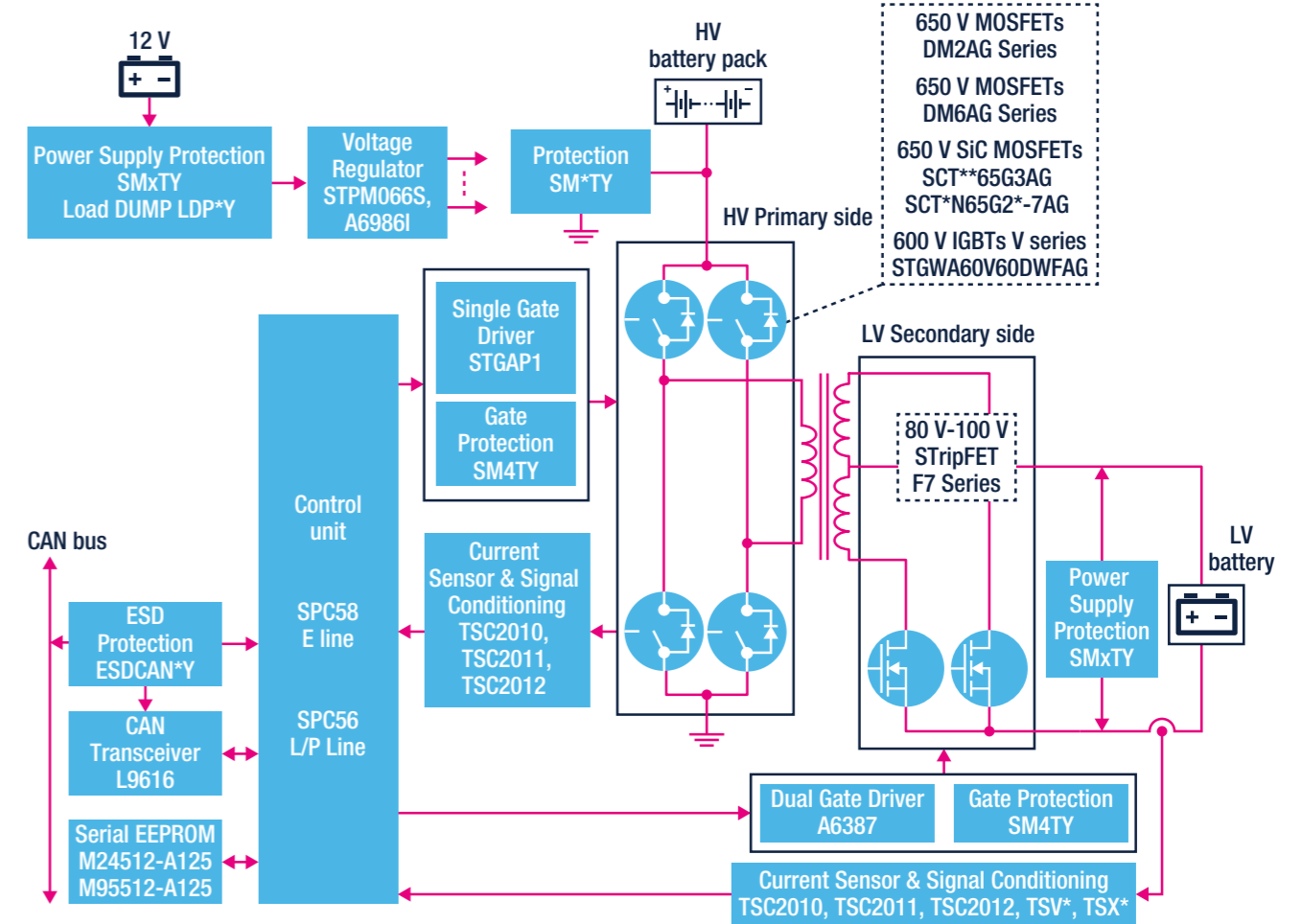
Bidirectional DC/DC Converter

Electric vehicles (EV) use two different power systems, a high-voltage battery (200 to 800 V_{DC}) for traction and a low-voltage (12/48 V) one for supplying all the electric appliances in the vehicle. Traditionally, the low-voltage battery was charged from the alternator, but in today's vehicles, it gets its power from the high-voltage battery pack. However, in specific electric car architectures, this low-voltage battery should be ready to help recharge the high-voltage battery pack in order to provide energy for cranking the car. This means that the on-board DC-DC converter must be bidirectional and very efficient, as well as highly reliable in order to run the complex control algorithms needed to ensure an energy-efficient solution.

ST has a wide offer of discrete semiconductors including AEC-Q101 qualified silicon and silicon carbide (SiC) MOSFETs and diodes, as well as IGBTs. These are complemented by AEC-Q100 qualified galvanically isolated IGBT and MOSFET gate drivers and SPC5 32-bit automotive microcontrollers to enable scalable, cost-effective, and energy-efficient solutions for implementing these challenging converters.



Typical Block Diagram - Bidirectional DC/DC Converter



Note: * is used as a wildcard character for related part number



FIND OUT MORE

www.st.com/bidirectional-dc/dc-converter

48 V Start-Stop System

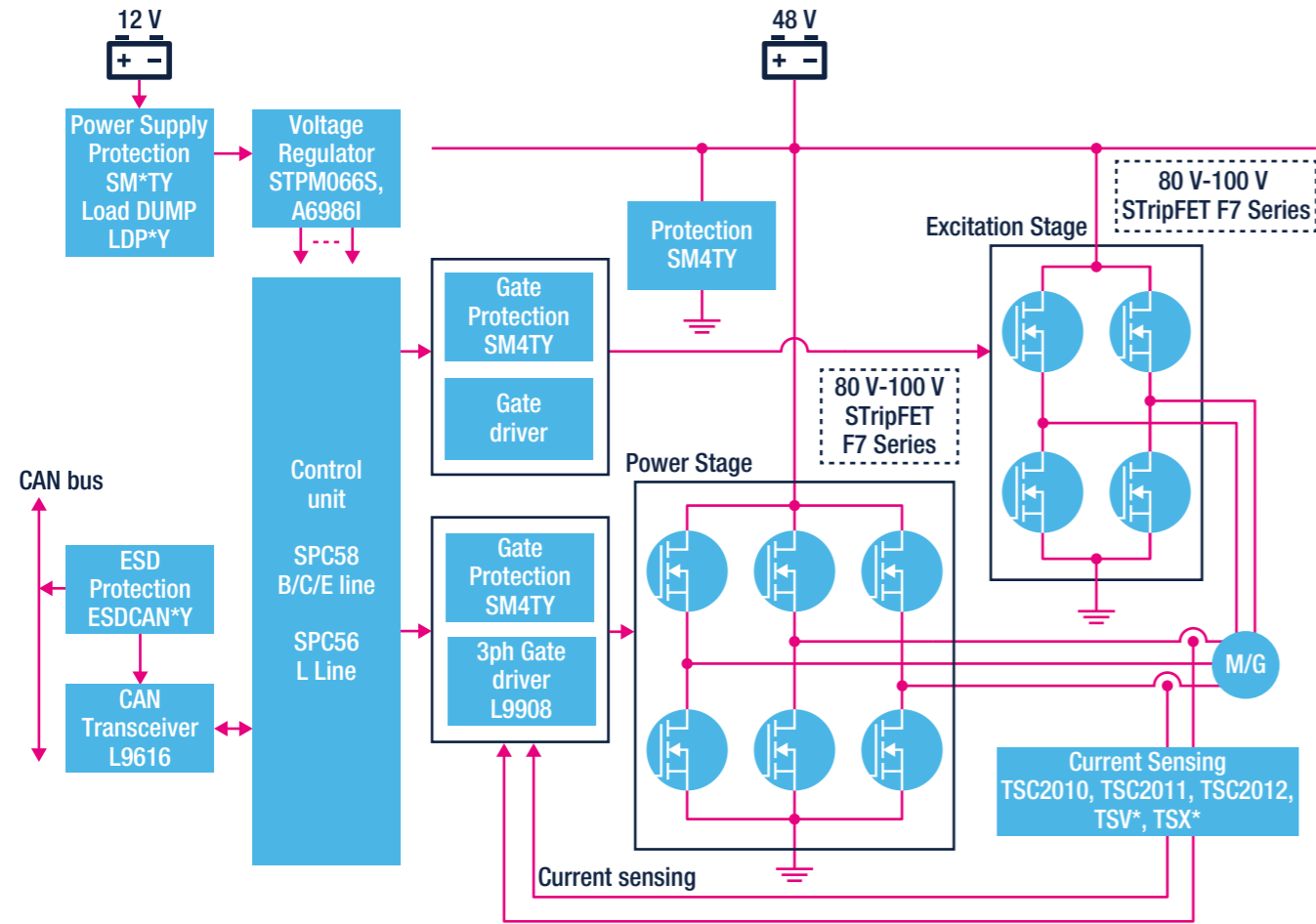
A start-stop system aims at reducing the amount of engine idle time by shutting down and restarting the internal combustion engine automatically when the vehicle stops. Thus, it contributes to improving fuel economy and reducing CO2 emissions. This is especially useful in urban environments where vehicles can spend significant amounts of time in traffic.

Start-stop operations require power electronics that can handle high current during cranking and ensure reliability during start-stop cycles, operating on/off at high temperatures.

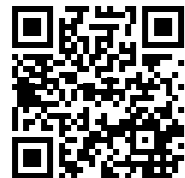
ST solutions include silicon power MOSFETs, protections, gate drivers, and microcontrollers in accordance with AEC-Q100 and AEC-Q101 standards.



Typical Block Diagram - Start-Stop system



Note: * is used as a wildcard character for related part number



FIND OUT MORE

www.st.com/48v-start-stop-system

On-Board Charger (OBC)

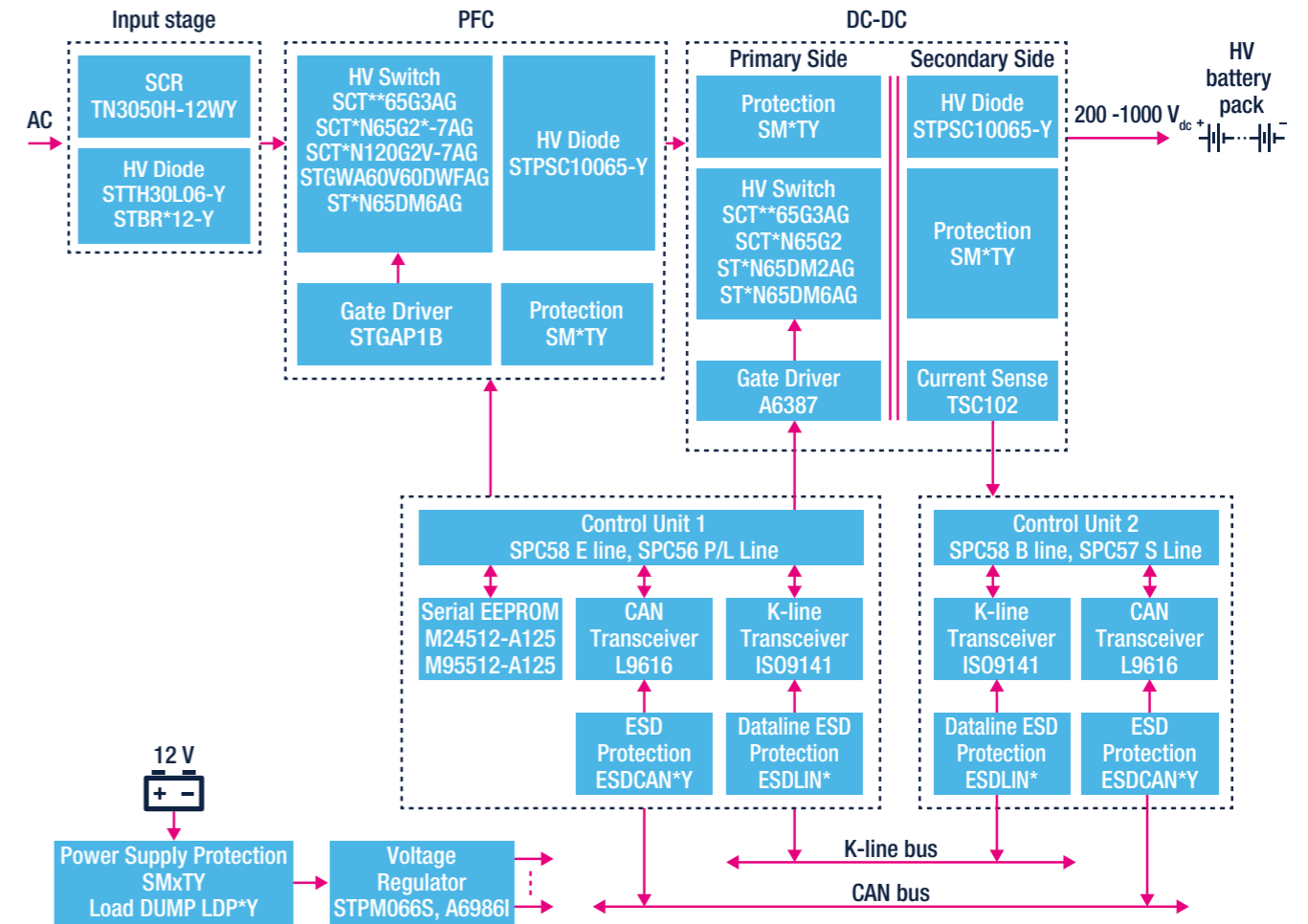
At the heart of any electric (EV) or plug-in hybrid (HEV) vehicle lies the high-voltage (200 to 800 Vdc) battery and its associated charging system. The on-board charger (OBC) provides the means to recharge the battery from the AC mains either at home or from outlets found in private or public charging stations.

From a 3.6 kW single-phase to a 22 kW three-phase high-power converter, today's OBCs must have the highest possible efficiency and reliability to ensure rapid charging times, as well as meet the limited space and weight requirements.

ST has a wide offer of discrete semiconductors, including AEC-Q101 qualified silicon and silicon-carbide (SiC) MOSFETs and diodes, as well as IGBTs. These are complemented by AEC-Q100 qualified galvanically isolated IGBT and MOSFET gate drivers and SPC5 32-bit automotive microcontrollers for implementing these challenging converters.



Typical Block Diagram - OBC



Note: * is used as a wildcard character for related part number



FIND OUT MORE

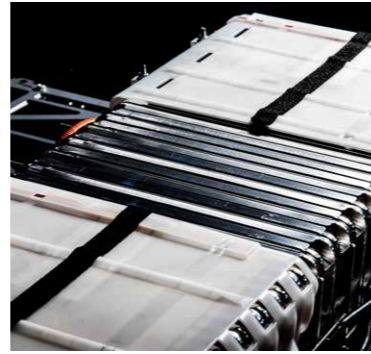
www.st.com/on-board-charger

Battery Management

Automotive Battery Management System (BMS) must be able to meet critical features such as voltage, temperature and current monitoring, battery state of charge (SoC), and cell balancing of lithium-ion (Li-ion) batteries.

Indeed, the main functions of a Battery Management System for electric vehicles are:

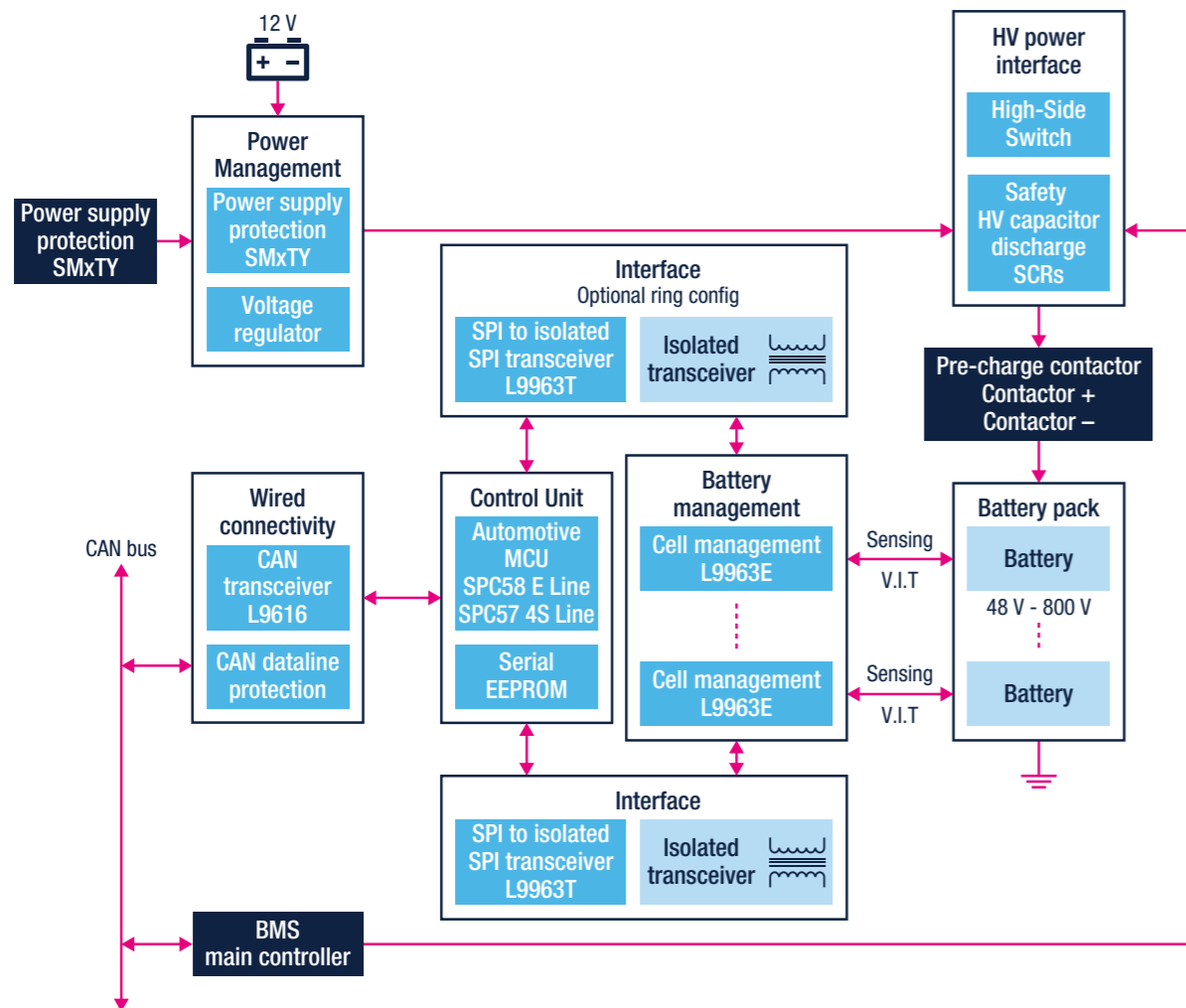
- **Battery protection** in order to prevent operations outside its safe operating area
- **Battery monitoring** by estimating the battery pack state of charge (SoC) and state of health (SoH) during charging and discharging
- **Battery optimization** thanks to cell balancing that improves the battery life and capacity, thus optimizing the driving range for hybrid (HEV), plug-in (PHEV) and full electric vehicles (BEV)



A discharge circuit is present using a HV Power MOSFET (MDmesh K5) working in linear mode to discharge the battery in case of malfunctioning or accident.

ST25R NFC Reader and ST25D NFC dynamic tags will help fulfill government requirements in certain countries to track batteries for light electric vehicles (like EV motorbikes) and exchange data between the battery and the vehicle.

Typical Block Diagram - Automotive Battery Management System (BMS)



FIND OUT MORE

<https://www.st.com/en/applications/electro-mobility/automotive-battery-management-system-bms.html>

DC Fast Charging Station

The number of full electric vehicles (EVs) is rapidly growing and, as a result, the charging infrastructure is also expanding, including DC fast charging stations, which have the attractive capability of providing the vehicle with a 100 km driving range in just 10-12 minutes.

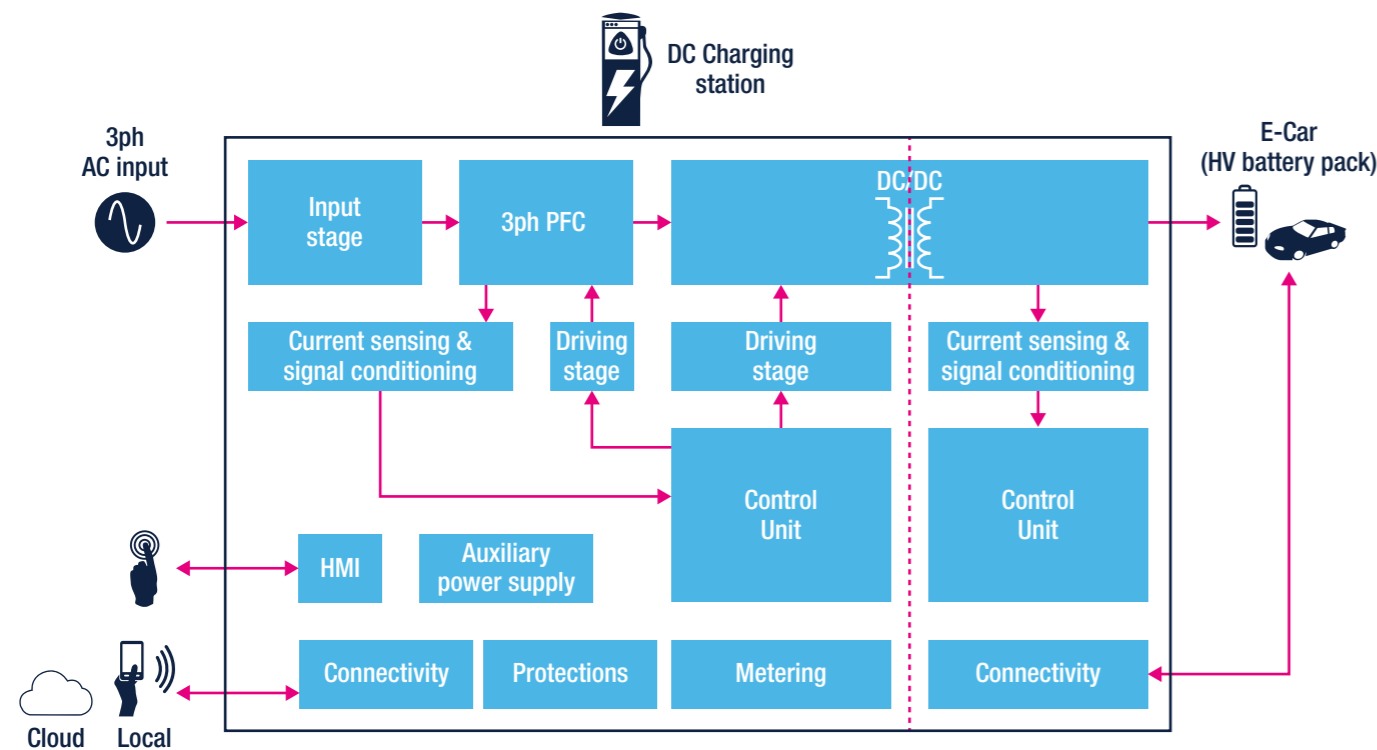
While architectures based on renewable sources and battery storage technologies to take charging stations off-grid are emerging, mainstream solutions are fed from the grid, and a converter, in the range of 120 kW or more, has a 3-phase input Power Factor Correction (PFC) stage and an isolated DC-DC converter. DC Charging stations also provide secure connectivity and authentication with the vehicle.

We can provide a range of power discretes including silicon carbide (SiC) and silicon power MOSFETs and diodes, isolated gate drivers, as well as high-performance STM32 microcontrollers to help develop high-efficiency, high-power density DC charging stations.

ST25R NFC readers will help compliance with rules in certain countries to accept credit cards following the EMVCo standard or accept closed-loop payment and even track charging in private environments.



Typical Block Diagram - DC Fast Charging Station



ST product offering for DC Fast Charging Station

	Input stage	3ph PFC	DC/DC		Control units		Driving stage	Current sensing & signal conditioning	Aux SMPS	HMI	Metering	Connectivity	
			1^ side	2^ side	1^ side	2^ side						1^ side	2^ side
Rectifiers	SiC series - 650 V		•	•									
	SiC series - 1200 V		•	•									
	Ultrafast RQ series - 600 V		•	•									
	Ultrafast R series - 600 V		•	•					•				
	STBR series - 800 V/1200 V		•	•									
Schottky series - 40/45/60/100 V									•				
Thyristors	TN series - 1200 V		•										
	TYN series - 1200 V		•										
	TM8050H series - 800 V		•										
	TN3050H, TN6050HP series - 1200 V		•										
TVS protections	SM4TY, SM6TY, SM15TY, SM30TY		•	•	•				•				
HMI ESD protections	ESDAxxY series, EMIF06-1005MX12Y									•			
Power MOSFETs	SiC series - 650 V/1200 V		•	•									
	M5 series - 650 V		•										
	M6 series - 600 V/650 V		•	•									
	DM6 series - 600 V/650 V			•									
	DM2 series - 600 V/650 V			•									
	K5 series - 1200 V		•						•				
	M9 series - 650 V		•	•									
DM9 series - 600 V			•										
IGBTs	H series - 1200 V		•										
	HB series - 650 V		•	•									
	HB2 series - 650 V		•	•									
	V series - 600 V		•	•									
ACEPACK Power Modules	A2F12M12W2-F1, A2U12M12W2-F2, A1F25M12W2-F1		•	•									
MCUs (32bit)	STM32F334, STM32G4, STM32F3		•	•		•							
	STM32F0, STM32F1, STM32G0					•		•					
Gate drivers	L6491												
	STGAP2*												
Iso Sigma-Delta ADC	ISOSD61, ISOSD61L								•				
Current sense amplifiers	TSC102, TSC2010, TSC2011, TSC2012, TSV*, TSZ*		•						•				
HV converters	VIPer*7, VIPer*6, VIPer26K									•			
Offline controllers	L6566BH, STCH03									•			
Voltage regulators	STPM066S, L5965, L9396, A6986I, A798*, A698*									•			
	L798*, L698*									•			
CAN transceivers	L9616												•
CAN ESD protections	ESDCAN*Y Series												•
													•
Power line transceivers	ST2100												•
	ST7540, ST7580, ST8500												•
Bluetooth Low Energy Transceiver	SoC and Wireless MCUs	BlueNRG-* STM32WB5*											•
	STM32 Wireless Module	STM32WB5MMG											•
	Modules	BlueNRG-M0, BlueNRG-M2											•
NFC/RFID	Dynamic tags	M24SR, ST25DV-I2C											•
	Readers	ST25R											•
Metering ICs	STPM32, STPM33, STPM34, STPMS2, STISO621										•		
LED array drivers	LED1642, STP08, STP16, LED77*, LED8102S, LED1202, STLED316S									•			

Note: * is used as a wildcard character for related part number

Main application boards and reference designs



STDES-PFCBIDIR
15 kW, three-phase, three-level Active Front End (AFE) bidirectional converter



STDES-VIENNARECT
15 kW, three-phase Vienna rectifier with low cost mixed-signal control for power factor correction



STDES-30KWVRECT
30 kW Vienna PFC rectifier reference design with digital control



STEVAL-DPSTPFC1
3.6 kW PFC totem pole with digital inrush current limiter

INDUSTRIAL POWER & TOOLS

Industrial Welding

Arc welding is an assembling process that joins metal parts by causing their fusion through high-current flowing through the electrode and the base material. The current, either DC or AC, is generated by a specifically designed high-frequency inverter switched mode power supply (SMPS), usually based on half-bridge, full-bridge, and two-transistor forward topologies.

The main requirements in an SMPS for welding are high efficiency and reliability, as well as power density to enable lighter and more compact designs.

We have a range of power MOSFETs and diodes – both Si and SiC based for higher efficiency – and IGBTs as well as galvanically isolated gate drivers and high-performance 32-bit STM32 microcontrollers to enable compact designs with higher efficiency.

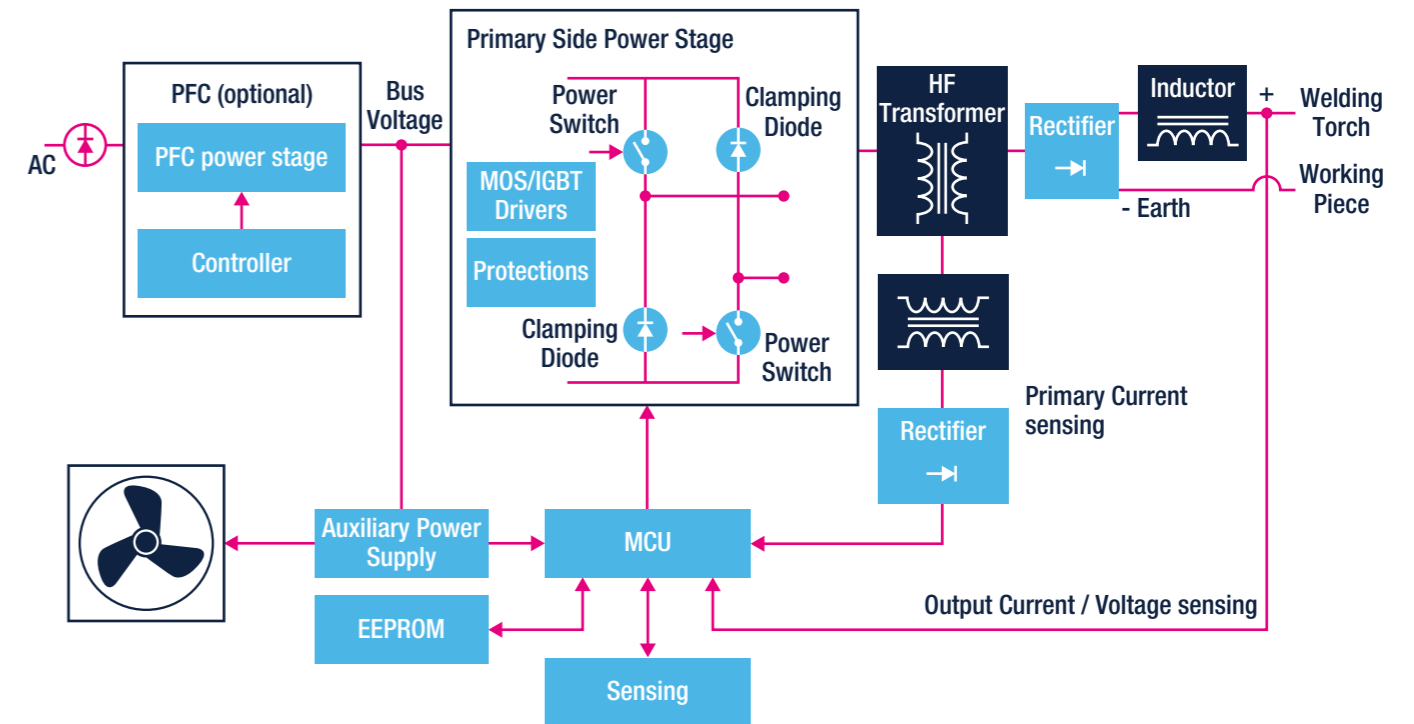


ST product offering for Industrial Welding

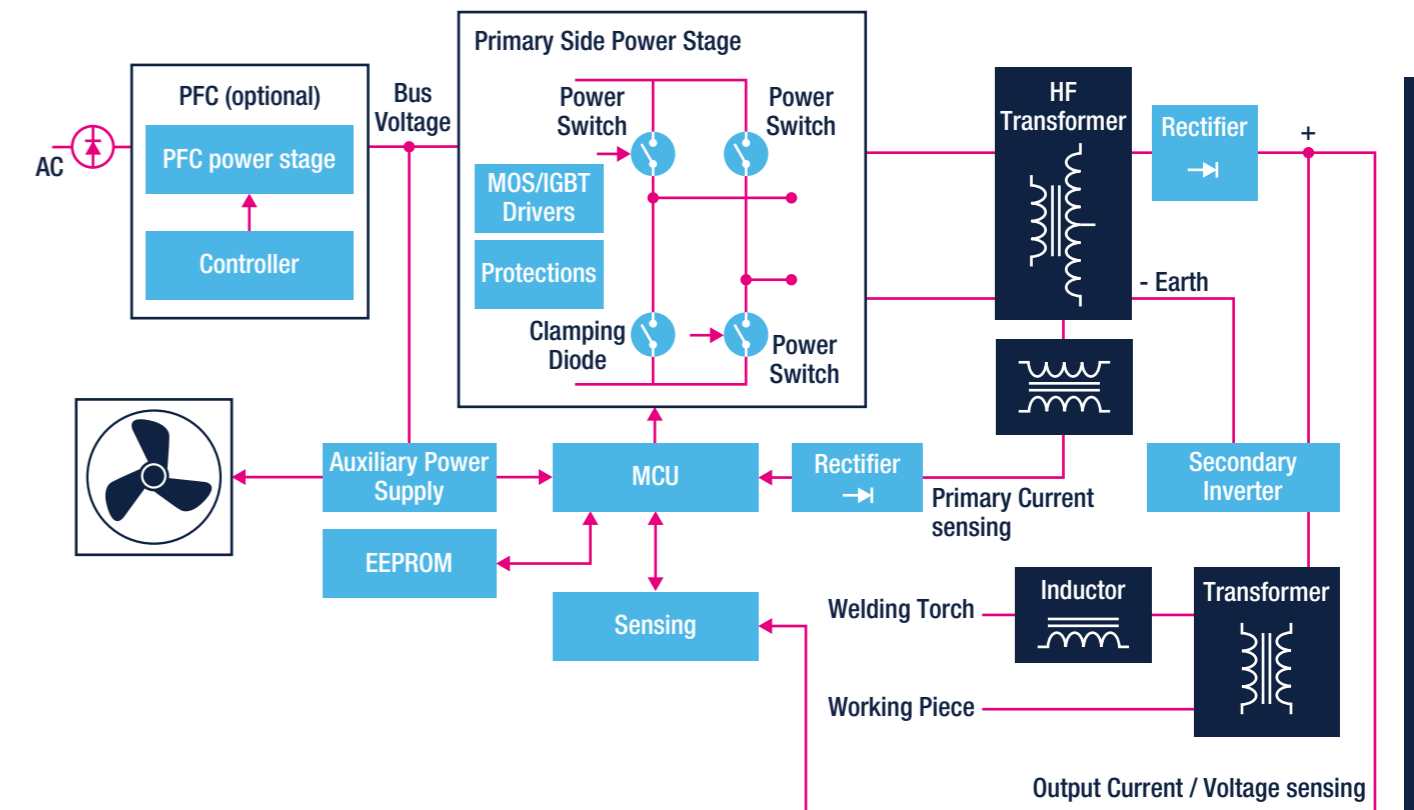
	MCUs & Digital Controllers	MOSFET/IGBT Gate Drivers	IGBTs & Power Modules	Power MOSFETs	Diodes & Protections
PFC	MCUs STM32F0 STM32G0 STM32F301 STM32F334 STM32G4 Digital Controllers STNRG388A	Single LS Gate Drivers PM88*1, TD35* Multiple LS Gate Drivers PM8834 Isolated Gate Drivers STGAP* HV HB Gate Drivers L649*	600 V V series STG*V60F 650 V HB series STG*HP65FB 650 V HB2 series STG*HP65FB2 1200 V H series STG*H120F2	650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 650 V MDmesh M5 ST*65M5 650 V-1200 V SiC MOSFETs SCT*65G3AG, SCT*N65G2, SCT*120G3AG, SCT*N120G2, SCT*N120	600 V Ultrafast STTH*W06, STTH*R06, STTH*T06 1200 V Ultrafast STTH*S12 SiC Diodes STPSC*065, STPSC*H12 TVS for Power Rail Surge Protection SM*T, SMC30J series
DC-DC TTF			600 V V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2 1200 V H series STG*H120DF2	600 V MDmesh DM9 ST*60N*DM9 600 V-650 V MDmesh DM6 ST*60DM6, ST*65DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 650 V MDmesh M5 ST*65M5 950 V to 1050 V MDmesh DK5 ST*95DK5, ST*105DK5 800 V MDmesh K6 ST*80*K6 800 V to 1200 V MDmesh K5 ST*80K5, ST*9*K5, ST*105K5, ST*120K5 650 V-1200 V SiC MOSFETs SCT*65G3AG, , SCT*N65G2, SCT*120G3AG, SCT*N120G2, SCT*N120	600 V Ultrafast STTH*R06, STTH*06 1000-1200 V Ultrafast STTH*10, STTH*12 TVS for Power Rail Surge Protection SM*T, SMC30J series
DC-DC PS-FB	STM32F334 STM32G4 STM32F301 STM32F1 STM32F3	Isolated Gate Drivers STGAP* HV HB Gate Drivers L649*	ACEPACK Power Modules Customized Modules		
Secondary Inverter			600 V V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V MDmesh DM6 ST*60DM6	200 V to 400 V Ultrafast STTH*W02, STTH*W03, STTH*W04 Power Schottky High Temperature STTH*10, STTH*12 TVS for Power Rail Surge Protection SM*T, SMC30J series

Note: * is used as a wildcard character for related part number

Typical configuration for Single-Phase Architecture for Low/Medium Power Welding



Typical configuration for Single and Three-Phase Architectures for Medium/High Power Welding



Uninterruptable Power Supplies (UPS)

Uninterruptable Power Supplies (UPS) ensure continuity of supply by converting the DC voltage from a battery or battery bank to an AC voltage with the requested amplitude and frequency in case of power outages.

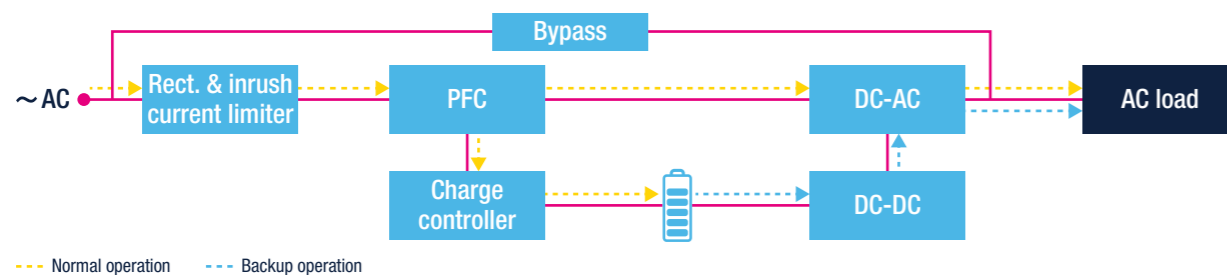
Depending on application requirements, an UPS can be built with a simple off-line configuration or with a double conversion online method for high-end, medium, or high-power UPSs. This also improves the quality of the power supplied to sensitive loads, including computers, servers, smart industry machines, instrumentation, and telecommunication equipment. We offer high-performance discrete devices, including high- and low-voltage power MOSFETs, IGBTs, thyristors, and silicon carbide (SiC) diodes and power MOSFET as well as galvanically-isolated and high-voltage gate drivers, PFC controllers, and high-performance STM32 microcontrollers to enable high-efficiency, high-reliability UPS designs.

ST product offering for Uninterruptable Power Supplies (UPS)

Rect. & inrush current limiter	SCRs & TRIACs		Diodes		Bypass	SCRs & TRIACs	
	High Temp. SCR TN*015H-6, TN*050H-8, TN*050H-12W High Temp. Triacs T1635T		Bridge Rectifier Diodes STBR*08, STBR*12			Standard SCR TYN6*, TYN8*, TYN10*, TYN12* High Temp. SCR TN5050H-12WY Standard and Snubberless Triacs T2550-12, TPDV*	
PFC Block	MCUs & Digital Controllers	Power MOSFETs	IGBTs	Diodes	Opamp V/I Sensing	Protections	
	MCUs STM32F0, STM32G0, STM32F301, STM32F334, STM32G4 Digital Controllers STNRG388A	650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2 650 V MDmesh M5 ST*65M5 650 V - 1200 V SiC MOSFETs SCT*65G3AG, SCT*N65G2, SCT*120G3AG, SCT*N120G2, SCT*N120	600 V V series STG*V60F 650 V HB series STG*HP65FB 650 V HB2 series STG*HP65FB2 1200 V H series STG*H120F2	600 V Ultrafast for CCM STTH*R06 STTH*06 1200 V Ultrafast STTH*12 SiC Diodes STPSC*065 STPSC*H12	Precision Op Amps (<50 MHz) TSZ*, TSV*, TS9*, LMV* MOSFET and IGBT Gate Drivers Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1 HV HB Gate Drivers L649* Isolated Gate Drivers STGAP*	TVS for Power MOSFET Protection SMAJ, SM6T, SM15T series	
Charge Controller	MCUs	Power MOSFETs	IGBTs	Diodes	MOSFET and IGBT Gate Drivers	Protections	
	STM32F334 STM32G4 STM32F4 STM32F7 STM32H7	600 V MDmesh DM9 ST*60N*DM9 600 V-650 V MDmesh DM6 ST*60DM6, ST*65DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 VMDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2	600 V V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2 1200 V H series STG*H120DF2	600 V Ultrafast STTH*06 1200 V Ultrafast STTH*12 SiC Diodes STPSC*065 STPSC*H12	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP*	DC-DC Converters L698*, ST1S14, L7983, L7985, L7986, L7987* Low Dropout (LDO) Linear Regulators LDF, LDFM, LDK220, LDK320, LDK715, LDL212, ST730/2	
DC-AC Stage	MCUs	Power MOSFETs	IGBTs	Diodes	MOSFET and IGBT Gate Drivers	Post Regulation	
	STM32F334 STM32G4 STM32F4 STM32F7 STM32H7	650 V-1200 V SiC MOSFETs SCT*65G3AG, SCT*N65G2, SCT*120G3AG, SCT*N120G2, SCT*N120	600 V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2 1200 V H series STG*H120DF2	600 V Ultrafast STTH*06 1200 V Ultrafast STTH*12 SiC Diodes STPSC*065 STPSC*H12	Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1 HV HB Gate Drivers L649* Isolated Gate Drivers STGAP*	DC-DC Converters L698*, ST1S14, L7983, L7985, L7986, L7987* Low Dropout (LDO) Linear Regulators LDF, LDFM, LDK220, LDK320, LDK715, LDL212, ST730/2	
DC-DC Stage		60 V-100 V StripFET F7 ST*N6F7, ST*N8F7, ST*N10F7					

Note: * is used as a wildcard character for related part number

Typical block diagram for Online UPS with double conversion stage



MAJOR HOME APPLIANCES

Refrigeration, Washing, Drying, and Miscellaneous Equipment

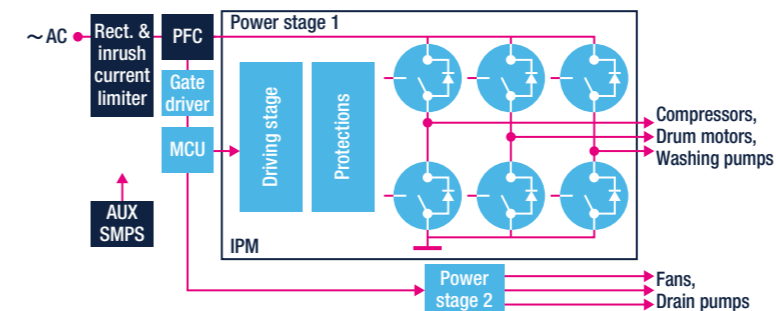
The white goods market requires low-cost and high-energy-efficiency solutions. The refrigeration, washing, drying, and miscellaneous (air conditioner, water heater) equipment are some of the major home appliance applications that ST, thanks to its wide product portfolio, is able to satisfy with suitable and dedicated power products and high-performing STM32 microcontrollers combined with complementary gate drivers (L638* and L649*). Using SiC diodes (STPSC*), new high-voltage MDmesh MOSFETs or suitable field stop trench-gate IGBTs, high-efficiency PFC is guaranteed. To reduce the 3-phase inverter design effort, ST offers the SLLIMM family (small low-loss intelligent molded module) of highly-integrated, high-efficiency intelligent power modules (IPM) integrating the power stage (both on IGBT and MOSFET discretes), driving network and protections. Another approach for designing a 3-phase inverter is based on the use of six discrete IGBTs/MOSFETs with the new 3-phase gate drivers STDRIVE601. High reliability against the inrush current is ensured by new SCRs in the front-end stage. STPW programmable electronic power breaker family provides a convenient, integrated solution for quickly and safely disconnecting a faulty load from a 12 V bus.

ST product offering for Refrigeration, Washing, Drying and Miscellaneous Equipment

Rect. & inrush current limiter	SCRs & TRIACs		Diodes		User Interface	LED Drivers	AUX SMPS	HV Converters
	High Temp. SCR TN*015H-6, TN1610H-6, TN*050H-12W High Temperature T-Series and 8H-Triacs Txx35T-8 and Txx35H-8		Bridge Rectifier Diodes STBR*08, STBR*12			LED Array Drivers STP04/08/16/24 LED12/16/24* STLED3165S STLED524 STCS*, LED8102S		
PFC Block	MCUs & Digital Controllers	IGBTs	Diodes	Opamp V/I Sensing	Power MOSFETs	Power Breakers		
	MCUs STM32F0, STM32G0, STM32F301, STM32F334, STM32G4 Digital Controllers STNRG388A	600 V V series STG*V60F 650 V HB series STG*HP65FB 650 V HB2 series STG*HP65FB2	STTH*AC06 STTH*R06 STPSC*065 DLF	Precision Op Amps (<50 MHz) TSZ*, TSV*, TS9*, LMV* MOSFET and IGBT Gate Drivers Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1	650 V MDmesh M9 ST*65N*M9 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh M2 ST*60M2, ST*65M2 650 V MDmesh M5 ST*65M5 650 V SiC MOSFETs SCT*65G3AG, SCT*N65G2	STPW12 Protections TVS for Power Rail SMAJ, SM6T, SM15T, SMC30J series		
3Ph Inverter Compressor, Drum Motor, Fan, Pumps	MCUs	IGBTs	IPM	MOSFET and IGBT Gate Drivers	Power MOSFETs	Post Regulation		
	STM32F0, STM32G0, STM32F103, STM32F301, STM32F334, STM32G4, STM32F4	600 V H series STG*H60DF 650 V M series STG*M65DF2	IPM for compressor and drum motor STGIPQ*60T-H STIPQ*M60T-H STGIF*CH60(T)S-L(E) STGIB*CH60(T)S-L(E) STGIB*M60(T)S-L(E) STIB*60DM2T-L IPM for fan and pumps STIPNS*M50T-H STGIPNS*H60T-H STIPQ*M60 STGIPQ*60T-H	3-Phase HV Gate Driver STDRIVE601 HV HB Gate Drivers L638*, L649* Isolated Gate Drivers STGAP* Protections TVS for Power Rail Surge Protection SMA4F, SMA6F, SMB15F, SMC30J series	600 V MDmesh DM9 ST*60N*DM9 600 V-650 V MDmesh DM6 ST*60DM6, ST*65DM6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 650 V SiC MOSFETs SCT*65G3AG, SCT*N65G2	DC-DC Converters L698*, ST1S14, L7986, L7985, L7986, L7987* Low Dropout (LDO) Linear Regulators LDF, LDFM, LDK220, LDK320, LDK715, LDL212		

Note: * is used as a wildcard character for related part number

Typical configuration



Main application boards



STEVAL-IHT008V1
1 kW, digital inrush current limiter based on Triac



STEVAL-IPM*
300 W to 3 kW Power board based on SLLIMM™

Induction Cooking

Induction cooking ranges must be efficient, safe, and provide friendly user interfaces. Resonant-switching topologies are typically used for the power converter in these appliances as they also help achieve lower levels of electro-magnetic interferences (EMI).

We have specifically developed trench gate field-stop IGBTs and diodes that, together with a selection of high-voltage gate drivers and high-performance STM32 microcontrollers, are ideal for high-efficiency converters. ST also offers environmental sensors and LED and LCD display drivers, touchscreen controllers, and proximity and sensors required for touch or touch-less user interfaces. The ST25R NFC reader portfolio will allow induction hubs to communicate with cookware to negotiate power transfer, making kitchen appliance, cordless.

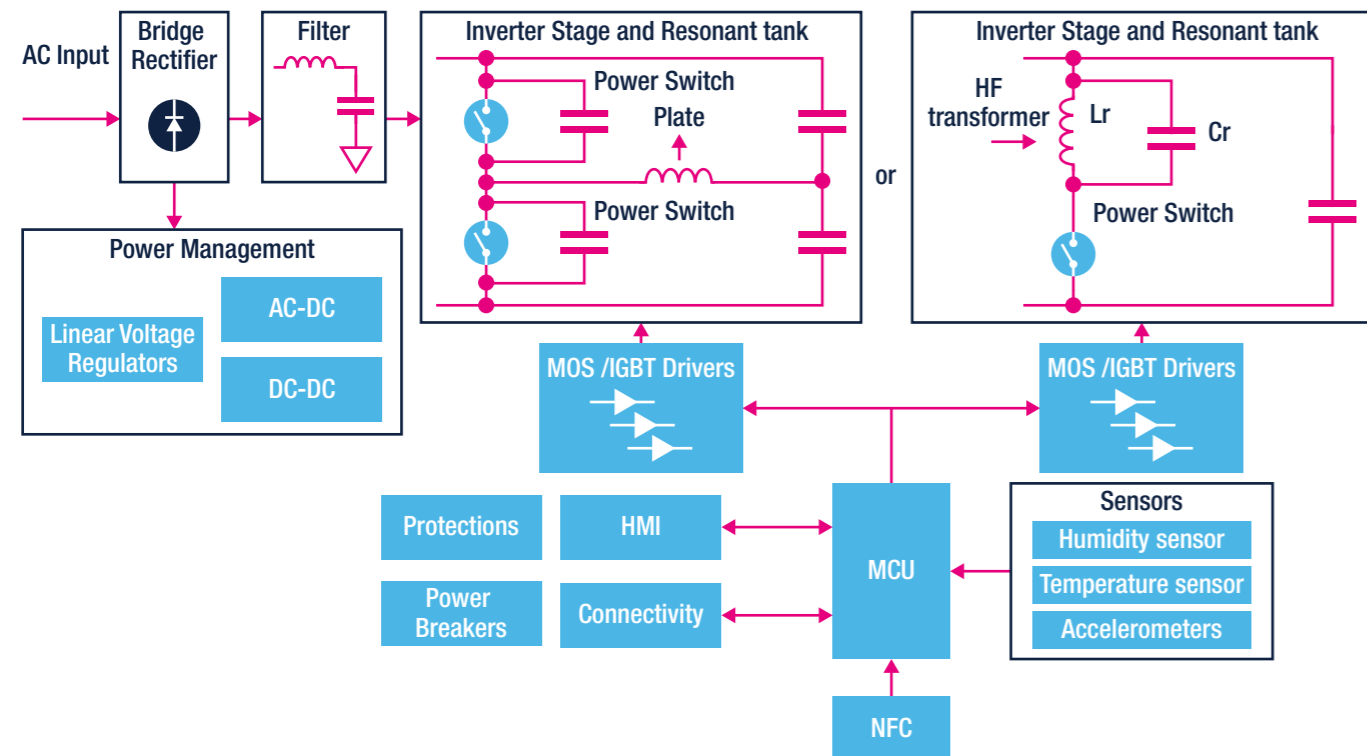


ST product offering for Induction Cooking

	MCUs	IGBTs	Gate Drivers	Sensors	NFC		
Single-switch quasi-resonant (voltage resonance)	STM8 STM32G0 STM32F0 STM32F301	1250 V IH series STG*IH125DF	Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1	Environmental Sensors Humidity - HTS221 Temperature - STLM20 Temperature - STTS751	ST25R3916, ST25R3918		
HB series resonant (current resonance)	MCUs STM32F0, STM32G0, STM32F303, STM32G4	IGBTs 600 V HB series STG*H60DLFB 650 V IH series STG*IH65DF	Gate Drivers HV HB Gate Drivers L649* Isolated Gate Drivers STGAP*	Motion Sensors Accelerometer - IIS3DHH Proximity Sensors ToF - VL53L*, VL6180*	Connectivity Bluetooth Low Energy SoC, Wireless MCUs, Modules BlueNRG-*, STM32WB*		
User interface (front panel)	MCUs STM8, STM32F0, STM32G0, STM32F4, STM32F7	LED Drivers LED Array Drivers STLED316S, STLED524, STP04/08/16/24, LED1642GW, LED8102S, LED12/16/24*	Power Management	AC-DC VIPerPlus	DC-DC L698*, ST1S14, L7983, L7985, L7986, L7987*	LDO LDF, LDFM, LDK220, LDK320, LDK715, LDL212, ST730, ST732	Power Breakers STPW12

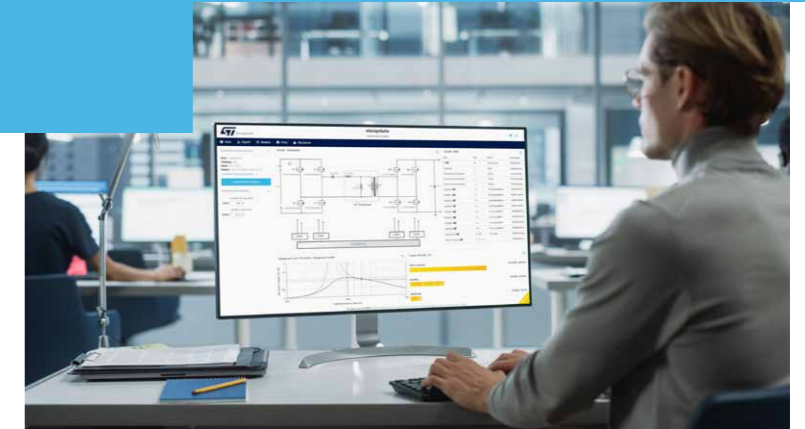
Note: * is used as a wildcard character for related part number

Topology example



Software tools

eDesignSuite is a comprehensive easy-to-use design aid tool supporting a wide range of ST products



eDesignSuite - Power Management Design Center

eDesignSuite is a comprehensive and flexible suite of design aid utilities and engineering tools that streamlines development of winning solutions with a wide range of ST products meeting user application requirements. Explore the advanced features of our Power Management Design Center, an on-line design tool that smartly helps designers of power management systems and subsystems accelerating the engineering development process (select, evaluate, refine, and prototype) for a large and growing number of ICs and Discrete devices in our broad portfolio. The software tool supports a variety of switching power converters in power supply, digital power, LED lighting, and battery charger applications, simplifying the design path from user specification to circuit analysis and customization. The main features of the tool are automatic proposal for complete solution or fully customizable design, fully annotated and interactive schematics, complete and interactive bill of materials, main current and voltage simulations, efficiency curves, Bode stability and power-loss data, and fully interactive transformer design.

POWER SUPPLY DESIGN TOOL

- SMPS design, by topology, by type and by product
- PFC design with analog and digital control
- Supports various PCB configurationst

LED LIGHTING DESIGN TOOL

- Handles AC-DC and DC-DC design in common topologies
- Displays interactive and annotated schematic
- Provides current/voltage graphs, Bode plots, efficiency curves and power-loss data

DIGITAL POWER WORKBENCH

- Provides a step-by-step optimized design of power section and control loop
- Generates the STM32Cube embedded software package for custom applications and allows firmware project generation, compatible with multiple STM32 IDEs

POWER TREE DESIGNER

- Specify input/output power for each node in the tree
- Check for consistency
- Design each individual node



eDSim is a fast and powerful electrical simulation tool for SMPS and analog ICs integrated in the eDesignSuite tool. It features enhanced accuracy and higher convergence speed for SMPS, enabling a simulation time 10-50x faster than the classic analog SPICE simulators. Design your analog circuit using the eDesignSuite engine, display a preview with full annotated schematic and BOM, and then run the electrical simulation through eDSim to get fast and accurate simulations and reliable design validation, thus reducing the effort and risks related to hardware prototyping. With the eDSim tool, you can also create your schematic from scratch using ST models or simulate your SMPS and analog ICs from a list of predefined ST application schematics-test benches, that you can partially modify according to your needs.



Products



GALLIUM NITRIDE (GaN) POWER ICs

Integrated Smart GaNs - MASTERGAN

Gallium nitride (GaN) is revolutionizing the power engineering world by enabling higher speed, efficiency and power density than ever before possible with silicon MOSFETs. Integrating GaN transistors and gate drivers, our advanced MASTERGAN system-in-package offer high efficiency due to their optimized gate drive layout, high power density, and increased switching frequency due to minimal parasitic effects, translating in a number of benefits for fast chargers, USB PD adapters, LED lighting drivers, TV power supplies, and server/telecom power designs.

KEY FEATURES AND BENEFITS

- QFN 9 x 9 x 1 mm package
- Embedded gate driver easily supplied by the integrated bootstrap diode
- Overtemperature protection
- Extended 3.3 to 15 V input range with hysteresis and pull-down
- Accurate internal timing match
- Interlocking function
- -40 to 125°C operating temperature range
- High switching frequency >1 MHz
- No investment to learn GaN required
- Fast time-to-market

Part Number	General description	Output current max (A) @25 °C	High side $R_{DS(on)}$ (mΩ)	Low side $R_{DS(on)}$ (mΩ)	Supported topologies
MASTERGAN1	High power density 600 V half-bridge high voltage driver with two 650 V enhancement mode GaN HEMT	10	150	150	Resonant, ACF
MASTERGAN2		6.5	225	150	ACF
MASTERGAN3		4	450	225	ACF
MASTERGAN4		6.5	225	225	Resonant, ACF, inverse buck
MASTERGAN5		4	450	450	Resonant, ACF

STDRIVE GaN Drivers - STDRIVEG600

The GaN driver devices are 600 V half-bridge gate drivers for enhancement mode GaN FETs or N-channel power MOSFETs. This single chip with integrated bootstrap diode allows designers to implement GaN performance advantages and simplify design and bill-of-material requirements at the same time.

KEY FEATURES AND BENEFITS

- Highest robustness, efficiency and integration:
- Up to 20 V gate driver
- Voltage rail to 600 V
- 5.5 A / 6 A source/ sink currents
- 45 ns short propagation delay
- Integrated bootstrap diode
- Separate ON-OFF outputs for easier tuning
- 3.3 V / 5 V logic inputs
- UVLO on Vcc and VBOOT
- Thermal shutdown
- Interlocking function
- Shut-down pin
- SO16 narrow package

Part Number	General description	Package
STDRIVEG600	High voltage and high-speed half-bridge gate driver for GaN Transistors	SO-16
STDRIVEG600TR		SO-16
STDRIVEG600W		Wafer

MAIN APPLICATIONS



SMPS



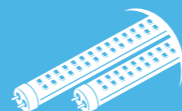
USB PD Adapter



UPS



Solar



LED Lighting

High-voltage GaN converters – VIPerGaN series

The high-voltage power converters series is enriched by the introduction of GaN HEMT (high-electron-mobility transistor) technology, in a small QFN5x6 package. The VIPerGaN series offers excellent design opportunities for compact and light fast chargers, adapters, and power supplies up to 100W with a wide input range.

Part Number	Package	$R_{DS(on)}$ @ 25°C	Max GaN HEMT transient voltage	Max P_{OUT} @ 85-265 V _{AC}	Max P_{OUT} @ 185-265 V _{AC}
VIPERGAN50TR	QFN 5x6 with exposed pad	0.45 Ω	850 V	50 W	75 W
VIPERGAN65TR		0.26 Ω	850 V	65 W	85 W
VIPERGAN100TR		0.26 Ω	850 V	75 W*	100 W

*100 W with a PFC in the front end

KEY FEATURES AND BENEFITS

- Quasi-resonant (QR) flyback controller
- 650 V E-mode power GaN transistor (850 V transient voltage)
- Minimal standby power consumptions
- Embedded sense FET
- Dynamic blanking time and adjustable valley synchronization delay
- Output OVP protection
- Input voltage feedforward compensation for mains independent OPP variation
- Brown-in and brown-out
- Input OVP protection
- Embedded thermal shutdown
- Frequency jitter for EMI suppression



MAIN APPLICATIONS



USB PD Adapter



Air Conditioning



TV Power Supply



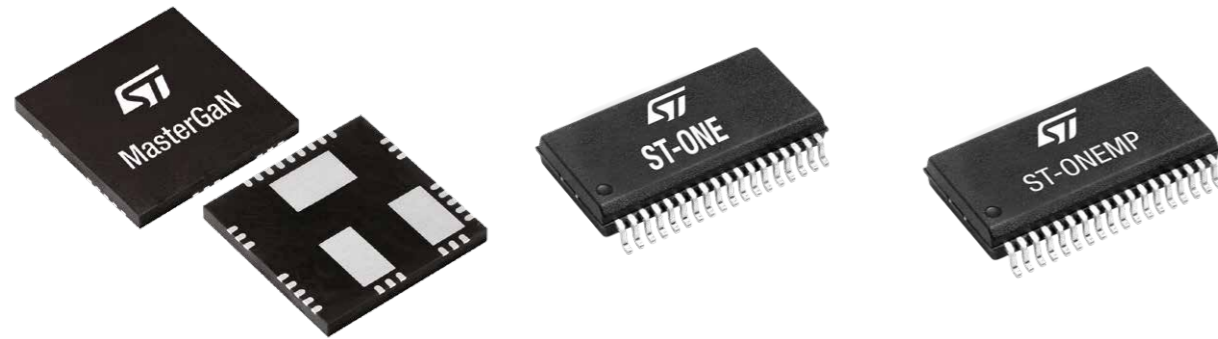
Home appliances

AC-DC CONVERSION ICs

ST-ONE all-in-one digital controller for USB-PD adapters

ST-ONE (single USB port) and **ST-ONEMP** (multiple USB port) are the world's first digital controllers embedding ARM Cortex M0+ core, an offline programmable controller with synchronous rectification, and USB PD PHY in a single package. Such a system is specifically designed to control ZVS non-complementary active clamp flyback converters to create high-power-density chargers and adapters with USB-PD interface. The device includes an active clamp flyback controller and its HV startup on the primary side, a microcontroller, and all the peripherals required to control the conversion and the USB-PD communication on the secondary side. The two sides are connected through an embedded galvanically isolated dual communication channel. By using a novel non-complementary control technique and specifically designed power modes, the device enables high efficiency and low no load power consumption.

The device is delivered with pre-loaded firmware that handles both the power conversion and the communication protocols for USB-PD including optional PPS and electronically marked cable management.



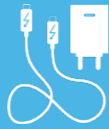
KEY FEATURES & BENEFITS

- All-in-one digital controller for USB-PD chargers up to 100 W
- ZVS Active Clamp Flyback + Synchronous rectification
- USB-PD 3.1 PPS interface and
- integrated 24 V USB-PD PHY
- >94 % peak efficiency soft switching topology
- >1 Mhz operation with MasterGaN and planar transformers
- Small weight and size solution with
- >30 W/inch³ power density
- 32bit Cortex M0+ core with 64 kB embedded flash memory
- >6.4 kV reinforced galvanically isolated dual communication channel

MAIN APPLICATIONS



Tablet AC chargers



Smartphone AC chargers



Power Adapter for laptops and desktops



Wall plug USB-C chargers

www.st.com/ac-dc-converters
www.st.com/pfc-controllers

Note: * is used as a wildcard character for related part number

High-voltage converters

ST **high-voltage AC-DC converters** combine an advanced pulse width modulation (PWM) controller with a high-voltage power MOSFET in a single package. This makes them ideally suited for offline switch mode power supplies (SMPS) with output power from a few watts to a few tens of watts.

The **VIPerPlus series** (VIPer0P, VIPer122, VIPer222, and VIPer*1, VIPer*5, VIPer*6, VIPer*7, VIPer*8 families) features an 800 V avalanche-rugged power MOSFET and leading-edge PWM controller and consumes less than 4 mW for VIPer0P, 10 mW for VIPer*1 and 30 mW in standby for the others. It also comes with the largest choice of protection schemes and supports different topologies.

The VIPer26K belongs to VIPer*6 family and integrates a 1050 V avalanche-rugged power MOSFET, suitable for cost effective 1-phase/3-phases smart meters, industrial systems, and lighting power supplies.

The Altair series has a built-in 800/900 V avalanche-rugged power MOSFET and a PWM controller specifically designed to work in constant-current/constant-voltage primary-side regulation (PSR-CC/CV). It offers opto-less implementation, thus significantly reducing component count.



1050 V	10 W	VIPer26K	Very High Voltage SMPS Embedded E/A for direct output regulation/fly-back or buck converter
900 V	7 W	Altair04	Accurate Primary Side Regulation Constant current/constant voltage
800 V	Up to 18 W	VIPer01-11-31	Logic Level MOSFET - 5 V supply voltage Embedded E/A, Very low standby consumption, 18 V DC start-up voltage
	6 W	VIPer0P	Zero Power Mode Smart standby management through buttons or MCU
	Up to 15 W	VIPer06-16-26	Embedded E/A Direct output regulation/settable current limit/fly-back or buck converter
		VIPer17-27-37	Brown-out Output OVP, current limit, fly-back with optocoupler
		VIPer28-38	Peak Power Output OVP, current limit, fly-back with optocoupler
730 V	Up to 8 W	VIPer25-35	Quasi Resonant Output OVP, current limit, fly-back with optocoupler
		VIPer122-222	Embedded E/A, 730 V BV Optimized for low power

Flyback Primary side regulation

VIPer01-11-31	VIPer122-222
VIPer26K	VIPer06-16-26
Altair04-05	VIPer0P

Flyback Secondary side regulation

VIPer01-11-31	VIPer122-222	VIPer28-38
VIPer26K	VIPer06-16-26	VIPer25-35
VIPer27-37	VIPer0P	VIPer122-222

Buck Converter Up to 600 mA Output Current

VIPer01-11-31	VIPer122-222
VIPer26K	VIPer06-16-26
	VIPer0P

MAIN APPLICATIONS

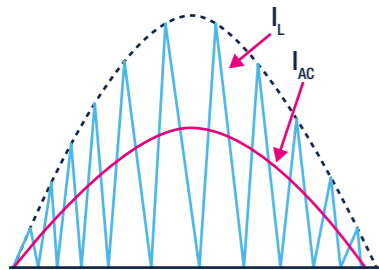


PFC controllers

ST **power factor correction (PFC) controllers** operate in transition mode (TM, suitable for $P \leq 250$ W) and continuous current mode (CCM, suitable for $P > 250$ W), and are suitable for wide-range-mains operation.

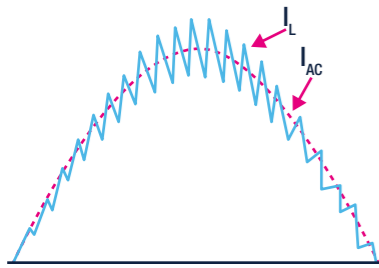
These devices embed advanced protection features, which make the SMPS more robust and compact, requiring fewer external components. These features include output overvoltage, brown-out, feedback disconnection, and boost inductor saturation protection. The high-voltage start-up capability present in the L6564H and L6563H helps improve the SMPS standby efficiency in systems that do not include an auxiliary power supply.

TM PFC controllers



	Basic features	Advanced protections	Remote on/off control	Tracking boost function	Interface for cascaded converter
L6562A*	●				
L6564*	●	●	●		
L6563*	●	●	●	●	●

CCM PFC controllers



L4984D	Line-modulated, fixed-off-time (LM-FOT) control
L4981A	Fixed frequency, average-current mode
L4981B	Line modulated frequency, average-current mode
L4985A/B	Quasi-fixed frequency, peak-current mode
L4986A/B	Quasi-fixed frequency, peak-current mode, adjustable PGOOD

MAIN APPLICATIONS



Adapters and TVs
L6562A*, L6563*, L6564,
L4985, L4986



Commercial and street lighting
L6562A*, L6563*, L6564*,
L4985, L4986, L4981*, L4984D



Desktop PCs and Server
L4985, L4986,
L4981*, L4984D

www.st.com/ac-dc-converters
www.st.com/pfc-controllers

Note: * is used as a wildcard character for related part number

PWM and resonant controllers

ST portfolio of advanced controllers includes a variety of **primary controllers** intended to fit high-performance applications. Very high efficiency is achieved with single-ended topologies at a fixed switching frequency or with quasi-resonant operation. The new STCH03 offline constant-current primary-side regulation mode (PSR-CC) guarantees very low power consumption at no load condition. For high-power, high-current applications, ST offers controllers for half-bridge resonant and asymmetrical half-bridge topologies. The STCMB1 and STNRG011 combo controllers with high-voltage start-up, Xcap discharge circuit, and PFC and resonant driving stages, guarantee high performance and high integration with a smaller pinout. The new STNRG012 is specifically designed to support LED lighting and industrial applications requiring DC source management, with additional THD optimizer function.

Flyback controllers

STCH03

- Offline quasi-resonant controller in SO-8 package
- Constant-current primary-side regulation mode (PSR-CC) or constant-voltage regulation with optocoupler
- Advanced burst mode operation (< 10 mW consumption @ no load)
- UVP, autorestart/latched OVP and internal OTP
- 650 V HV start up

L6566*

- Offline fixed-frequency or quasi-resonant controllers
- Suited for SMPS with PFC front-end (A version)
- Suited for SMPS with 3-phase mains (BH version)
- 700 V start up (A/B version), 840 V start up (BH version)
- Brownout protection

L6565

- Offline quasi-resonant controller
- Constant power vs mains change
- Ultra-low start-up current

HB-LLC resonant controllers

	Basic features	Anti-capacitive protection	Self-adjusting dead-time	Soft burst mode	Smooth Start-up
L6699	●	●	●	●	●
L6599A*	●				

Analog combo controller (PFC+LLC/LCC)

STCMB1

- 800 V start-up voltage
- Embedded X-cap discharge circuit
- Transition Mode (TM) PFC control method
- Enhanced fixed on time TM PFC controller
- Self-adjusting dead-time and anticapacitive mode for LLC
- Time-shift control of resonant half-bridge

Asymmetrical half-bridge controller

L6591

- PFC interface
- Brown out
- 700 V start-up voltage

MAIN APPLICATIONS



Tablets and smartphones
L6565, L6566*, STCH03



Laptops
L6565, L6566*, STCH03,
STCMB1



High-power adapters and TVs
L6565, L6566*; L6599A*,
L6699, STCMB1



Desktop PCs, commercial
and street lighting
L6599A*, L6699, STCMB1

www.st.com/ac-dc-converters
www.st.com/pwm-controllers
www.st.com/resonant-controllers

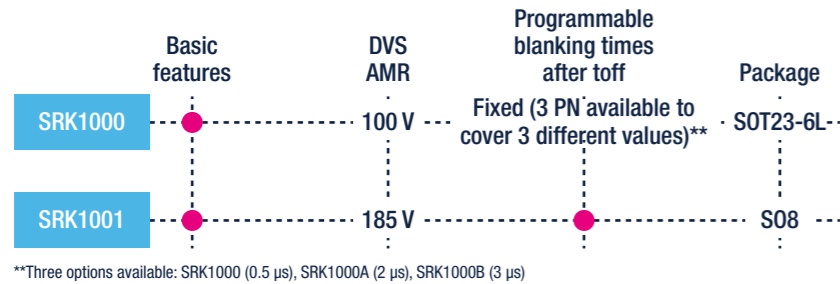
Note: * is used as a wildcard character for related part number

Synchronous rectification controllers

Synchronous rectifiers are used to drive power MOSFETs that replace the rectification diodes in the secondary side of SMPS, thus providing high efficiency especially in low-output-voltage, high-current power supplies.

The product portfolio supports the most common flyback and LLC resonant topologies. The main benefits include high efficiency, space saving, cost reduction, and high reliability.

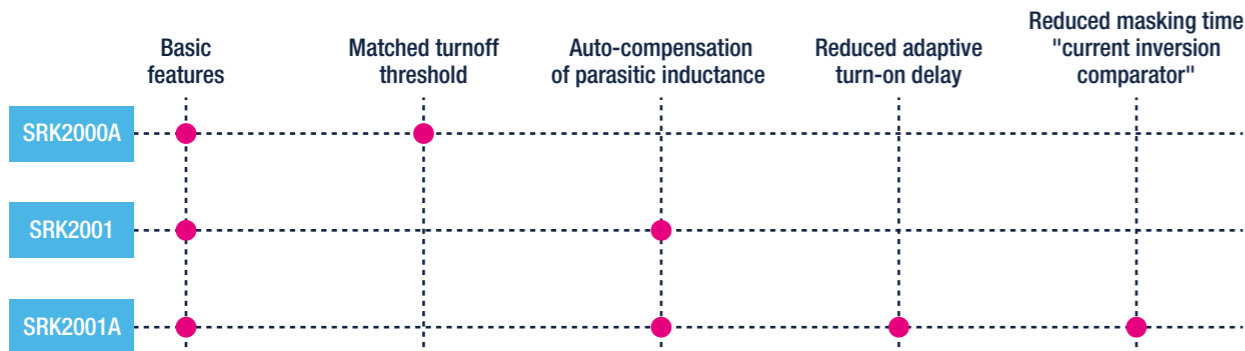
SR Controllers for Flyback



SYNCHRONOUS RECTIFICATION BENEFITS

- Improved efficiency
- Better thermal performance
- High power density
- Increased reliability

SR controllers for LLC resonant



MAIN APPLICATIONS



High-power adapters and TVs
SRK1000, SRK1001



Desktop PCs and Server/Telecoms
SRK2000A, SRK2001, SRK2001A

www.st.com/ac-dc-converters
www.st.com/synchronous-rectification-controllers

Note: * is used as a wildcard character for related part number

Signal conditioning

Signal conditioning devices include **Operational Amplifiers** and **Current Sense Amplifiers**. These devices enable accurate and fast current measurement in power supplies. **Comparators** are also very powerful allies of the power supply designer to implement protection features such as over-temperature, over-current, and over/under voltage.



Operational Amplifiers

TSZ181, TSZ182

- Operating voltage 2.2 to 5.5 V
- 5 V zero-drift amplifier
- Input offset voltage 25 μV max
- Temperature up to 175 °C
- Gain bandwidth 3 MHz

TSV772/TSV782

- Operating voltage 2.0 to 5.5 V
- Rail-to-rail input and output
- V_{io} max 200 μV
- Gain bandwidth 20/30 MHz

TSB711/2, TSB7191/2

- Operating voltage 2.2 to 5.5 V (TSB71) and 2.7 to 36 V (TSB719)
- 36 V amplifier
- Input offset voltage 300 μV max
- Gain bandwidth 6 MHz (unity gain stable) or 22 MHz

TSV791/2

- Operating voltage 1.8 to 5.5 V
- Rail-to-rail input and output
- V_{io} max 200 μV
- Gain bandwidth 50 MHz

Current Sense Amplifiers

TSC103

- Operating voltage 2.9 to 70 V
- Surviving voltage on shunt -16 to 75 V
- Amplification gain x50 x100
- Package TSSOP8, SO8

TSC2010/1/2

- Bi-directional
- Operating voltage -20 to 70 V
- Amplification gain x20 x60 x100
- Offset voltage ±200 μV max
- 2.7 to 5.5 V supply voltage
- Gain error 0.3% max
- Packages MiniSO8 SO8

TSC200

- Operating voltage -16 to 80 V
- Amplification gain x20
- Comparator +V_{ref} embedded
- Package SO8, MiniSO8

TSC21*

- Bi-directional
- Operating voltage -0.3 to 26 V
- Amplification gain x50 x75 x100 x200 x500 x1000
- Offset voltage ±35 μV max
- Gain error 1% max
- Packages QFN10, SC70-6

Comparators

TS3021, TS3022

- Propagation delay 38 ns
- Low current consumption: 73 μA
- Rail-to-rail inputs
- Push-pull outputs
- Supply operation from 1.8 to 5 V

TS3011

- Propagation delay 8 ns
- Low current consumption 470 μA
- Rail-to-rail inputs
- Push-pull outputs
- Supply operation from 2.2 to 5 V

MAIN APPLICATIONS



Wireless battery charger transmitters



Server/Telecom



Solar



UPS

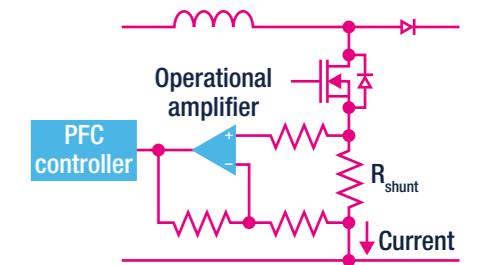


Lighting

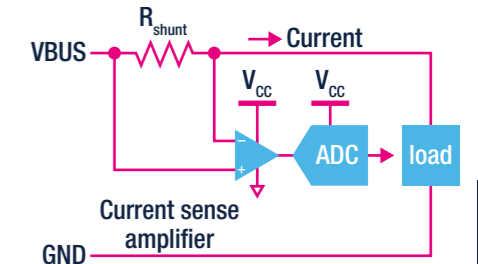


Factory automation

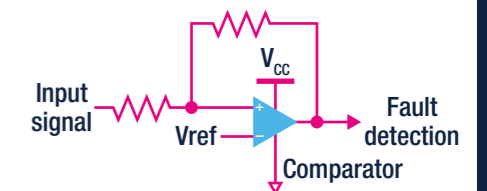
Typical application schematic for low-side current measurement in a PFC



Typical application schematic for high-side current measurement



Typical application schematic for fault detection using a non-inverting comparator, with hysteresis



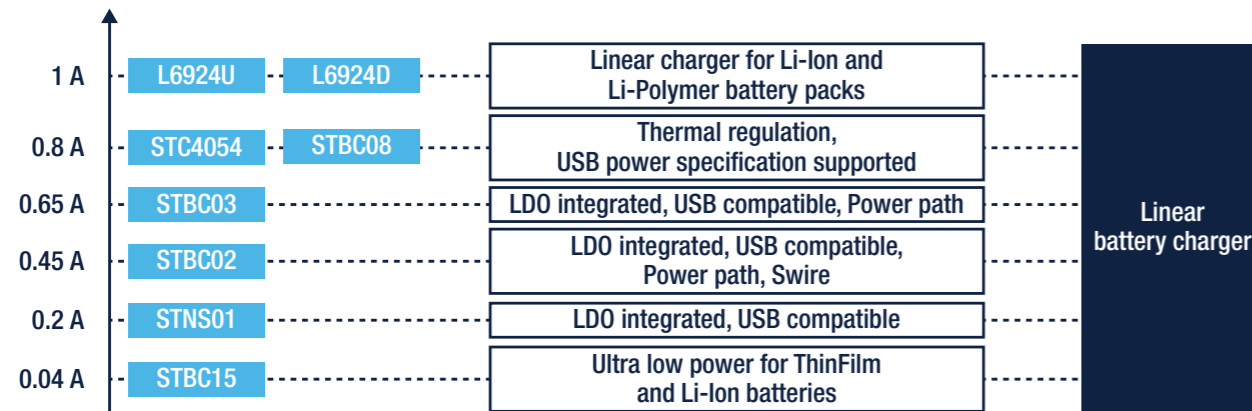
www.st.com/opamps
www.st.com/current-sense-amplifiers
www.st.com/comparators

BATTERY MANAGEMENT ICs

Battery chargers and battery monitoring ICs

ST **battery chargers** are specifically designed for the portable and mobile markets and add value to new designs by minimizing power consumption and reducing the space on the PCB. These products offer charge currents from as little as 40 mA up to 1.2 A and can be used for any rechargeable lithium-ion and Li-Polymer battery. Using very simple topologies, some of these devices also feature a power-path function, offering instant-on operation and thermal regulation according to the JEITA international standard.

Battery chargers



STBC02/STBC03

- Embed a linear battery charger, a 150 mA LDO, 2 SPDT load switches and a protection circuit module
- STBC02 embeds a smart reset/watchdog and a single wire interface for IC control
- Use a CC/CV algorithm with programmable (only STBC02) fast charge, precharge and termination current

STBC15

- Microbatteries charging and monitoring circuit
- Charging current up to 40 mA (set by dedicated pin)
- 150 nA quiescent current

ST **battery fuel gauge ICs** can be located in the battery pack or in the handheld device and integrate functions to monitor the battery voltage, current, and temperature. Using a built-in Coulomb counter, these fuel gauge ICs calculate battery charge and store the data in 16-bit register resolution for retrieval by the system controller. Access is via an industry-standard I2C interface, enabling the controller to create an accurate graphical representation of the remaining battery-operating time.

STC3115

- OptimGauge algorithm for STC3115
- OptimGauge+ algorithm for SCT3117

STC3117

- Coulomb counter and voltage gas gauge operations
- Programmable low battery alarm
- Internal temperature sensor

FUEL GAUGE ICs MAIN BENEFITS

- 3% accuracy of battery state of charge no need for shunt resistor
- Accurate estimation of battery state of charge at power-up
- Reliable battery swap detection
- SoH and impedance tracking with OptimGauge+ algorithm (ST IP)
- Charger enable and system reset control for accurate OCV reading

MAIN APPLICATIONS



Wireless charging ICs

ST fully covers wireless charging applications with **dedicated ICs for both transmitter and receiver**. The STWBC, compatible with Qi standard, and the STWBC86 dedicated to wearable applications, make up the ST wireless power transmitters (Tx) family. The receiver family (Rx) consists of the STWLC38 dedicated to Qi compliant consumer applications, the STWLC86 and the STWLC98 for higher power applications.



Wireless charger transmitter ICs

STWBC2-HP

STWBC2-HP

- Supports applications up to 70 W
- Qi 1.2.4 / 1.3 compatible
- Qi certified reference design with MP-A2 topology and supports MP-A22

STWBC86

- Optimized for standard Qi Baseline Power Profile (BPP) applications for up to 5 W
- Monolithic solution with integrated full-bridge inverter
- Popular applications are not only Tx for public spaces like restaurants, offices, and airports, but also chargers for wearable and hearable devices

Wireless charger receiver ICs

STWLC38

STWLC38

- Qi 1.3 compatible
- Supports up to 15 W Rx for Qi Extended Power Profile
- Supports up to 5 W Rx for Qi Baseline Power Profile

STWLC86/98

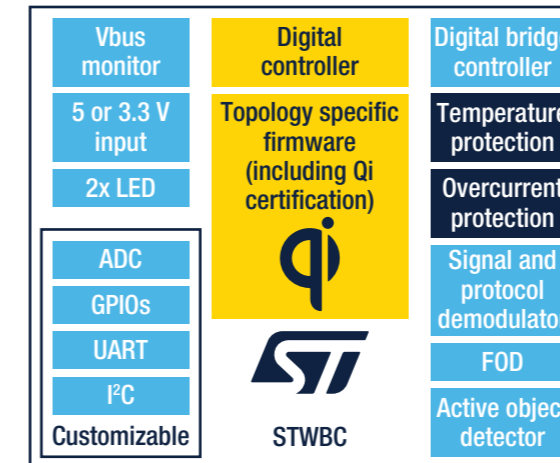
- Qi 1.3 compatible
- Supports up to 30 W (STWLC86) / 70W (STWLC98) Rx
- Supports up to 7.5 W (STWLC86) / 15 W (STWLC98) in Tx mode (coil dependent)
- Embedded OS for Qi 1.3 standalone certification (STWLC98)

- Supports up to 5 W in Tx mode (coil dependent)
- ARC (Adaptive Rectifier Configuration) mode for enhanced spatial freedom

- ARC (Adaptive Rectifier Configuration) mode for enhanced spatial freedom
- ARM 32-bit Cortex™-M3 core up to 64 MHz (STWLC98)
- Optimized device size (STWLC98)

Common features

- Industry leading efficiency
- Accurate foreign object detection (FOD)
- Best-in-class power consumption with smart standby
- GUI for run-time analysis, tuning and basic customization
- Firmware customization via API
- Robust device protection from over-voltage, over-current and over-temperature events



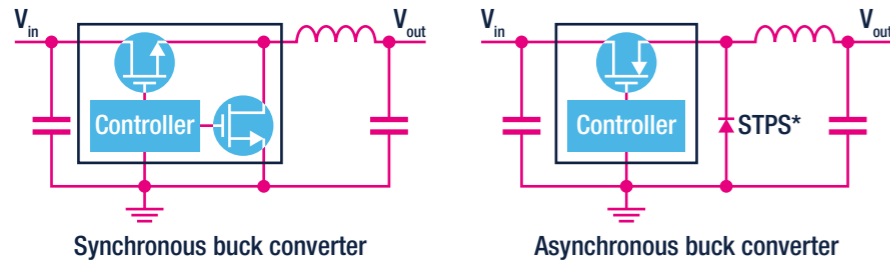
MAIN APPLICATIONS



DC-DC SWITCHING CONVERSION ICs

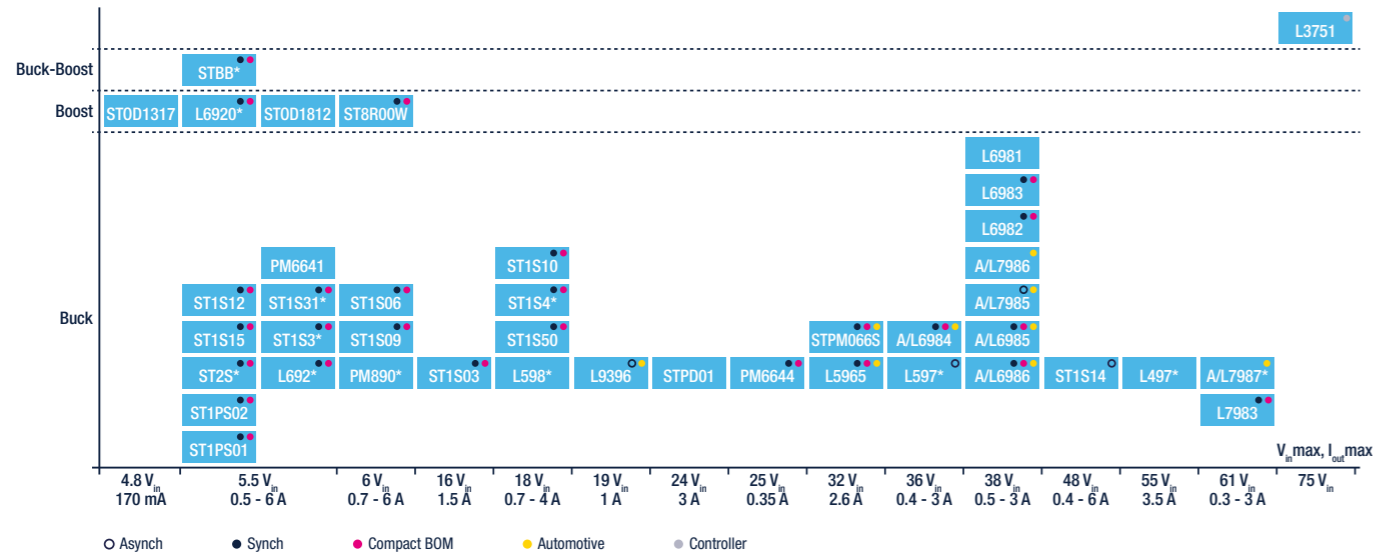
DC-DC converters

ST offers a wide portfolio of monolithic **DC-DC switching converters** (i.e., controller and MOSFET in the same package). This broad portfolio of ICs consists of highly specialized products to meet every market requirement. High reliability and robustness for industrial (factory automation, UPS, solar, home appliances, lighting, etc.) and other high-voltage applications. High efficiency at any load and a high level of performance for consumer (smartphones, digital cameras, portable fitness devices, LED TVs, set top boxes, Blue-ray players, computer & storage, etc.) and server/telecom applications.



DC-DC CONVERTERS MAIN FEATURES

- Up to 61 VIN/3 A
- Synchronization capability
- Internal compensation
- Low consumption
- Adjustable fsw
- Internal soft start
- Low quiescent current



MAIN APPLICATIONS



www.st.com/dc-dc-switching-converters

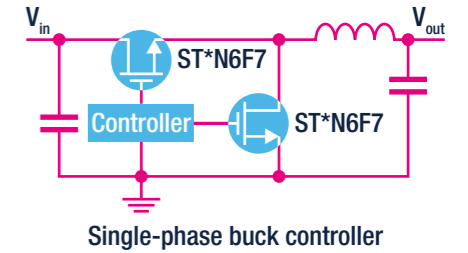
Note: * is used as a wildcard character for related part number

DC-DC controllers

ST offers a wide portfolio of **DC-DC switching controllers** for server and telecom applications according to market requirements: single-phase controllers with embedded drivers, advanced single-phase controllers with embedded non-volatile memory (NVM), and our newest controllers with or without SPS (Smart Power Stage) compatibility, as well as multiphase digital controllers for CPU & DDR memory power supplies.

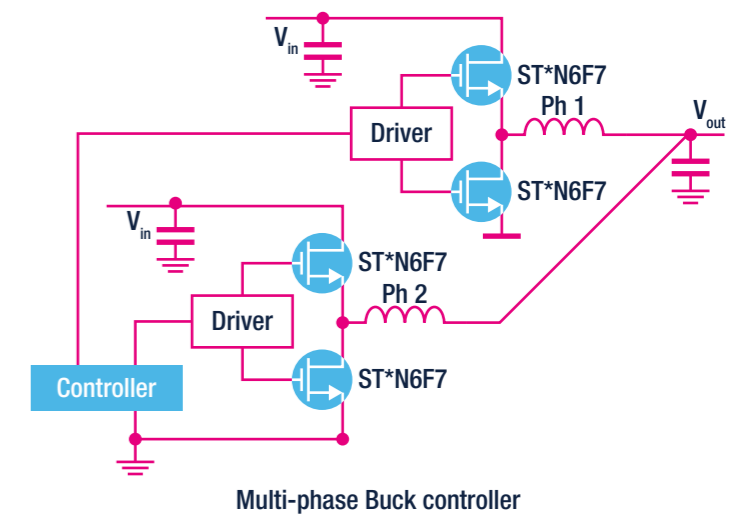
Single-phase Buck controllers

- L6726A** Single-phase cost effective PWM controller
- A6727** Single-phase cost effective PWM controller for automotive applications
- L6739** Single-phase PWM controller with embedded driver and light load efficiency optimization
- PM6680** Dual-output PWM controller up to 36Vin



Multi-phase Buck controllers

- PM676*** Fully digital buck controller with PMBus for CPU/DDR
- PM677*** Fully digital buck controller with PMBus for advanced CPU/DDR



MAIN APPLICATIONS



www.st.com/dc-dc-switching-converters
www.st.com/single-phase-controllers
www.st.com/multi-phase-controllers

Note: * is used as a wildcard character for related part number

Highly integrated power management IC for micro-processor units

STPMIC1, a high performance fully integrated power management IC, is the ideal companion chip of the **STM32MP1 microprocessor** series, being also optimized for power applications requiring low power and high efficiency. The STPMIC1 integrates buck and boost converters, linear regulators with sink/source capability, power switches specifically designed to supply all required power rails for the STM32MP1 and for other components on the board such as DDR, Flash memory, Wi-Fi and Bluetooth connectivity ICs, providing a total system solution.



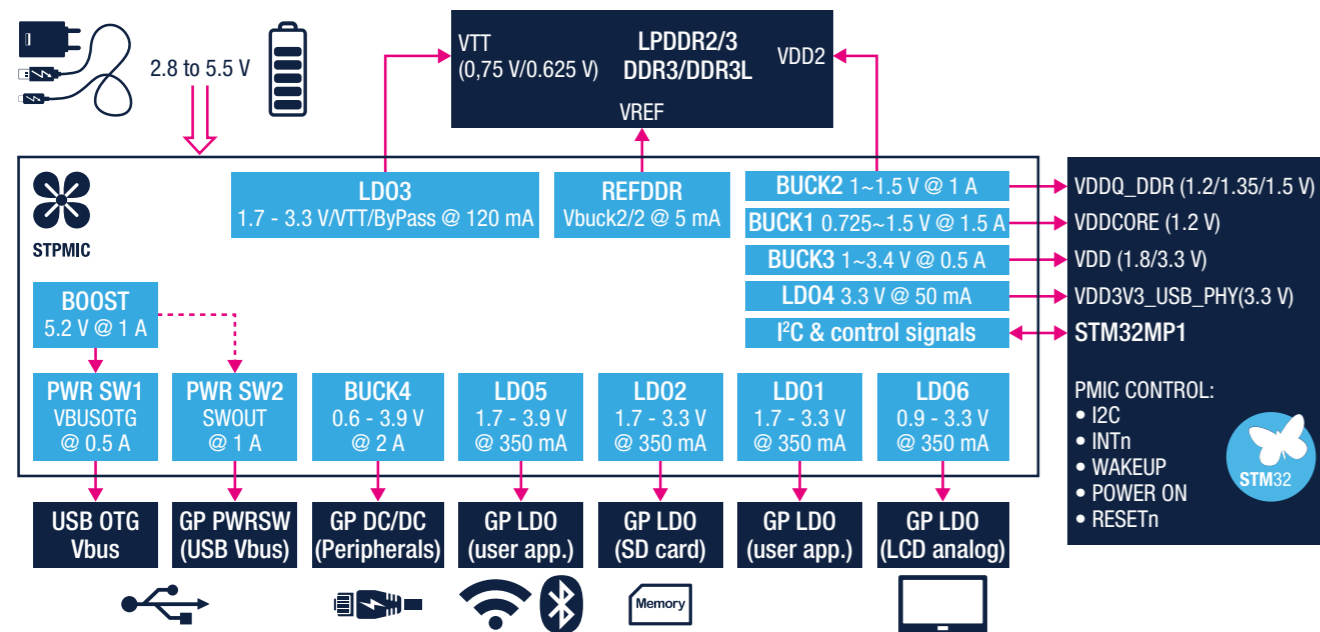
STPMIC1 versions

	5 V power supply application		Battery power supply application		Custom application, no output turned ON		5 V power supply application		Battery power supply application	
	STPMIC1A		STPMIC1B		STPMIC1C		STPMIC1D		STPMIC1E	
	Default output Voltage (V)	Rank	Default output Voltage (V)	Rank	Default output Voltage (V)	Rank	Default output Voltage (V)	Rank	Default output Voltage (V)	Rank
LD01	1.8	0	1.8	0	1.8	0	1.8	0	1.8	0
LD02	1.8	0	2.9	2	1.8	0	1.8	0	1.8	0
LD03	1.8	0	1.8	0	1.8	0	1.8	0	1.8	0
LD04	3.3	3	3.3	3	3.3	0	3.3	3	3.3	3
LD05	2.9	2	2.9	2	1.8	0	3.3	2	2.9	2
LD06	1.0	0	1.0	0	1.0	0	1.0	0	1.0	0
REFDDR	0.55	0	0.55	0	0.55	0	0.55	0	0.55	0
BOOST	5.2	N/A	5.2	N/A	5.2	N/A	5.2	N/A	5.2	N/A
BUCK1	1.2	2	1.2	2	1.1	0	1.2	3	1.2	3
BUCK2	1.1	0	1.1	0	1.1	0	1.1	0	1.1	0
BUCK3	3.3	1	1.8	1	1.2	0	3.3	1	1.8	1
BUCK4	3.3	2	3.3	2	1.15	0	1.2	2	1.2	2

Rank = 0: rail not autom. turned ON
Rank = 2: rail autom. turned ON after further 3 ms

Rank = 1: rail autom. turned ON after 7 ms
Rank = 3: rail autom. turned ON after further 3 ms

STPMIC1 and STM32MP1



MAIN APPLICATIONS



Home automation



Industrial control



POS terminals



Networking



Medical monitoring

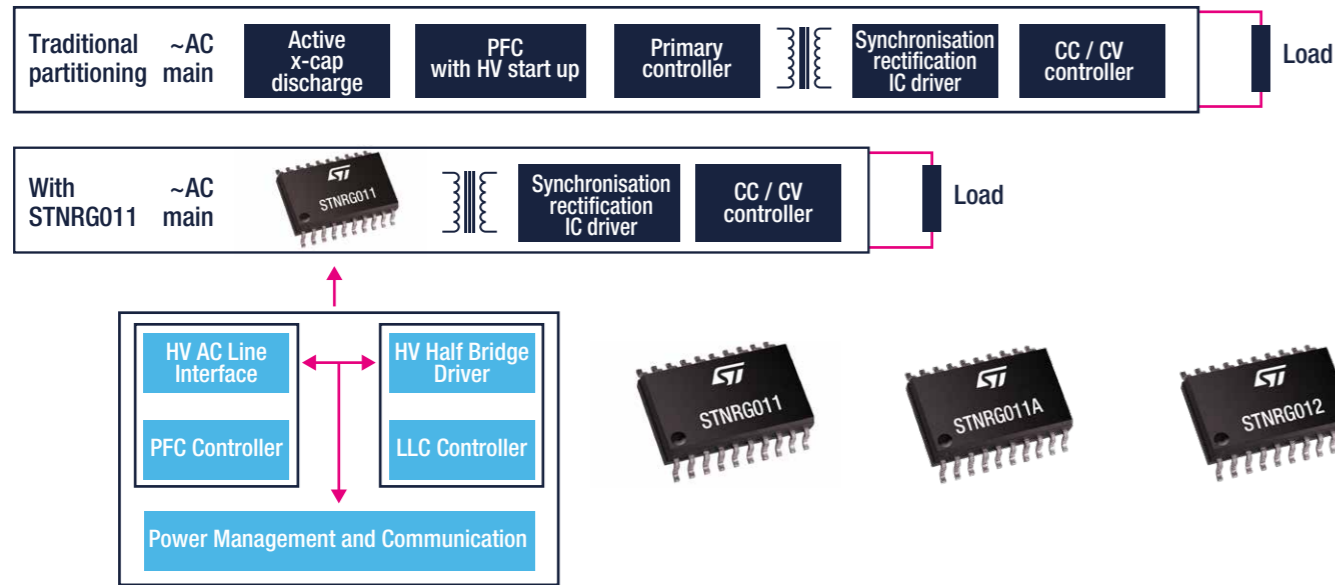


DIGITAL POWER CONTROLLERS AND MICROCONTROLLERS

STNRG Digital Power Controllers

The high level of integration of today's latest features and functions make **STNRG011**, **STNRG11A**, and **STNRG012** ideal for SMPS and lighting applications required to comply with the most stringent energy-saving regulations and guarantees high reliability, safety and BOM optimization. Configurable through an intuitive GUI, ST STNRG digital controllers provide high-end performance and flexibility and do not require any firmware implementation. All the key application parameters of the device are stored in an internal NVM, allowing wide configurability and calibration.

Simplified 2-stage digital smps design with high performance and low component count



Multi-mode digital combo controller (PFC+LLC/LCC)

STNRG011 STNRG011A STNRG012

- Onboard 800 V startup circuit, line sense and X-cap discharge compliant with IEC 62368-1, for reduced standby power (STNRG011 only)
- DC source management with no X-cap discharge (STNRG012 only)
- THD optimizer for LED Lighting applications (STNRG012 only)
- Enhanced fixed on time multi-mode TM PFC controller

- Time-shift control of resonant half-bridge
- ROM memory for SW digital algorithms
- NVM memory for programmable key application Parameters
- Advanced OLP - Over Load Management (STNRG011A only)



MAIN APPLICATIONS



Microcontrollers for digital power

The **32-bit microcontrollers** most suitable for power management applications are the STM32F334 and the STM32G474 MCU from the mixed-signal **STM32F3 series** and **STM32G4 series**, the STM32H743 MCU from the high performance **STM32H7 series**, and those of the entry-level **STM32G0 series**.

The STM32G0 series has a 32-bit ARM® Cortex®-M0+ core (with MPU) running at 64 MHz, and is well suited for cost-sensitive applications. STM32G0 MCUs combine real-time performance, low-power operation, and the advanced architecture and peripherals of the STM32 platform.

The STM32F3 series MCU combines a 32-bit ARM® Cortex®-M4 core (with FPU and DSP instructions) running at 72 MHz with a high-resolution timer and complex waveform builder plus event handler.

The STM32G4 series with 32-bit ARM® Cortex®-M4 core running at 170 MHz continues the STM32F3 series, keeping leadership in analog, leading to cost reduction at the application level and a simplification of the application design.

Finally, the STM32H7 series has a 32-bit ARM® Dual core Cortex®-M7 + Cortex®-M4 (480 MHz + 240 MHz) or single-core Cortex®-M7 (480 MHz) with precision FPU, DSP, and advanced MPU.

STM32 F3, G4, and H7 series contain a flexible high-resolution timer to generate highly accurate pulse-width modulated (PWM) signals for stable control of switched-mode power circuits.

These MCUs specifically address digital power conversion applications, such as digital switched-mode power supplies, lighting, welding, solar, wireless charging, motor control, and much more.

STM32G0

- Cortex®-M0 core
- Very low power consumption
- Timer frequency up to 128 Mhz resolution (8ns)
- High-speed ADCs for precise and accurate control
- More RAM for Flash: up to 36 KB SRAM for 128 KB and 64 KB Flash memory

STM32F334

- Cortex®-M4 core
- High resolution timer V1 (217ps resolution) with waveform builder and event handler
- 12-bit ADCs up 2.5 Msps conversion time
- Built-in analog peripherals for signal conditioning and protection (25ns from fault input to PWM stop)

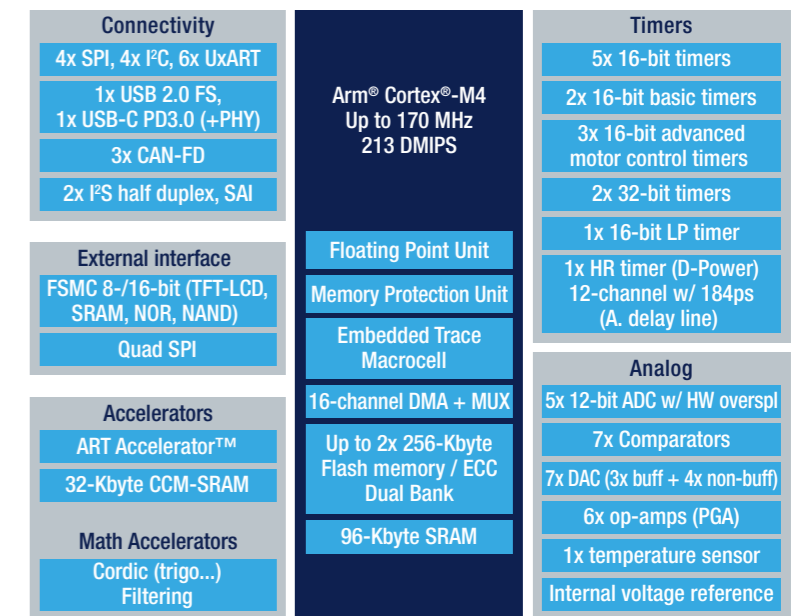
STM32G474

- Cortex®-M4 core
- High resolution timer V2 (184ps resolution) with waveform builder and event handler
- Mathematical accelerator, digital smps and power factor correction
- High-speed ADCs for precise and accurate control (4Msps)

STM32H743

- Cortex®-M7 core
- High performance up to 480 MHz
- High resolution timer V1 (2.1ns resolution) for real time control
- High-speed ADCs for precise and accurate control (3.6 Msps)

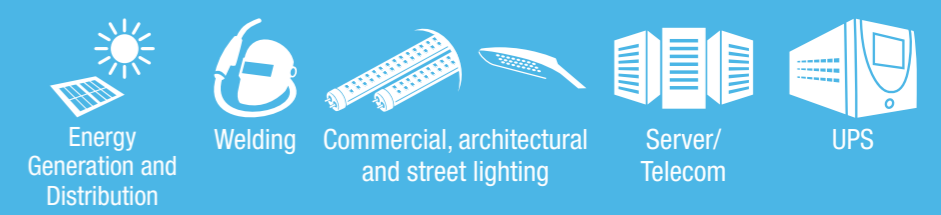
STM32G474 block diagram



- Dual bank flash for live upgrade
- Digital Power Supply and PFC Design Workshop with STM32 MCUs in collaboration with the company partner Biricha



MAIN APPLICATIONS



www.st.com/stm32

STM32 Digital Power Ecosystem

Automotive microcontrollers for in-car digital power


SPC5 automotive microcontrollers are suited for in-car digital power applications, such as traction inverters, on-board chargers, bidirectional DC/DC, and Battery Management Systems.

SPC58 E-line combines real-time behavior with ISO26262 ASIL-D safety.


The embedded hardware security module (HSM) ensures protection against cyber security attacks.

The Generic Time Module (GTM) completes the peripheral set by delivering a high-performance timer, synchronization units, embedded hardware DPLL, and micro-cores.

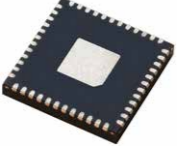
SPC58 Chorus family provides a connected, secure, and scalable platform delivering a wide range of communication interfaces and low-power capabilities to complete the in-car connectivity needs.

 SPC5	SPC58 E Line
Core	Triple 3x e200z4d @ 180 MHz
eFlash Code	4 MB to 6 MB
Timers	GTM3
Safety	ASIL-D
Advanced Networking	8x CAN-FD FlexRay 2x Ethernet
Security	HSM medium
ADC	5x 12 bit (SAR) 3x 10 bit (SAR) 6x 16 bit (SigmaDelta)
High Temperature support (165 Tj)	Qualified

Package Options



eTQFP 64-176
(exposed pad)








QFN 48
(exposed pad)

Scalability





Up to:
3 cores, 200 MHz, 10 MB flash

Networking











Secure & Safety








MAIN APPLICATIONS



Vehicle Security

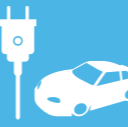

Software over-the-air


Parking Services


Remote Assistance


Maintenance free


Safety


HEV

AutoDevKit, a viable, simple, low-cost toolset for automotive application engineers

AutoDevKit is a new development flow and toolset dedicated to the Automotive & Transportation market, offering engineers the best and easiest approach to quick evaluation and rapid prototyping in a common, integrated, and flexible environment supporting complete ECU-like development.

AutoDevKit is an Eclipse plugin running under the SPC5Studio Integrated Development Environment.



KEY FEATURES

- Focus on developing your application without bothering about hardware and software implementation details.
- Assemble and re-assemble hardware and software components without compatibility issues.
- Expand and customize your application adding new components, scaling your microcontroller for cost optimization, changing the compiler, adding a real-time operating system and other Eclipse-compatible plugins

AutoDevKit Ecosystem

AEK MCU Discovery and Functional Boards

AEKD System Solution Demonstrators



STSW Embedded Software

Find out more at www.st.com/autodevkit


Software download www.st.com/autodevkitsw

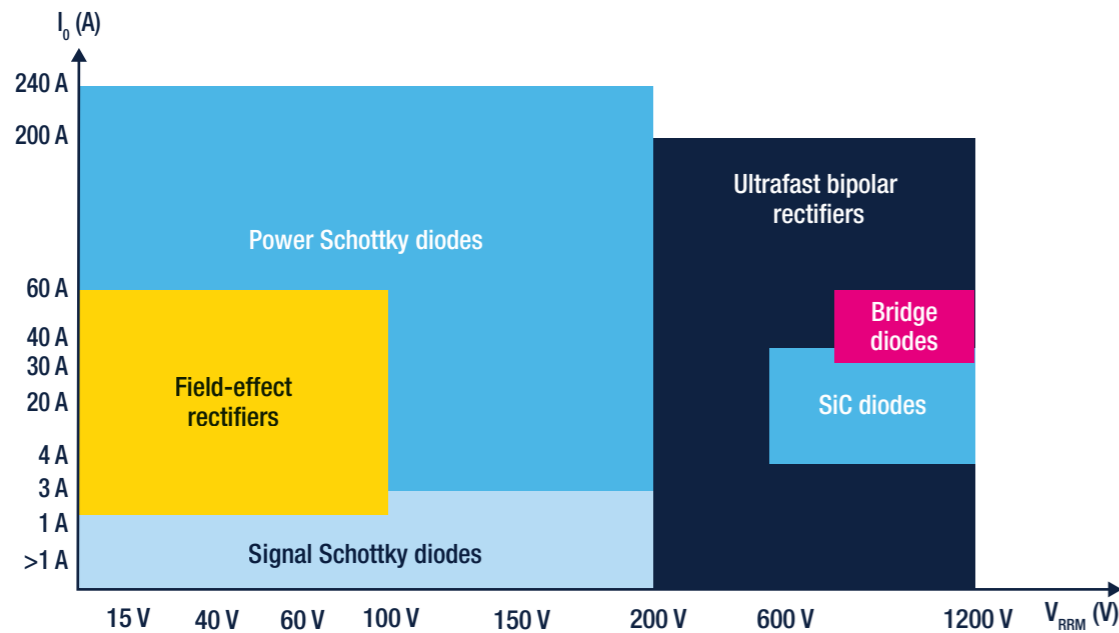
Join our Community at <https://community.st.com/autodevkit>

DIODES AND RECTIFIERS

ST **Schottky** and **Ultrafast** diode portfolio includes 650 to 1200 V SiC and 45 to 100 V field-effect rectifier diodes (**FERD**), ensuring that designers can take advantage of the very latest technologies to develop cost-efficient, high-efficiency converter/inverter solutions. Depending on the targeted application and its voltage, developers can choose from a wide range of devices to ensure the best compromise in terms of forward voltage drop (VF) and leakage current (IR) as well as other characteristics.



 **AEC-Q101 automotive-grade qualified diodes and rectifiers >**



Field-effect rectifiers (FERD)

FERD*

Low voltage diodes, for high efficiency and high power density applications

Power Schottky diodes

STPS*

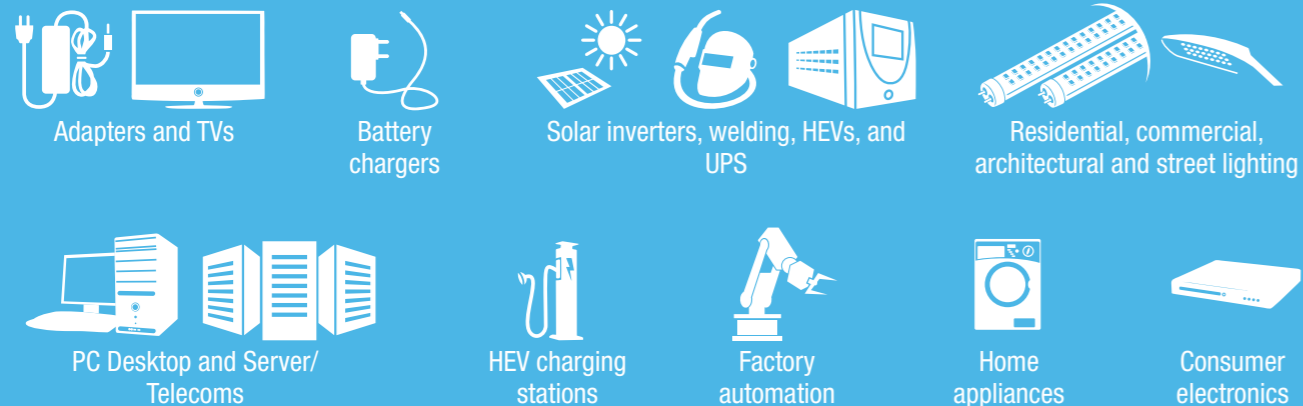
Power Schottky diodes for low voltage general purpose applications

Ultrafast rectifiers

STTH*

Ultrafast high voltage diodes for general purpose application

MAIN APPLICATIONS



www.st.com/schottky
www.st.com/ultrafast-rectifiers
www.st.com/field-effect-rectifier-diodes

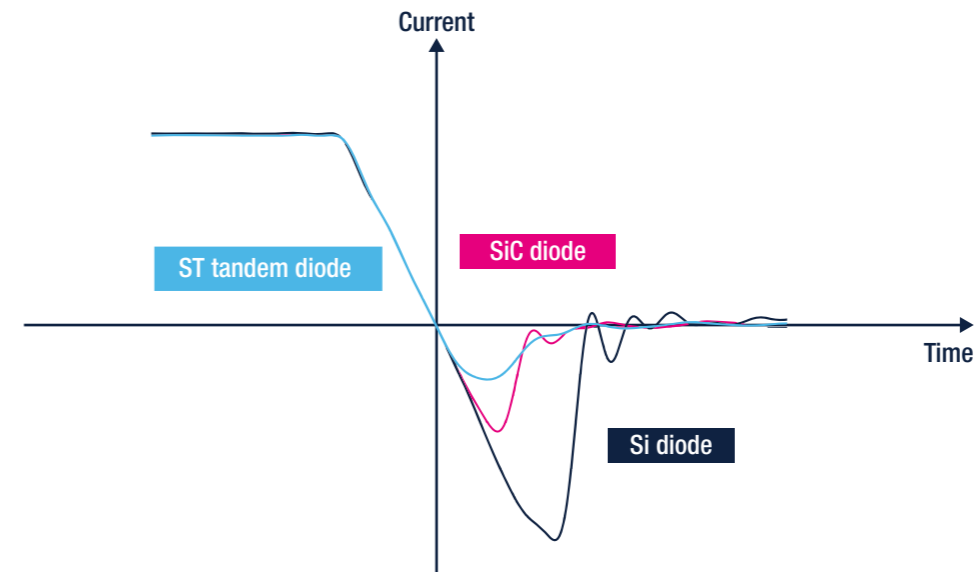
Note: * is used as a wildcard character for related part number

SiC diodes

In addition to ensuring compliance with today's most stringent energy efficiency regulations (Energy Star, 80Plus, and European Efficiency), ST **silicon carbide** diodes feature four times better dynamic characteristics with 15% less forward voltage (VF) than standard silicon diodes. Silicon carbide diodes belong to the STPOWER family.

The efficiency and robustness of solar inverters, motor drives, uninterruptible power supplies, and circuits in electrical vehicles are therefore greatly improved by the use of silicon carbide (SiC) diodes.

ST proposes a 600 to 1200 V range with single and dual diodes in packages ranging from DPAK to TO-247, including the ceramic insulated TO-220 and the slim and compact PowerFLAT 8x8 featuring excellent thermal performance and representing, the new standard for high-voltage (HV) surface-mount (SMD) packages and available for 650 V SiC Diodes from 4 to 10 A.



SiC diodes provide zero recovery time with negligible switching losses

SIC DIODES BENEFITS

- High efficiency adding value to the power converter
- Reduced size and cost of the power converter
- Low EMC impact, simplifying certification and speeding time to market
- High robustness ensuring high reliability of the power converter
- Gain on PCB and mounting cost with the dual diodes

650 V SiC diodes in insulated TO-220 packages: the solution to speed production

STPSC*065

STPSC*H12

- 650 V (STPSCx065)
- 1200 V (STPSC*H12)
- 2 available trade-offs, low VF and High surge

MAIN APPLICATIONS



www.st.com/sic-diodes

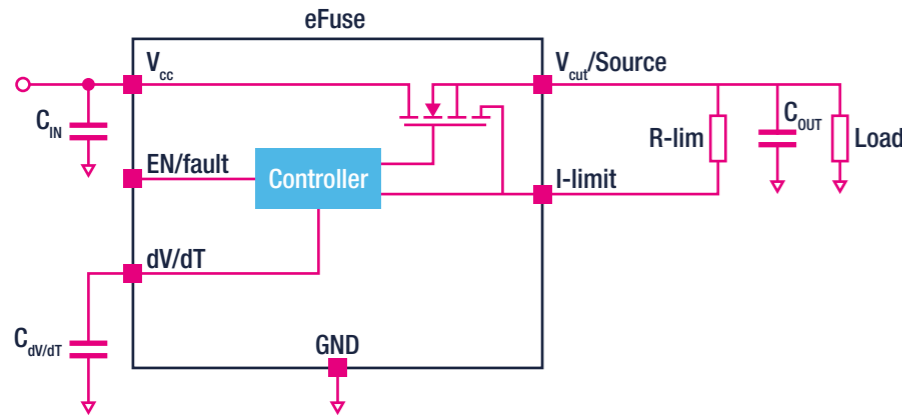
Note: * is used as a wildcard character for related part number

eFuses AND HOT-SWAP ICs

eFuses

eFuses are electronic fuses that can replace larger conventional fuses or other protections, reducing ownership costs in production and in the field.

Unlike fuses, they offer complete and flexible management of the fault (overcurrent/overvoltage) without requiring replacement after actuation. They thus help improve equipment uptime and availability, and also reduce maintenance costs and false returns. Compared to traditional protection devices, these new electronic fuses enable versatile and simple programming of protection parameters such as overcurrent threshold and start-up time.

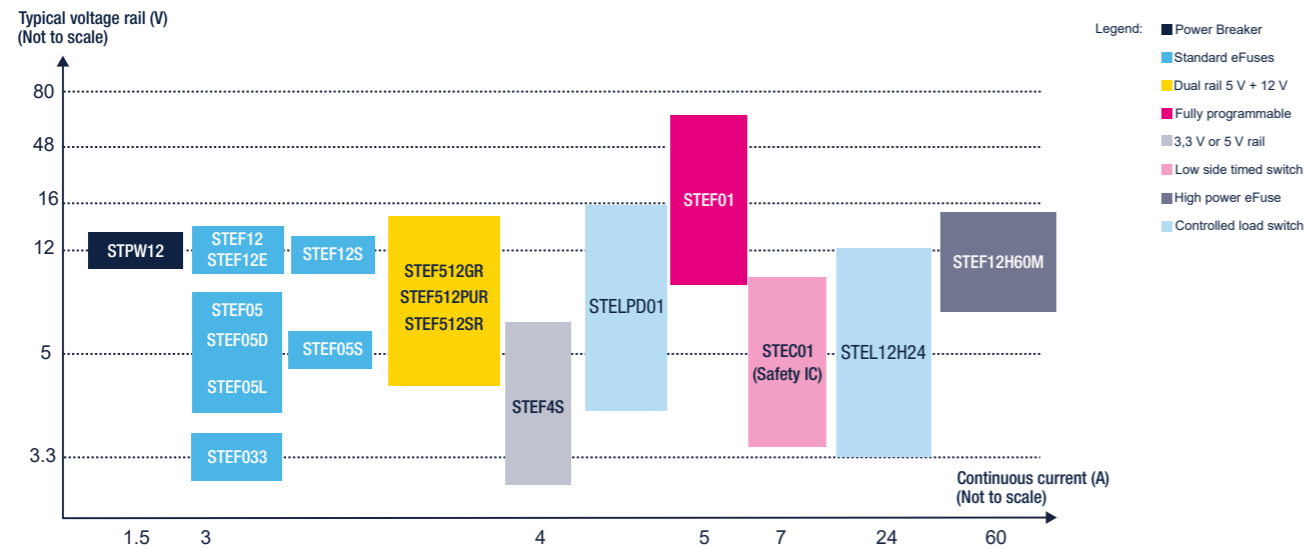


eFuse MAIN FEATURES

- Do not degrade or require replacement after a trip event
- Programmable over-current protection and turn-on time
- Latched or autoretry function
- Overvoltage clamp
- Over-temperature protection
- Integrated power device
- Internal undervoltage lockout

www.st.com/efuse

eFuses, a smart offer for a lots applications



MAIN APPLICATIONS



Home appliances
STEF05, STEF01,
STEF12, STEF12S



Server and Data Storage
STEF033, STEF05, STEF05L,
STEF4S, STEF12,
STEF05S, STEF12S,
STEF512, STEF512SR,
STEL12H24



USB connections
STEF05, STEF05L,
STEF05S, STELPD01



Factory automation
STEF01,
STEF12, STEF12S,
STELPD01



Set-top boxes
STEF12,
STEF12S

Power breakers

Connected in series to the power rail, **ST power breakers** are able to disconnect the electronic circuitry when power consumption exceeds the programmed limit. When this happens, the device automatically opens the integrated power switch, disconnecting the load, and notifies the remote monitoring feature.

The STPW programmable electronic power breaker family provides a convenient and integrated solution for quickly and safely disconnecting a faulty load from a 12 V bus.

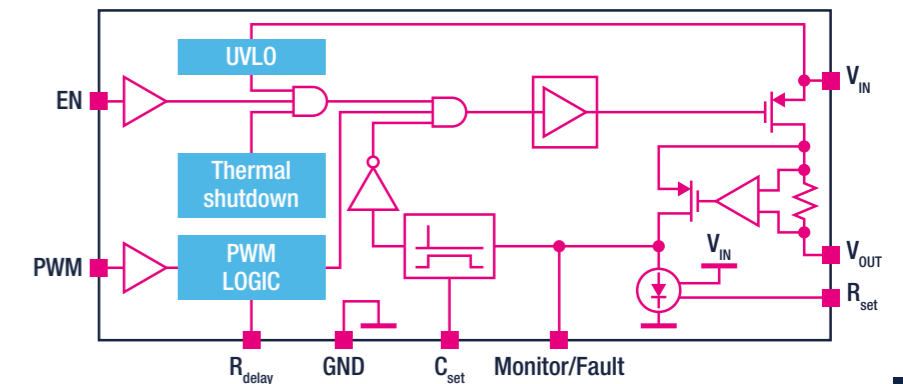
Inserted between the power rail and the load, STPW power breakers contain a low-resistance (50 mΩ) power switch and precision circuitry for sensing the load power. If the user-programmed limit is exceeded, the switch turns off and a signal on the dedicated monitor/fault pin informs the host system. In normal operation, this output presents an analog voltage proportional to the load power to permit continuous monitoring.

Also featuring built-in auto-restart after a user-adjustable delay and programmable PWM masking time to prevent protection triggering by inrush current, the STPW family simplifies design for safety and eases certification for standards such as the UL 60730 specifications for abnormal operation. This integrated solution effectively replaces discrete circuitry or a combination of ICs such as a current-sense amplifier or a hot-swap controller plus MOSFET switches, by offering improved accuracy and saving board space and bill of materials for each load protected.

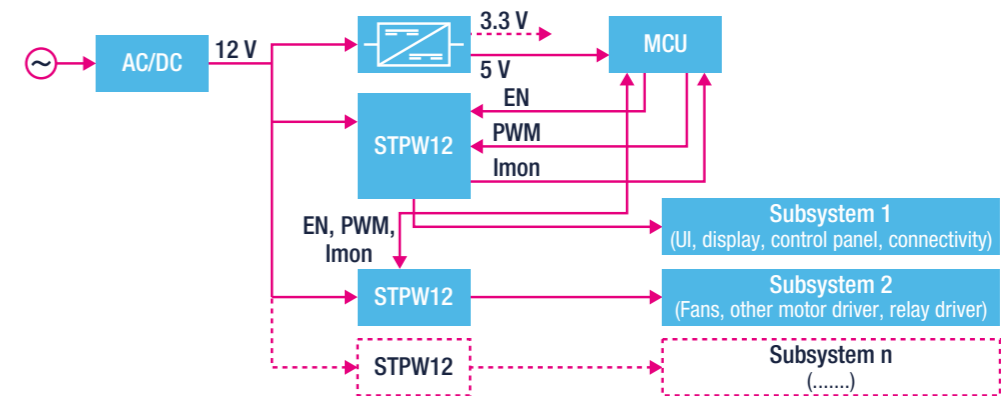
Power breakers

STPW12

- Auto-retry function with programmable delay
- Adjustable precise power limitation from 11 to 16 W
- 12 V rails
- Programmable power limit masking time
- Over-temperature protection
- Integrated N-channel power MOSFET
- Internal undervoltage lockout



Typical home appliance block diagram for STPW12



MAIN APPLICATIONS



Home appliances
STPW12



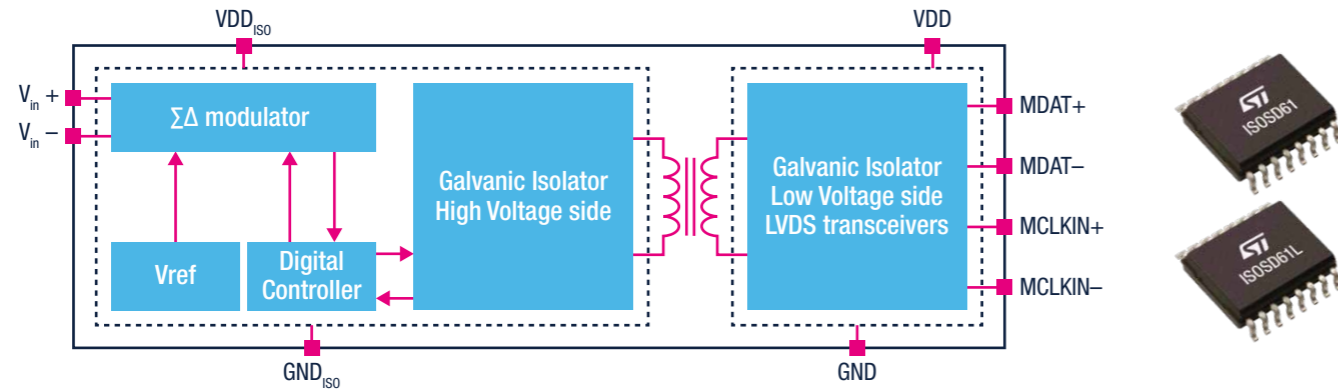
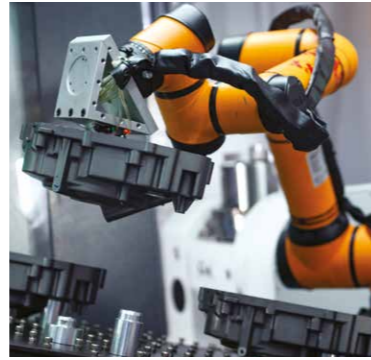
Air conditioning
STPW12



Factory automation
STPW12

GALVANIC ISOLATED SIGMA-DELTA ADC

The galvanically isolated **ISOSD61/ISOSD61L** second order Sigma-Delta modulator, based on the highly successful ST transformer coupling technology, is available in the single-ended (**ISOSD61**) and differential (**ISOSD61L**) signaling versions. It converts analog input signals into high-speed single-bit digital data streams, from which analog information can be recovered by a low-pass filter and further processed by a host controller. The modulator protects the output peripheral interface with a galvanic isolation barrier that separates low and high voltage domains and blocks stray currents between different grounds. The silicon-based isolation technology offers a number of advantages over traditional opto-coupling, including significantly lower power consumption, higher data transfer rates, and greater reliability for longer device lifetime, and over Hall-effect sensors in terms of accuracy, noise rejection, latency, form factor, and cost.



KEY FEATURES

- 2nd order 16-bit Sigma-Delta Modulator
- ± 320 mV Full Scale Differential Input Signal Range
- Up to 25 MHz external clock input for easier synchronization
- Up to 50 kHz Bandwidth
- 86 dB typical SNR
- -83 dB typical THD
- 30 kV/ μ s typical Common-Mode Transient Immunity
- 6 kV VPEAK Highest Allowable Over-Voltage (V_{IOTM})
- 6 kV VPEAK Maximum Surge Insulation Voltage (V_{IOSM})
- 1.2 kV V_{PEAK} Maximum Working Insulation Voltage (V_{IORM})
- Flexible interface options: Low Voltage Differential Signaling (LVDS) and Single Ended (TTL/CMOS) options
- -40 °C to $+125$ °C extended industrial temperature range
- S0-16 wide package

Product table

Part Number	Version	Input Range	Max. Clock Frequency	Resolution	SNR	Isolation	CMTI	Package & Packing
ISOSD61	TTL/CMOS	± 320 mV	25 MHz	16-bit	86 dB	1.2 kV Viorm	30 kV/us	S016W Tray
ISOSD61TR	TTL/CMOS							S016W Tape & Reel
ISOSD61L	LVDS							S016W Tray
ISOSD61LTR	LVDS							S016W Tape & Reel

MAIN APPLICATIONS



Servo drive



Factory automation



EV charging station



Server & telecom power



IGBTs

ST offers a comprehensive portfolio of **IGBTs (Insulated Gate Bipolar Transistors)** ranging from 600 to 1700 V in trench gate field-stop (TGFS) technologies.

Featuring an optimal trade-off between switching performance and on-state behavior (variant), ST IGBTs are suitable for industrial and automotive segments in applications such as general-purpose inverters, motor control, home appliances, HVAC, UPS/SMPS, welding equipment, induction heating, solar inverters, traction inverters, on-board chargers, and fast chargers.

Industrial

Breakdown Voltage								
600 V	650 V			1200 V	1250 V	1700 V		
Nominal Current								
4 to 20 A	20 to 80 A	4 to 200 A	15 to 100 A	20 to 50 A	8 to 75 A	15 to 75 A	20, 30 A	50 A (bare die)
Switching frequency								
8 to 30 kHz	50 to 100 kHz	2 to 20 kHz	16 to 60 kHz		2 to 20 KHz	20 to 100 kHz	16 to 60 kHz	2 to 20 KHz
IGBT Series								
H	V	M	HB/HB2	IH	M	H	IH	M
Focus Applications								
Home appliances	Welding, PFC, solar, UPS, charger	Industrial motor control, automotive traction inverter, GPI, Air-Con	PFC, Solar, UPS, Charger, Welding and soft switching	Induction heating and soft switching	Industrial motor control, GPI, Air-Con	Welding, PFC, solar, UPS, charger	Induction heating, microwave and soft switching	Industrial motor control, GPI, Windmill

Automotive

Breakdown Voltage					
600 V	650 V			750 V	1200 V
Nominal Current					
20 to 80 A	30 to 200 A	20 to 80 A	15 to 100 A	200 to 500 A	15 to 40 A
Switching frequency					
50 to 100 kHz	2 to 20 kHz	16 to 60 kHz		2 to 20 KHz	2 to 20 KHz
IGBT Series					
V	M	HB	HB2 (eligible)	MH	MS
Focus Applications					
OBC (PFC section)	Traction inverter, Motor Control, Aux loads, PTC heaters	OBC (PFC), Air-Con		EV, HEV Traction inverter	Motor Control, Aux loads, PTC heaters, Battery thermal management

Development

H series

STG*H*

H* - 600 V family

- 3 μ s of short-circuit capability
- Low saturation voltage
- Minimal collector turn-off
- Series optimized for home appliance applications

H - 1200 V family

- 5 μ s of short-circuit capability @ starting $T_J = 150^\circ\text{C}$
- Low turn-off losses
- Up to 100 kHz as switching frequency

HB series

STG*H*B

- Low saturation voltage
- Minimal tail current turn-off
- Different diode option
- Optimum trade-off between conduction and switching losses
- Low thermal resistance
- 4 leads package available
- Very high robustness in final application
- Automotive eligible

MH series

STG*MH*

- Increased BV robustness and current density
- Low $V_{CE(sat)} = 1.3\text{ V (typ.) @ IC = 300A}$
- Integrated Kelvin and current sensing option
- Enhanced switching performances
- Dice top and back metallization suitable for high performance linking
- High current and temperature fully tested
- Rebuilt wafers for customized modules

V series

STG*V60*F

- Optimized for high switching frequencies
- Negligible current tail at turn-off
- Very low turn-off switching losses
- Soft and very fast recovery antiparallel diode
- Up to 100 kHz in hard switching topologies
- AEC-Q101 qualified device

HB2 series

STG*H*FB2

- Very low saturation voltage
- Reduced gate charge
- Different diode option
- Optimum trade-off between conduction and switching losses
- Low thermal resistance
- 4 leads package available
- High efficiency in final application
- Automotive eligible

M series

STG*M*

650 V family

- 6 μ s of min short-circuit capability @ starting $T_J = 150^\circ\text{C}$
 - Wide safe operating area (SOA)
 - Very soft and fast recovery antiparallel diode
 - Suitable for any inverter system up to 20 kHz
- AEC-Q101 qualified devices

1200 V family

- 10 μ s of min short-circuit capability @ starting $T_J = 150^\circ\text{C}$
- Freewheeling diode tailored for target application
- Suitable for any inverter system up to 20 kHz

IH series

STG*IH*

650 V IH family

- Very low $V_{CE(sat)}: 1.5\text{ V @ ICN}$
- Very low E_{off}
- Low drop forward voltage diode
- Designed for soft commutation application only

1250 V IH family

- Minimized tail current
- Very low drop freewheeling diode
- Tailored for single-switch topology

MS series

STG*MS*

- Designed for automotive application
- 8 μ s of short-circuit withstanding time @ $V_{CC}=800\text{ V}, V_{GE}=15\text{ V}, T_{J-start}=150^\circ\text{C}$
- Maximum continuous operating junction temperature: $T_J=175^\circ\text{C}$
- Low $V_{CE(sat)} = 1.95\text{ V (typ.) @ IC = 40A}$

MAIN APPLICATIONS



Note: * is used as a wildcard character for related part number

www.st.com/igbt

INTELLIGENT POWER MODULE - SLLIMM











The **SLLIMM**, small low-loss intelligent molded module, is the ST family of compact, high efficiency, dual-in-line **intelligent power modules (IPM)** with extra optional features. This family includes different solutions in terms of package (SMD, through hole, full molded, and DBC) and silicon technology (IGBT, MOSFET and superjunction MOSFET). Optimally balancing conduction and switching energy with an outstanding robustness and EMI behavior makes the new products ideal to enhance the efficiency of compressors, pumps, fans, and any motor drives working up to 20 kHz in hard switching circuitries and for an application power range from 10 W to 7 KW.

KEY FEATURES

- Low $V_{CE(sat)}$, Low $R_{DS(on)}$
- Optimize driver and silicon for low EMI
- Lowest R_{th} value on the market for the DBC package versions
- Internal bootstrap diode
- Maximum junction temperature: 175 °C for IGBT and 150 °C for SJ-MOSFET
- Separate open emitter outputs
- NTC on board
- Integrated temperature sensor
- Comparator for fault protection
- Shutdown input/fault output

KEY BENEFITS

- Integrated and efficient solution
- Easy to drive through microcontroller
- Higher robustness and reliability
- Plug'n Play solution

SLLIMM nano SMD	SLLIMM nano	SLLIMM nano 2nd series	SLLIMM 2nd series	SLLIMM HP
600 V IGBT 500 V MOSFET 1 up to 3 A	600 V IGBT 500 V MOSFET 1 up to 3 A	600 V IGBT 600 V SJ-MOSFET 3 up to 8 A	600 V IGBT 600 V SJ-MOSFET 8 up to 35 A	IGBT 650 V, 50 A 1200 V, 10 A
				
NSDIP-26L (SMD) 12.45 x 29.15 x 3.10 mm	NDIP-26L (TH) 12.45 x 29.15 x 3.10 mm	N2DIP-26L (TH) 12.45 x 32.15 x 4.10 mm VISO = 1.5kVrms/min	SDIP2F-26L SDIP2B-26L 24 x 38 x 3.5 mm VISO = 1.6kVrms/min	SDIPHP-30L 31 x 52 x 5.6 mm VISO = 2.5kVrms/min
Power rating: 10 to 80W 	Power rating: 60 to 110W 	Power rating: 100 to 600W 	Power rating: 300W to 3kW 	Power rating: 3 to 7kW 

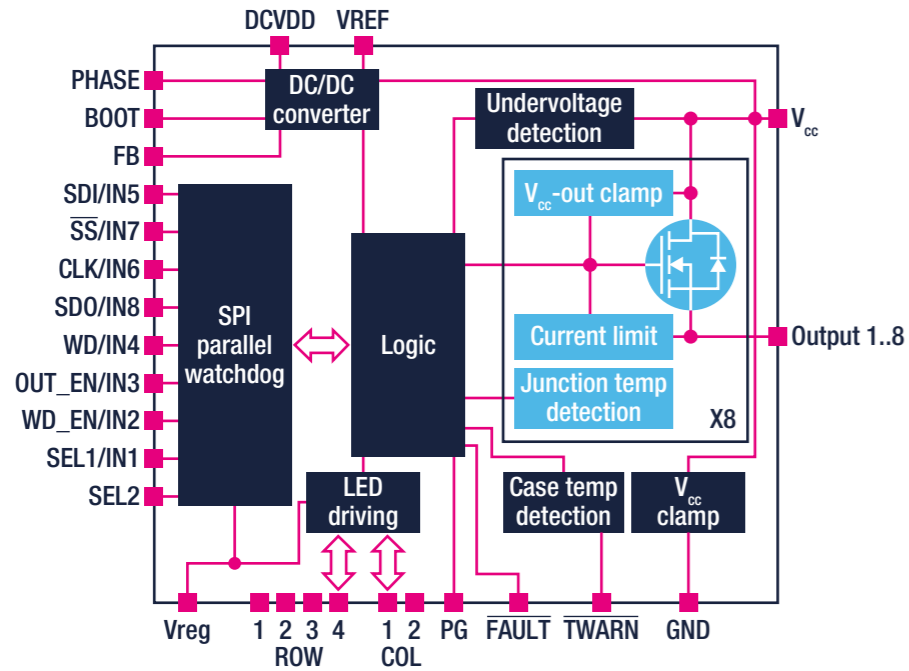
www.st.com/igbt



INTELLIGENT POWER SWITCHES

STMicroelectronics offers **intelligent power switches (IPS)** for low- and high-side configurations. ST IPS feature a supply voltage range from 6 to 60 V, overload and short-circuit protection, current limitation set for industrial applications, different diagnostic types, high-burst, surge and ESD immunity, very low power dissipation, and fast demagnetization of inductive loads.

The devices are designed using ST latest technologies for state-of-the-art solutions in any application field.



IPS MAIN FEATURES

- Logic
- Driving
- Protections
- Diagnostic
- Power stage
- Isolation
- ...all on a single chip

www.st.com/ips

Output Current/Channel (A)

5	IPS1025H(Q)-32 ²	IPS2050H(Q)-32 ²		
2	IPS160H ² , IPS160HF ² , IPS1025H(Q) ² , IPS1025HF(Q) ² , VN540SP ⁴ , VN751 ⁴ , L6370 ⁴	IPS2050H(Q) ²		
1		VNI2140J ⁴	VNI4140K-32 ⁴ VN340SP-33 ⁴	ISO808(Q)-1 ¹ , ISO808A(Q)-1 ¹ VN808(CM)-32 ⁴ , VNI8200XP-32 ⁴ , IPS8160HQ-1 ⁴
0.5	IPS161H ² , IPS161HF ² , L6375 ⁴ , L6377 ⁴ , TDE1707 ⁴ , TDE1897 ⁴ , TDE1898 ⁴ , TDE1798 ⁴		IPS4260L ³ , VNI4140K ⁴ , VN330SP ⁴ , VN340SP ⁴ , L6376 ⁴	ISO8200AQ 1, ISO8200B(Q) ¹ , ISO808(Q) ¹ , ISO808A(Q) ¹ , VN808(CM) ⁴ , VNI8200XP ⁴ , IPS8160HQ ⁴
<0.5	TDE1708DF ⁴ , TDE3247 ⁴ , TDE1747 ⁴		VN0860 ⁴ , L6374 ⁴	
	Single Channel	Dual Channel	Quad Channel	Octal Channels

Note 1: Isolated HS 2: 60V HS 3: LS 4: HS

MAIN APPLICATIONS



Factory automation



Vending machines



Renewable energy



Lighting for Building Automation

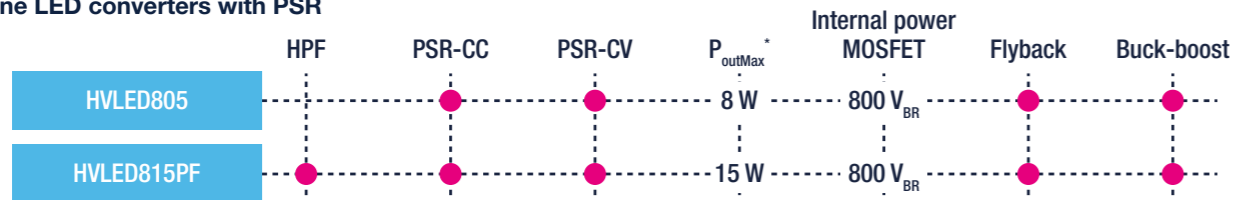


LED DRIVERS

Offline LED drivers

Dedicated **LED drivers** operating from the AC mains ensure highly accurate LED control to provide a high level of light quality and avoid flickering. By combining state-of-the-art low-voltage technology for the controller and extremely robust 800 V technology for the power MOSFET in the same package, HVLED8* converters (i.e., controller + MOSFET in the same package) feature an efficient, compact, and cost-effective solution to drive LEDs directly from the rectified mains. This family of converters works in constant-current/constant-voltage primary-side regulation (PSR-CC/CV). HVLED001A and HVLED001B controllers are also available for high power needs working in constant-voltage (PSR-CV) primary-side regulation; a dimming function is also available. For both families (HVLED converters and controllers), the primary-side regulation cuts bill-of-material costs, while also simplifying design and reducing the space occupied by LED control circuitry.

Offline LED converters with PSR



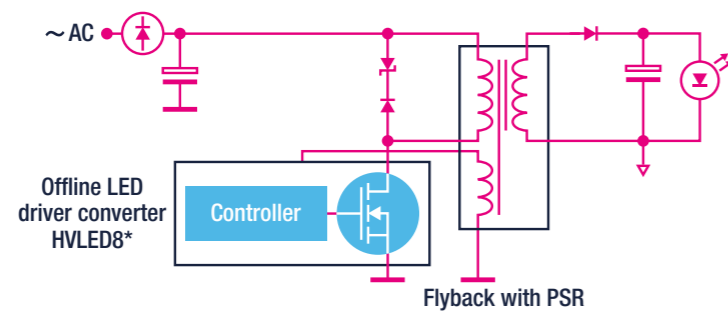
Offline LED controllers with PSR



Offline LED controllers



Topology example



MAIN APPLICATIONS

Residential lighting
HVLED815PF

Commercial and street lighting
HVLED001A, HVLED001B, HVLED007

www.st.com/led

Note: * output power for european input voltage 230 Vac

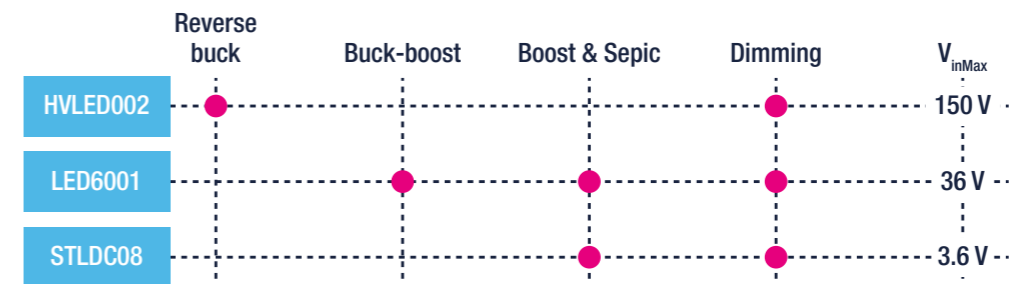
DC-DC LED drivers

ST monolithic buck switching regulators offer input voltage capability up to 61 V and deliver output currents up to 4 A with high switching frequency. They enable simple, efficient, and cost-effective solutions for driving high-brightness LEDs. They also feature dedicated circuitry for dimming. Boost regulators provide the necessary high voltages to drive multiple LEDs in series, guaranteeing accurate LED current matching.

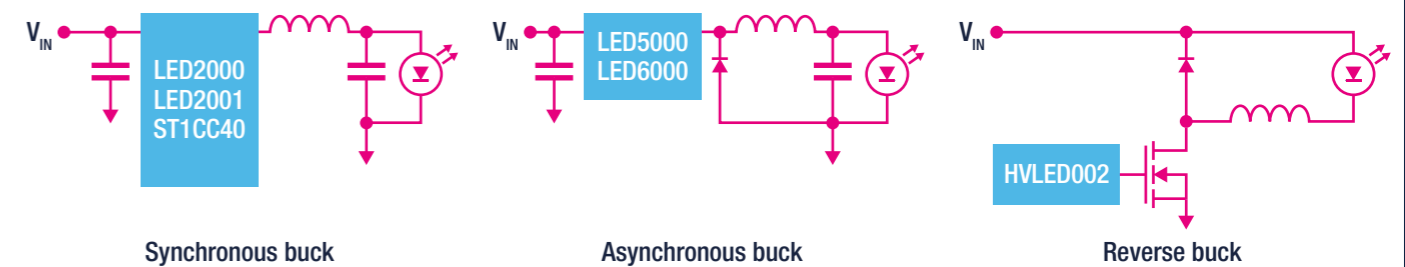
DC-DC LED drivers converters



DC-DC LED drivers controllers



Topology examples



MAIN APPLICATIONS

Halogen bulbs replacements and home appliances
LED5000, LED6000

Traffic signals
LED2000, LED2001, ST1CC40, LED5000, LED6000

Street lighting
LED5000, LED6000, HVLED002

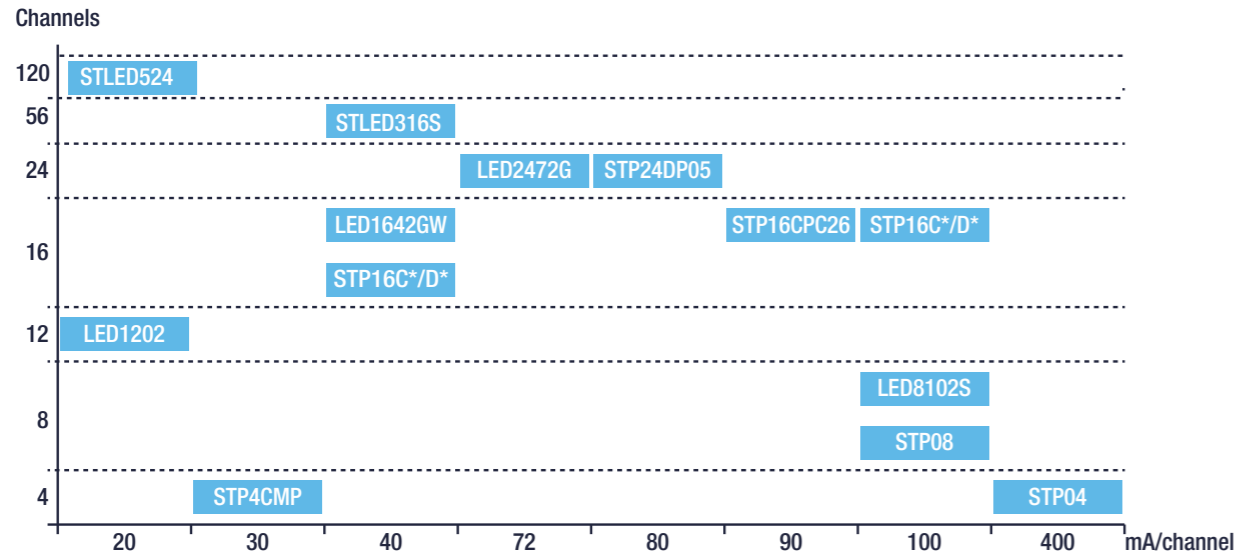
Emergency lighting
LED6001, ST1CC40

Commercial and architectural lighting
LED5000, LED6000, LED6001, HVLED002

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LED array drivers

ST LED array drivers fully integrate all functions required to drive high-brightness LEDs. These devices allow constant-current control in a single-chip solution. The external parts are reduced to only one resistor that sets the preferred maximum current for all outputs. Devices also come with additional features such as high current, high precision, local and global LED brightness adjustment, thermal shutdown, error detection, and auto power-saving functionalities.



24 channel RGB (8x3) drivers

- Current gain control (LED2472G), constant current (STP24DP05)
- Error detection
- Autopower saving (LED2472G)

5x24 matrix drivers

- 20 mA/dot
- Adjustable luminance for each LED (dot)

12/16 channel drivers

- Current gain control (LED1642GW), constant current (STP16C*/D*)
- Error detection (STP16C*/D*)
- Dot correction (LED1202)
- Autopower saving
- Local dimming (LED1642GW, LED1202), global dimming (STP16C*/D*)

4/8 channel drivers

- Constant current
- Direct I/O (LED8102S)
- Error detection (STP08)
- Global dimming

16 Digit, 56 LED Matrix

- 40 mA Current capability
- 6 Key-scanning (8 x 2 matrix)
- 3-wire serial bus interface

MAIN APPLICATIONS



Traffic signals

LED8102S, LED2472G, STP24DP05, STP04



Large panel signs

LED1642GW, LED2472G, STP24DP05, STP16, STP08



Home appliances

LED8102S, STP16, STP08, LED1642GW, STP4CMP, STLED524



Special lighting

STP04, LED1642GW, LED2472G, LED8102S



Smartphones / Wearable

STLED524, LED1202

Note: * is used as a wildcard character for related part number

www.st.com/led

LED row drivers

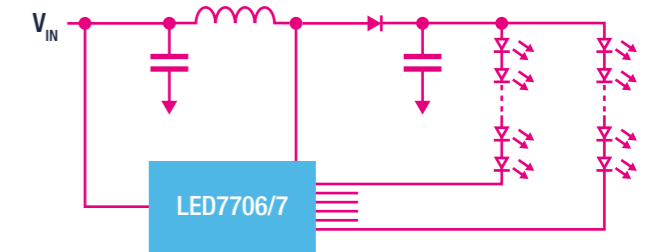
LED row drivers are essentially boost regulators that provide the necessary high voltages to drive multiple LEDs in series, guaranteeing accurate LED current matching.

ST offers both single- and multi-channel high-efficiency boost LED drivers featuring a wide dimming range, low noise, and small footprint. They also embed protection functions such as overvoltage and overcurrent protection, thermal shutdown, and LED-array protection.

LED row driver converters

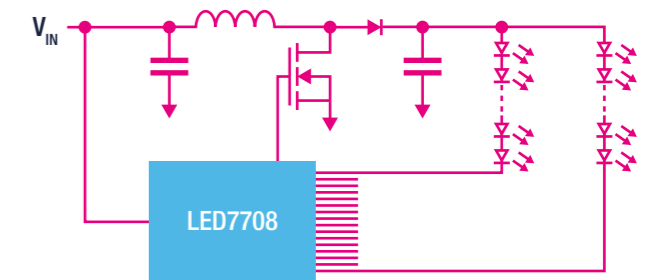
Rows	Device	Current Capability
6 rows	LED7707	• 85 mA/row
	LED7706	• 30 mA/row
1 row	STLA02*	• 20 mA/row
	STLD40D	• 0.5 A/1.5 A/2 A/row
	STCS*	• 0.5 A/1.5 A/2 A/row

Global dimming



LED row driver controllers

Rows	Device	Current Capability
16 rows	LED7708	• 85 mA/row • Grouped or independent row dimming



MAIN APPLICATIONS



Smartphones
STLA02, STLD40D



Keyboard and accessories
STLA02*



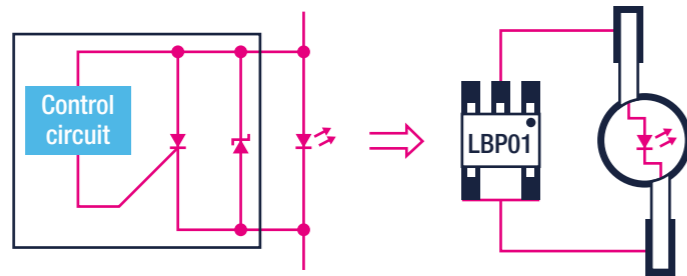
Home appliances and ATMs
LED7706, LED7707, LED7708, STCS*

Note: * is used as a wildcard character for related part number

www.st.com/led

LED bypass protection

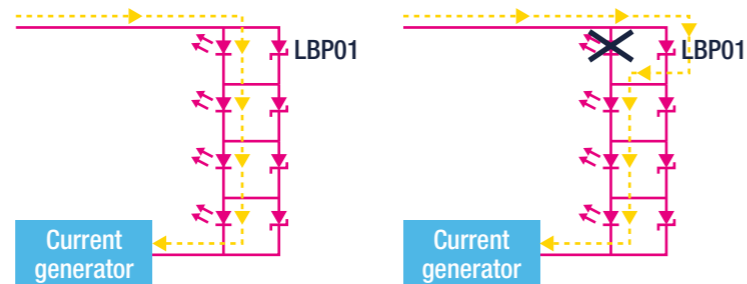
The **LBP01** series of LED bypass protection devices are bypass switches that can be connected in parallel with 1 or 2 LEDs. In the event of a LED failure, this device shunts the current through other LEDs. It also provides overvoltage protection against surges as defined in IEC 61000-4-2 and IEC 61000-4-5



lbp01 get reliable your led application

LBP01

- Keep LED strings on in case of LED open mode failure
- Reduced maintenance cost
- Increase lifetime of the lighting system



LINEAR VOLTAGE REGULATORS

ST offers a complete portfolio of industry-standard **high-performance regulators** for both positive and negative outputs. Among our products, you can find the optimal combination of ultralow dropout voltage (from 50 to 220 mV for 100 mA to 3 A load current) and low quiescent current - for the highest efficiency design - (from 0.3 to 20 μ A for 50 mA to 2 A) or dynamic performance for the best transient response, power supply ripple rejection (up to 92 dB at 1 kHz), and low noise (as low as 6.3 μ Vrms). This is coupled with a range of the smallest form factor packages for size-conscious applications, such as a 0.47 x 0.47 mm STSTAMP package.



			Ultra-low dropout	Low Iq	Low noise, high PSRR
STLQ015	LDK120/130	LD39015	●	●	●
STLQ50	LD040L	LD59030	●	●	●
ST/LDK715	LDK220	LD39020/30	●	●	●
ST1L08	LDK320	ST730/2	●	●	●
LD56100	LD56050	LD39050/100/49100	●	●	●
LDBL20	LDCL015	LD57100	●	●	●
LDFM/LDF	LDLN015	LD39115J	●	●	●
LD59100	LDL112	LD39130S	●	●	●
STLQ020	LDL212	LD39200	●	●	●
LDLN025/30/50	LD59015	LD59150	●	●	●
L5050	L5150	L5300	●	●	●
L99VR01	L4949	L4995	●	●	●

Ultra-low dropout

- High efficiency in low-/medium-power applications
- Best cost/performance trade-off
- Large offer for lout capability and packaging

Low quiescent current Iq

- Extending battery life
- Suitable for space-constrained battery-powered applications

Low noise, high PSRR

- High signal fidelity
- Reduced size of external filter components

MAIN APPLICATIONS



www.st.com/lbp01

MAIN APPLICATIONS

Tablets, smartphones, and wearables
LD39115, LD39130, LD39020/30, ST1L08, LDBL20, LD59015, LDLN025/30 /50, STLQ020, LD56030, LD56050, LD56100, LD57100, L99VR01

Healthcare
STLQ015, STLQ020, ST715, LD39130

Home appliances
LDK220/320, LDF, LDFM, LDL212, ST730/2

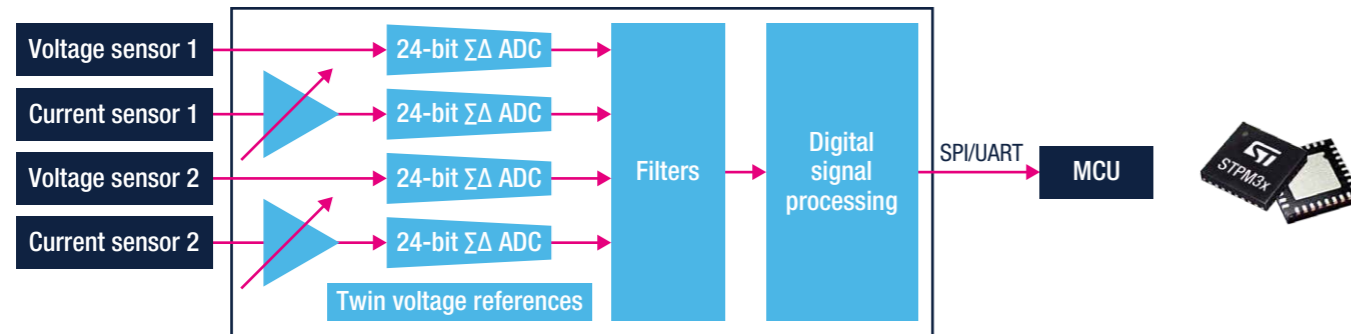
Automotive ADAS, ECU
LDK130, LD39100, LD59150, LD040L, L5050, L5150, L99VR01, L4949, L4995, L5300

www.st.com/linear-regulators

METERING ICs

STPM32, STPM33, and STPM34 are high accuracy AFE (Analog Front End) for DC and AC energy measurement, offering high accuracy down to extremely low current typical of home appliances in standby. A full set of on-board features provides high system integration and enables on-chip power quality monitoring, reducing smart-meter cost of ownership, and contributing to a fast and easy design to dramatically reduce manufacturing time and cost.

STPM34: 4 independent channels block diagram



KEY FEATURES

- Up to 4 independent 24 bits 2nd order $\Sigma\Delta$ ADC with PGA Integrated DSP for "turn-key energy parameters calculations"
- Built-in twin independently temperature compensated voltage references
- Double LED output programmable for active and reactive energy pulses generation
- Applicable to Class 0.2 meters
- < 0.1% active power accuracy over a dynamic range of 5000:1
- 3.6 kHz Bandwidth
- Very fast single point calibration
- AC and DC measurement
- Multiple sensors support: Shunt, current transformer, Rogowsky coils
- Multiple host interfaces 5 and 3 wires SPI, UART
- I, V bit stream available to host controller for customer own processing
- Case removal and Neutral Anti-tamper detection
- Exceeds 50-60 Hz EN 50470-x, IEC 62053-2x, ANSI12.2x

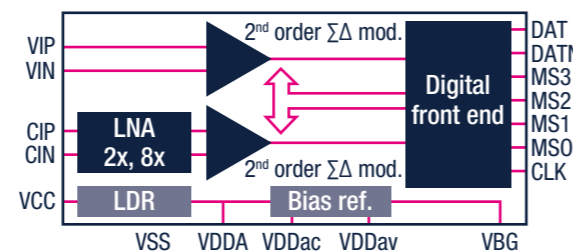
STPMS2

The STPMS2, also called smart-sensor, is a dual SD modulator with embedded PGA. In combination with a microcontroller that embeds DFSDM filters, it allows you to position the A/D conversion (STPMS2) very close to the current transducers, therefore minimizing noise capture from the analog tracks. Once converted, the SD streaming of voltage and current are multiplexed and transferred through a single-wire data line to the MCU.

KEY FEATURES

- Two 2nd order SD modulators
- 0.1% active energy max. error over 1:2500 dynamic range
- Standards supported: EN 50470-1, EN 50470-3, IEC 62053-21, IEC 62053-22,
- IEC 62053-23, ANSI C12.1-2001, ANSI C12.10-1997, ANSI C12.20-2002
- Fast digital calibration
- Allows the use of multiple shunts

STPMS2



MAIN APPLICATIONS



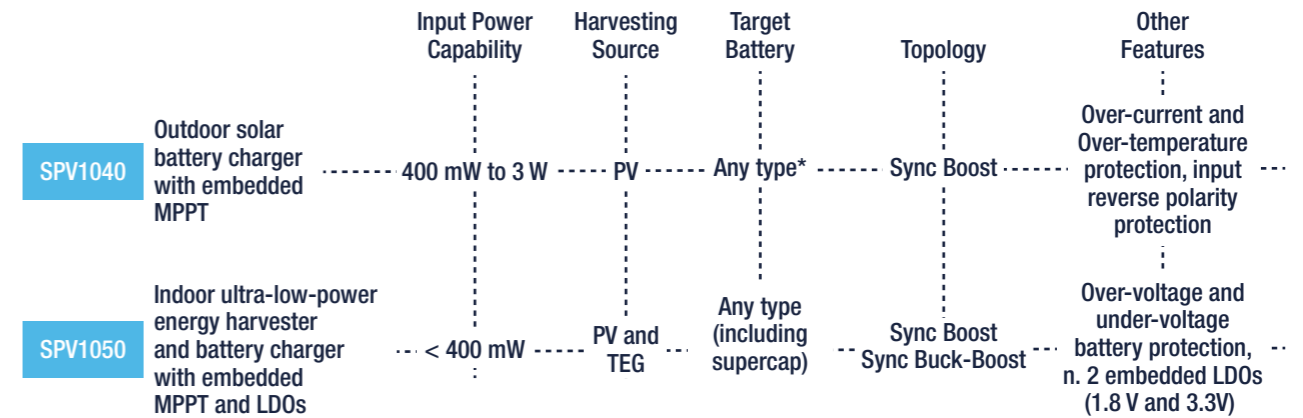
PHOTOVOLTAIC ICs

DC-DC converters with embedded MPPT algorithm

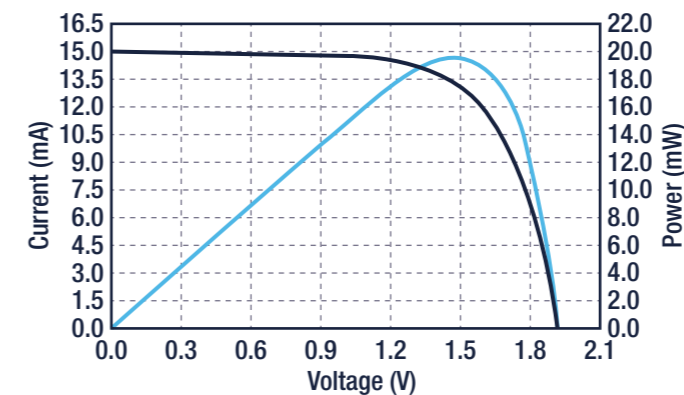
The maximum power point tracking (MPPT) algorithm maximizes the power output by photovoltaic panels according to temperature and solar irradiation conditions.

The SPV1040 is a monolithic DC-DC synchronous boost converter able to harvest the energy generated by even a single solar cell characterized by a very low output voltage. It is especially designed to work in outdoor environments with loads up to about 3 W.

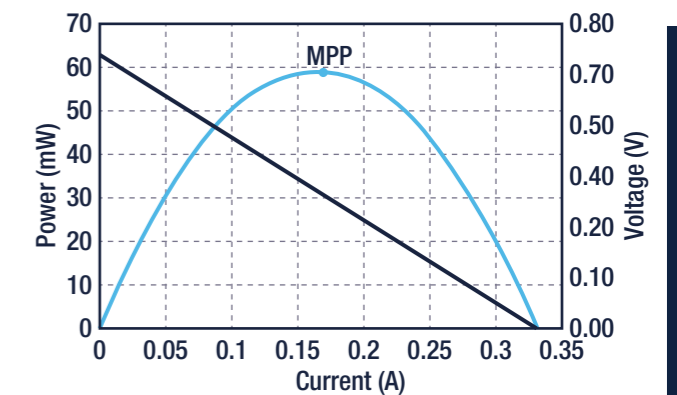
The SPV1050 is an ultra-low-power battery charger and energy harvester (from photovoltaic cells or thermo-electric generators) that guarantees a very fast charge of supercapacitors and any type of battery, including thin-film solid-state batteries. It is specifically designed to work in indoor environments or with very small thermal gradients with loads up to about 350 mW.



Solar curves



Thermo-electric generator (TEG)



MAIN APPLICATIONS



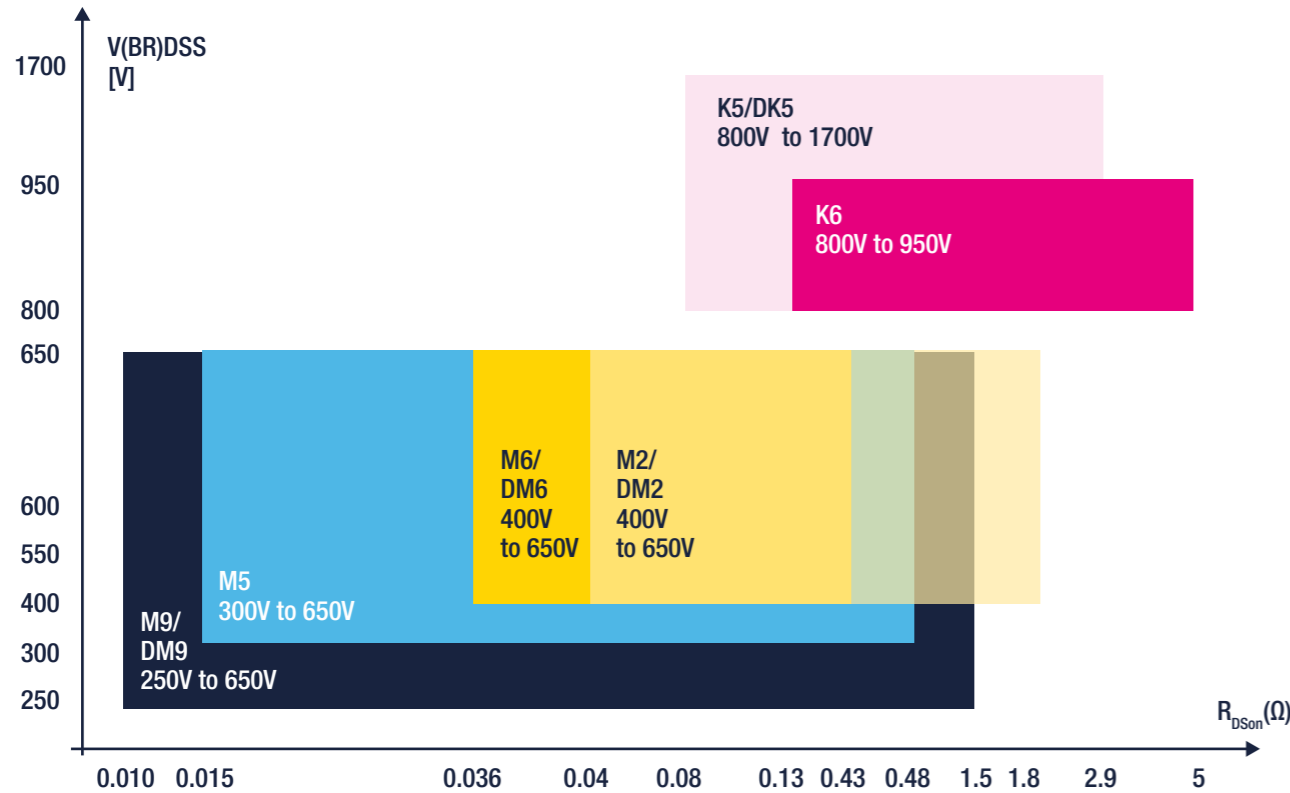
Note: * A CC-CV battery charger is needed to apply lithium batteries charging profile

www.st.com/photovoltaic-ics
www.st.com/mppt-dcdc-converters

POWER MOSFETs

High-voltage power MOSFETs

The ST HV Power MOSFETs portfolio offers a broad range of breakdown voltages from 250 to 1700 V with low gate charge and low on-resistance, combined with state-of-the-art packaging. The **MDmesh** high-voltage MOSFET technology has enhanced power-handling capability, resulting in high-efficiency solutions. Supporting applications for a wide voltage range, such as switch mode power supplies, lighting, DC-DC converters, motor control, and automotive applications, ST has the right Power MOSFET for your design.



M9 series

ST*N*M9

- Best Figure of Merit ($R_{DS(on)} \times Q_g$) on the market
- Industry's best $R_{DS(on)}$ for 650V voltage range
- Lowest Q_g
- Higher reverse diode dv/dt and MOSFET dv/dt ruggedness

M2/M2-EP series

ST*N*M2

ST*N*M2-EP

- Extremely low Q_g
- Optimized for light load conditions
- Tailored for high-frequency applications (M2-EP)
- Suited for hard switching & ZVS/LLC topologies

K5 & K6 series

ST*N*K5/6

- Very low $R_{DS(on)}$
- Small Q_g and capacitance
- Small packages
- Suited for hard switching topologies

M5 series

ST*N*M5

- Very low $R_{DS(on)}$
- High switching speed
- Suited for hard switching topologies

DM9 series

ST*N*DM9

- Best Figure of Merit ($R_{DS(on)} \times Q_g$) on the market
- Improved intrinsic diode reverse recovery time (trr)
- Higher dv/dt and di/dt capability
- Optimized body diode recovery phase and softness

DK5 series

ST*N*DK5

- Lowest trr @ Very High Voltage BVDSS
- High dv/dt capability
- Targeting high power 3-phases industrial equipment

M6 series

ST*N*M6

- Lower $R_{DS(on)} \times \text{area}$ vs previous generation
- Extremely low gate charge (Q_g)
- Optimized capacitances profile for better efficiency @ light load
- Optimized threshold voltage (VTH) and gate resistance (RG) values for soft switching

DM6/DM2 series

ST*N*DM6

ST*N*DM2

- Improved trr of intrinsic diode
- High dv/dt capability
- Suited for ZVS/LLC topologies

MAIN APPLICATIONS



Adapters
K5, M5, M2, M2-EP, M6



Solar inverters, EV Charging stations, Energy storage systems and UPS
K5, M5, DM2, DM6, DK5



Welding, residential, commercial and street lighting
K6, K5, DK5



5G Server/Telecoms
M9, M5, M6, M2, DM9, DM6, DM2

Note: * is used as a wildcard character for related part number

www.st.com/mosfet

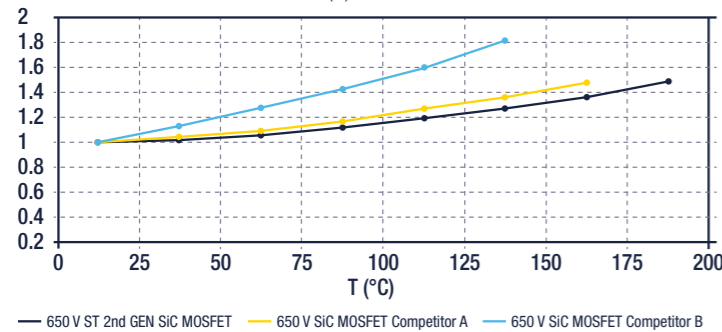
SiC MOSFETs

Based on the advanced and innovative properties of wide-bandgap materials, ST **silicon carbide (SiC) MOSFETs** feature very low $R_{DS(on)}$ per area for the 650 V/1200 V Gen2 and the new Gen3 product families, combined with excellent switching performance, translating into more efficient and compact designs.

ST is among the first companies to produce high-voltage SiC MOSFETs. These new families feature the industry's highest temperature rating of 200 °C for improved thermal design of power electronics systems.

Compared to silicon MOSFETs, SiC MOSFETs also feature significantly reduced switching losses and minimal variation with the temperature. These features render the device perfectly suitable for high-efficiency and high-power-density applications.

ST's SiC Mosfet 650 V - Normalized $R_{DS(on)}$ vs Temperature



SiC mosfets, the real breakthrough in high voltage switching

SCT*N120G2 SCT*N65G2 SCT*N170 SCT**65G3AG

- VBR = 1700 V (SCT*N170), 1200 V (SCT*N120G2), 650 V (SCT*N65G2), 650 V (SCT**65G3AG)
- Low power losses at high temperature
- High operating temperature capability (200 °C)
- Body diode with no recovery losses
- Low power losses at high temperatures
- Easy to drive
- Low gate charge (SCT*N65G2)



SIC MOSFETS MAIN BENEFITS

- Smaller form factor and higher power density
- Reduced size/cost of passive components
- Higher system efficiency
- Reduced cooling requirements and heatsink size

THROUGH-HOLE EXTENDED PACKAGE RANGE



SURFACE MOUNT EXTENDED PACKAGE RANGE



MAIN APPLICATIONS



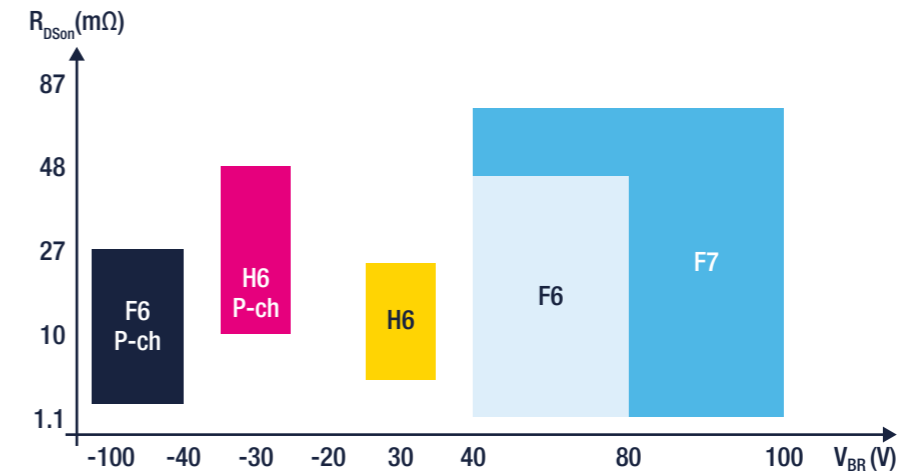
Note: * is used as a wildcard character for related part number

www.st.com/sicmos

Low-voltage power MOSFETs

ST **LV Power MOSFET** portfolio offers a broad range of breakdown voltages from -100 V to 100 V, with low gate charge and low on-resistance, combined with state-of-the-art packaging.

ST **STripFET** low-voltage MOSFETs support a wide voltage range for synchronous rectification, UPS, motor control, SMPS, power-over-Ethernet (PoE), inverter, automotive, and other applications in a wide range of miniature and high-power packages: DPAK, D2PAK, SOT-223, TO-220, TO-220FP, TO-247, PowerFLAT (5 x 6)/(3.3 x 3.3)/(2 x 2), SO-8 and SOT23-6L.



H6 series

ST*N*H6

- Very good $R_{DS(on)}$
- Soft diode recovery
- Suited for OR-ing, square-wave HB, battery management

F6 series

ST*N*F6

- Wide voltage range
- Soft diode recovery
- Very good $R_{DS(on)}$
- Suited for load-safety switch, buck and sync rectification

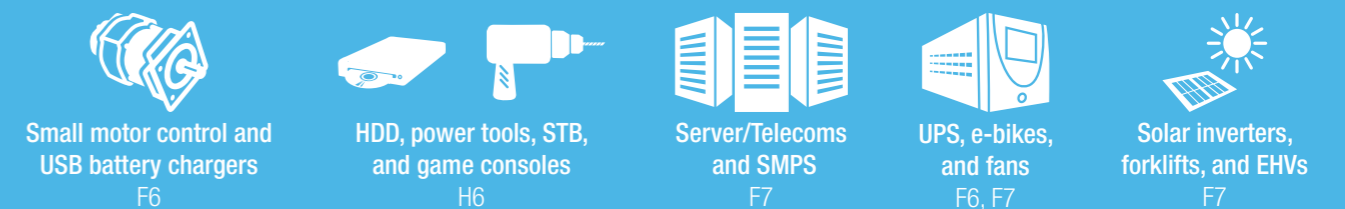
F7 series

ST*N*F7

- Extremely low $R_{DS(on)}$
- Optimized body diode (low Q_{rr}) and intrinsic capacitance for an excellent switching performance
- Proper C_{rss}/C_{iss} ratio for best-in-class EMI performance
- Outstanding performance for motor control and synchronous rectification



MAIN APPLICATIONS



Note: * is used as a wildcard character for related part number

www.st.com/mosfet

POWER MODULE – ACEPACK PACKAGES OPTIONS

ST ACEPACK power modules come with several topologies that address industrial applications such as motor drives, solar inverters, charging stations, UPS, welding tools, and power converter solutions, while they are also suitable for electric vehicle power applications like on-board chargers (OBC), electric traction drives, and power converter solutions.

These highly reliable and compact power modules feature an embedded NTC thermistor and offer the best compromise between conduction and switching losses, maximizing the efficiency of any converter system in hard-switching circuitries for an application range from few kW to hundreds of kW. For flexible and stable mounting, PressFIT and additional soldered pin options are provided. These power modules implement power semiconductor switches based on ST state-of-the-art SiC MOSFET and IGBT technologies.

ACEPACK 1

Up to 15 kW



ACEPACK 2

Up to 30 kW



KEY FEATURES

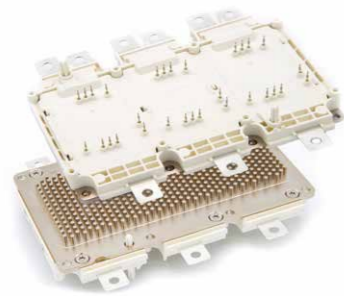
- Very low Stray inductance
- 2.5 kVrms electrical isolation
- Pin out flexibility
- Custom configurations
- Optimized thermal behavior
- Different DBC Options (AI203–AIN)
- Press-fit and solder pin options

CONFIGURATIONS

- CIB
- Six-pack
- Three level t-type
- Four Pack
- Half Bridge
- Boost
- Customized configurations

ACEPACK DRIVE

120 kW to 300 kW



KEY FEATURES

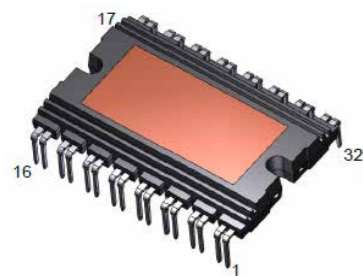
- AMB substrate for enhanced thermal dissipation
- 3 different bus bar configuration options
- Extremely low energies dissipation
- Direct Cooled Cu Base Plate with pin fins

CONFIGURATIONS

- Six-pack

ACEPACK DMT32

120 kW to 300 kW



KEY FEATURES

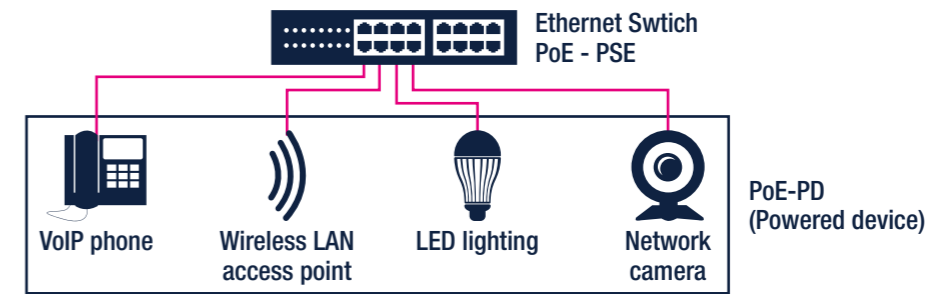
- Designed for automotive applications
- Different DBC Options (AI203–AIN)
- 2.5 kV insulation voltage
- 1200 V SiC MOSFET, Rectifiers
- Several configurations
- Integrated NTC temperature sensor

CONFIGURATIONS

- Six-pack
- Four Pack
- Customized configurations

POWER OVER ETHERNET ICs

Power over Ethernet (PoE) is a widely adopted technology used to transfer both data and electrical power over an RJ-45 cable. ST offers solutions for PoE applications on the powered devices (PD) side that integrate a standard Power over Ethernet (PoE) interface and a current mode PWM controller to simplify the design of the power supply sections of all powered devices. ST **PoE-PD ICs** are compliant with the more recent IEEE 802.3bt specification.



PoE-PD devices

PM8803

- IEEE 802.3at PD interface
- PWM current mode controller with double gate driver
- Integrated 100 V, 0.45 W, 1 A hot-swap MOSFET
- Supports flyback, forward active clamp, and flyback with synchronous rectification topologies

PM8800A

- IEEE 802.3af PD interface
- PWM current mode controller
- Integrated 100 V, 0.5 W, 800 mA hot-swap MOSFET
- Supports both isolated and non-isolated topologies

PM8804

- PWM current mode controller
- Double Gate Driver
- Support Isolated Active Forward Converter
- Input voltage up to 75 VDC
- Embedded start-up (20 mA)
- Slope compensation
- Programmable fixed frequency (up to 1 MHz)

PM8805

- IEEE 802.3bt PoE-PD interface
- System in Package
- Dual Active bridges
- HotSwap MOSFET
- Compact package (10 times smaller than discrete BOM) with high thermal performances
- 100 W capability

Main standards



Power over Ethernet power supply protection

PEP01-5841

- Power supply protection compliant with IEC61000-4-5 Level 2 : 1 kV
- Allow to use 100 V power Mosfet
- Stand off voltage: 58 V
- Surface mount SO-8 package

www.st.com/PoE

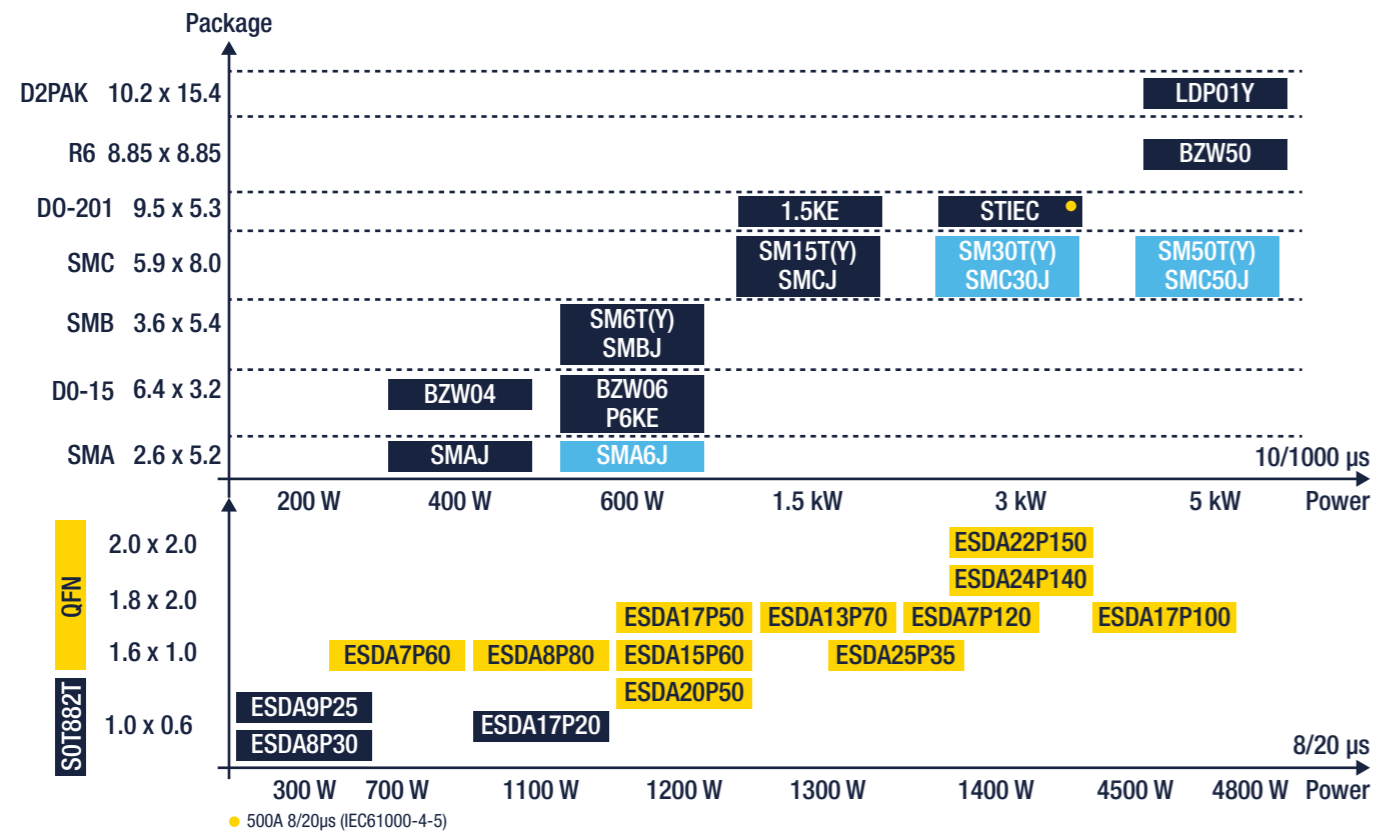


PROTECTION DEVICES

TVS

The **TVS Transient Voltage Suppressor** is an avalanche diode designed to clamp over-voltages and dissipate high transient energy. TVS are power devices to protect applications against Electrical Over-Stress (EOS), specifically against surge events as defined by IEC 61000-4-5.

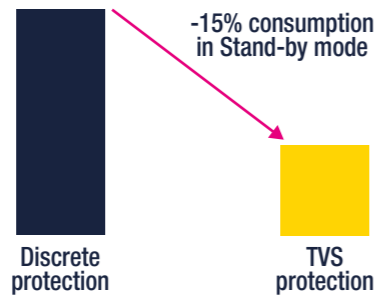
A large choice of package is available to meet application requirements.



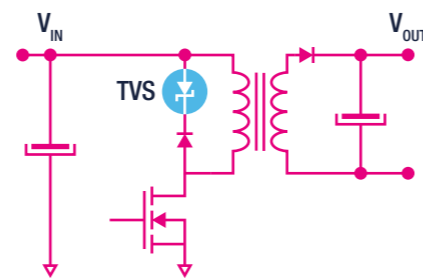
TVS Transil series against repetitive overvoltage in high temperature conditions

TVS

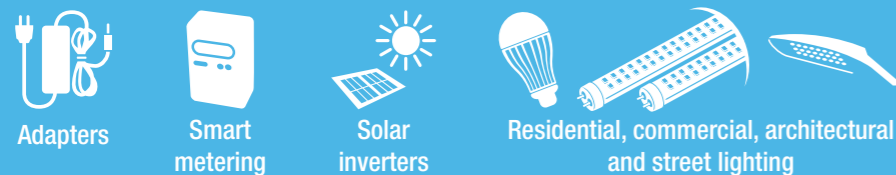
- Clamping voltage characteristics defined at 25 °C, 85 °C and 125 °C
- Stand-off voltage range: from 85 to 188 V
- Low leakage current: 0.2 µA at 25 °C
- Maximum operating junction temperatures:
 - SMB and SMC: 150 °C
 - DO-15 and DO-201: 175 °C



MOSFET Protection with TVS



MAIN APPLICATIONS

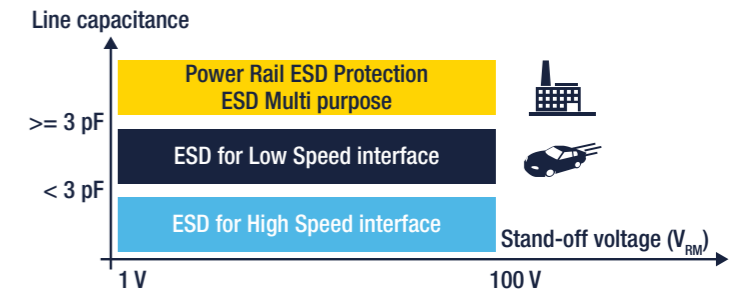


www.st.com/eos8-20-protection

ESD protection

Driven by market needs, ST **ESD protection** devices are available as single line devices for flexibility and multi-line arrays for integration in compact applications. All these devices are rated according to IEC 61000-4-2 and specific requirements, such as low capacitance and bandwidth for high speed lines.

A large choice of packages is available to meet application requirements.



Power delivery Protections

Ultimate TVS protection for USB fast-charging ports

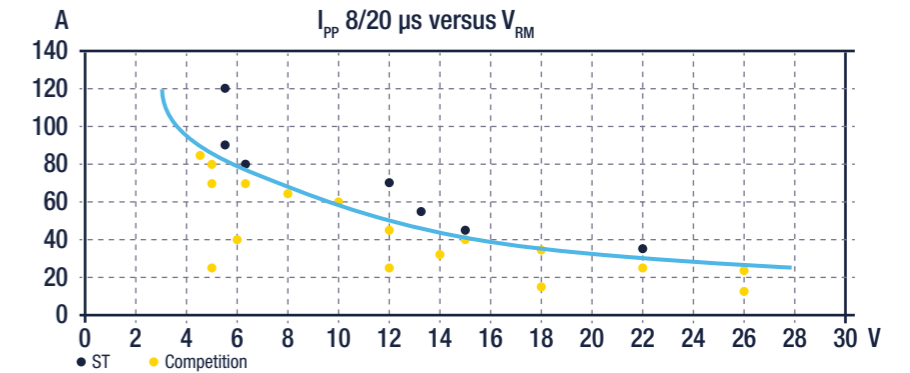
ESDAxxP

Strong and thin protection, the ESDAxxP series helps to stop damages due to the surge events

KEY FEATURES & BENEFITS

- Complete voltage range: 5 to 22 V
- High 8/20 µs surge protection capability from 25 to 160 A peak pulse current
- 4 small, thin packages:
 - ST1610x (1.6 x 1.0 mm)
 - QFN (2.0 x 1.8 mm)
 - QFN (2.0 x 2.0 mm)
 - SOD3882T (1.0 x 0.6 mm)
- High-power, miniature protection
- Saves PCB real-estate
- Highest peak pulse current in the market

Peak pulse current performance



Type	STM32	Pins	5 V - 15 W	9 - 27 W	15 - 45 W	20 V - 100 W
All	With or without STM32	D+/D-	ESDAXLC5-1U2	ESDAXLC5-1U2	ESDAXLC5-1U2	ESDAXLC5-1U2
		SSR/SSTx	ESDZX051-1BF4	ESDZX051-1BF4	ESDZX051-1BF4	ESDZX051-1BF4
		CC1/CC2	ESDZV5-1BF4	ESDALC14-1BF4	ESDZV18-1BF4	ESDZV201-1BF4 ESDL20-1BF4
		SBU1/SBU1	ESDA6V1L	ESDA14V2L	ESDA25L	ESDA25L
Sink	Yes	Vbus	ESDA7P60-1U1M ESDA7P120-1U1M ESDA8P30-1T2 ESDA8P80-1U1M ESDA9P25-1T2 SMAJ6.0A	ESDA13P70-1U1M ESDA15P60-1U1M SMAJ10A	ESDA17P20-1F2 ESDA17P50-1U1M ESDA17P100-1U2M SMAJ18A	ESDA22P150-1U3M ESDA24P140-1U3M ESDA25P35-1U1M SMAJ22A
		DRP	TCPP01-M12 TCPP02-M18 TCPP03-M20			

Note: 1 available in Q4 2021

MAIN APPLICATIONS

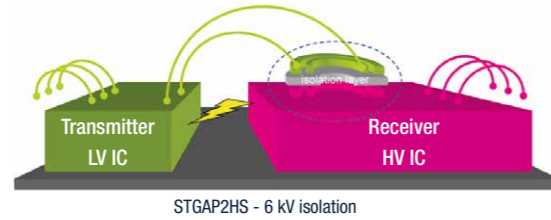


www.st.com/esd-protection

Note: * is used as a wildcard character for related part number

STDRIVE AND STGAP GATE DRIVERS

ST power MOSFETs and IGBTs gate drivers include integrated high-voltage half-bridge, single and multiple low-voltage gate drivers. Robustness and reliability, system integration and flexibility. The STGAP series of isolated gate drivers provides galvanic isolation between the input section, which connects to the control part of the system and the MOSFET or IGBT being driven.



Features ↑	L6389E	L6390	STDRIVE601 (3-Phase HV)	Features ↑	TD350E
	L6388E	L6392	L6491		TD352
	A/L6387E	L6391	L6494		TD351
	L6386E/AD	L6393	L6498		PM8851
	L6385E	L6395			PM8841
	L6384E	L6398			PM8834
	L6399				

Features ↑	STGAP2S
	STGAP2D
	STGAP2HS
	STGAP2SiCSN
	STGAP2SiCS
	STGAP2HD
	STGAP2SiCD
STGAP1BS	

600 V gate drivers

Half bridge

- 4 A source/sink driver high current capability (L6491)
- Integrated bootstrap diode
- Adjustable deadtime (L6494L)
- Comparator, op amp integrated, smart SD, interlocking and program. DT (L6390)
- Extended temperature range (A version)

3-Phase

- Best In Class for propagation delay 85 ns
- 200 mA/350 mA sink / source driver current capability
- Integrated bootstrap diode

Low side gate drivers

- 2 level turn-off (TD35*)
- Miller clamp (TD35*)
- Pulse trans / opto input (TD35*)
- Dual independent low side driver (PM8834)
- 4 A source/sink driver high current capability (PM8834)



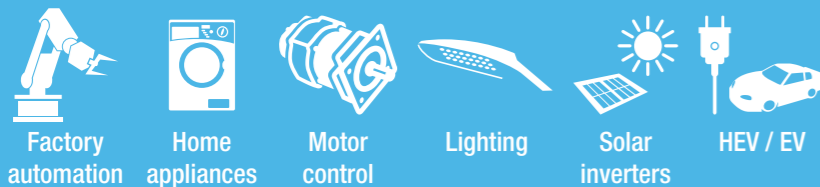
Galvanically-isolated single and dual gate drivers

- Up to 6 kV isolation (STGAP2HS)
- High voltage rail up to 1.7 kV
- Up to 5 A source/sink driver current capability
- 2 Level turn-off (STGAP1B)
- Miller clamp, negative gate supply
- Optimized for SiC MOSFET driving (STGAP2SiCS)

STDRIVEG600 - High voltage half-bridge gate driver for GaN transistors

- dV/dt immunity ± 200 V/ns
- Driver current capability:
 - 1.3/2.4 A source/sink typ @ 25 °C, 6 V
 - 5.5/6 A source/sink typ @ 25 °C, 15 V
- Separated turn on and turn off gate driver pins
- 45 ns propagation delay with tight matching
- 3.3 V, 5 V TTL/CMOS inputs with hysteresis
- Interlocking function
- UVLO on low-side and high-side sections

MAIN APPLICATIONS



www.st.com/stdrive



THYRISTORS

Available in through-hole and surface-mount packages, ST **high-temperature Silicon Controlled Rectifiers SCR** provide designers with more headroom for heatsink reduction or more compactness. In addition, the voltage surge immunity is fully specified at 150 °C, ensuring designs are precise and secure. These 12 - 80 A SCRs are ideal for use in charging stations, solid-state relays, inrush current limiters, motor starters, SMPS, UPS, and renewable-energy junction boxes. The 1200 V automotive-grade thyristor makes AC/DC converters safe by limiting the inrush current and providing insulation against AC line over-voltages.



Automotive Grade SCR AECQ101 qualified

TN3050H-12
30 A, 1200 V

TN4050H-12
40 A, 1200 V

TN6050HP-12
60 A, 1200 V

Medium Power SCR

TN4050-12
50 A, 1200 V

TN6050-12
50 A, 1200 V

TM8050H-8
80 A, 800 V

High Temperature SCR

TN1205H-6
12 A, 600 V

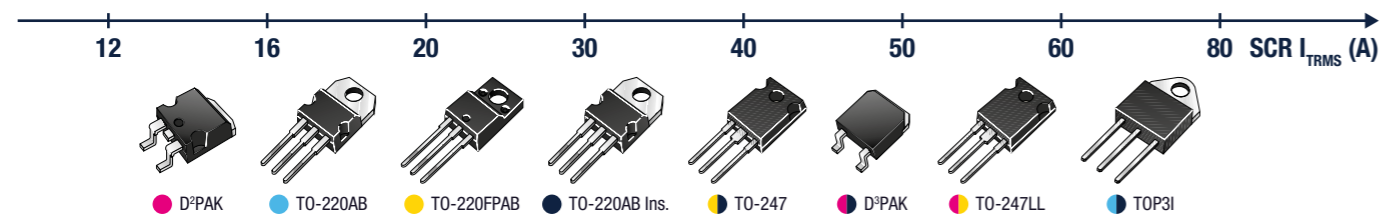
TN1605H-6
12 A, 600 V

TN2010H-6
20 A, 600 V

TN3015H-6
30 A, 600 V

TN4015H-6
40 A, 600 V

TN5015H-6
50 A, 600 V



MAIN APPLICATIONS



1200 V High Temperature SCRs are now available in Surface Mount packages with top-cooled capability. In discrete package with HU3PAK or in module integration with ACEPACK SMIT package, these products are suitable in all bridge or bridgeless AC/DC converter topologies, where compactness and thermal performances are optimized. Thanks to 150 °C maximum junction temperature, the **1200 V High Temperature SCRs** are suitable for industrial and automotive applications in harsh environments.



Optimized for Industrial, Building and Residential appliances and based on ST new high temperature technology, our 800 V **8H Triacs** can work at 150 °C without compromise. Enabling designers to maximize current density or reduce the heatsink size by up to 50%, these triacs are the right choice to run in very hot, confined environments and improve the reliability of systems such as light control, compact heaters, starters or solid-state relays.

Part number	Package			I_T (RMS) A max	T_J °C max	V_{DRM}/V_{RRM} V max	I_{GT} mA max	I_{TSM} A max	dV/dt V/ μ s @ 150 °C min	$(di/dt)_c$ A/ms @ 10 V/ μ s, @ 150 °C min
	TO-220AB	TO-220AB Ins.	D²PAK							
T835H-8	T	I	G	8	150	800	35	80	2000	8
T1235H-8	T	I	G	12				120		12
T1635H-8	T	I	G	16				160		16
T2035H-8	T		G	20				200		20
T3035H-8	T	I	G	30				270		25

MAIN APPLICATIONS



USB TYPE-C® AND POWER DELIVERY CONTROLLERS

With an extensive technology and IPs portfolio, ST provide a range of **USB-IF certified solutions for USB Type-C and Power Delivery** to support implementations in a variety of sink, source, and dual role devices. From USB Type-C interfaces and PD Controllers to Authentication, ST complements the portfolio with Power Management ICs, full range of **protection** for data, and power line protection. ST solutions range from **Type-C port interface ICs** to **USB PD controllers** and offer wide flexibility with hard wired and MCUs to fit different use cases and all power ratings.



Standalone solutions

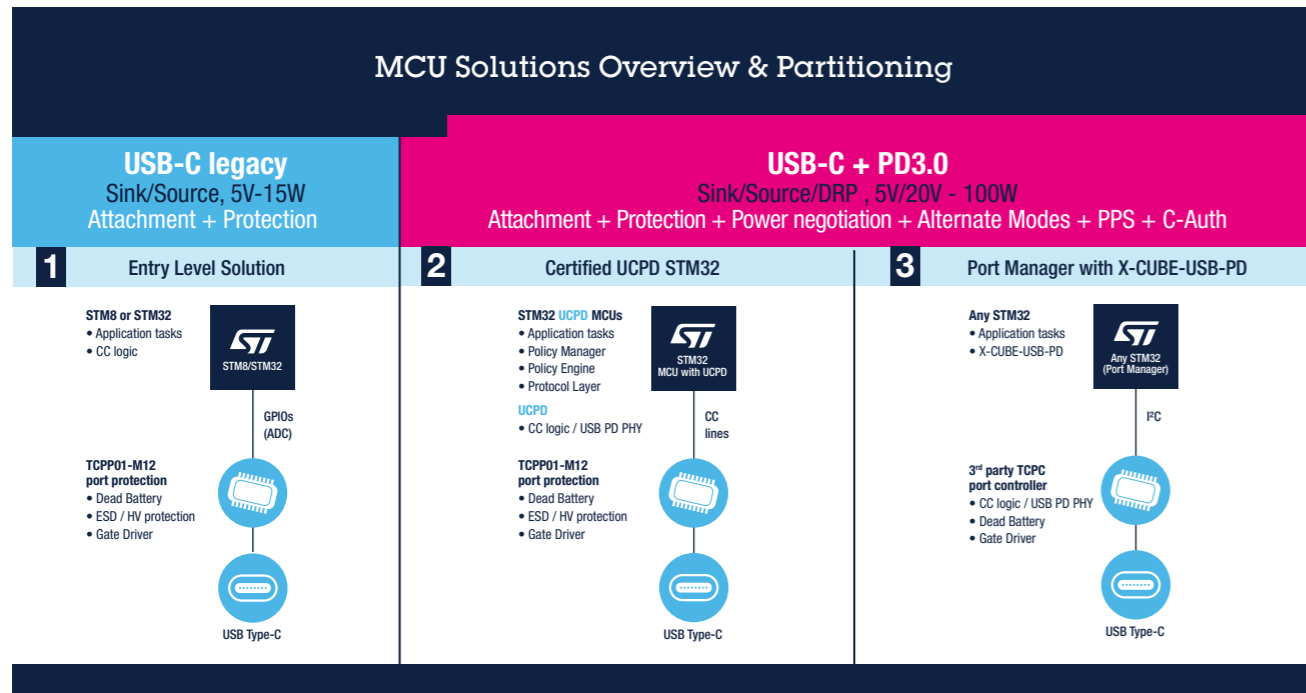
STUSB controllers cover power path applications with optimized partitioning from USB Type-C® Interface for 15 W device to Power Delivery PHY and BMC Driver IC companion chip of STM32-based solutions to standalone full hardware USB PD controller optimized for AC adapters up to 100 W.

MCU-based solutions

Our STM32 solutions help you manage the complexity of implementing USB Type-C® and Power Delivery technology to ensure that your embedded application supports the latest use cases. The ST ecosystem for USB Type-C reduces the acquisition cost of a technology that requires multiple areas of expertise, such as connectivity, power management, data communication, and authentication.

Combining middleware, configuration, and debugging tools, as well as hardware development platforms, our MCU-based solutions are specifically designed to address this challenge and offer high flexibility to implement USB Type-C and Power Delivery (PD).

A companion Type-C Port Protection device **TCPP01-M12** is proposed for advanced protection of the USB-C connector line in sink applications, such as CC and Vbus line. For source applications like power adapters, **TCPP02-M18** is recommended (mass-production Q4-2020). For Dual Role Port applications (DRP), **TCPP03-M20** is recommended (mass-production Q4-2020).



STM32 USB PD3.0 controllers

Introduced in December 2017, **STM32G0** is the world's 1st standard USB PD 3.0 microcontroller with a UCPD interface (UCPD stands for USB Type-C and Power Delivery). This new IP, available in **STM32G0/G4/L5 series**, allows development of USB-C sink, source and dual role devices in a wide range of embedded applications.

UCPD-enabled STM32G0/G4/L5 provides a high flexibility to migrate embedded applications to USB-C and Power Delivery technology, while managing other application environments thanks to the versatile feature set and peripherals available in a traditional MCU. UCPD is certified PD3.0 and supports all new features such as C-Authentication and Programming Power Supply (PPS).

https://www.st.com/content/st_com/en/stm32-usb-c.html

STM32G081 block diagram



UCPD is a new interface that supports:

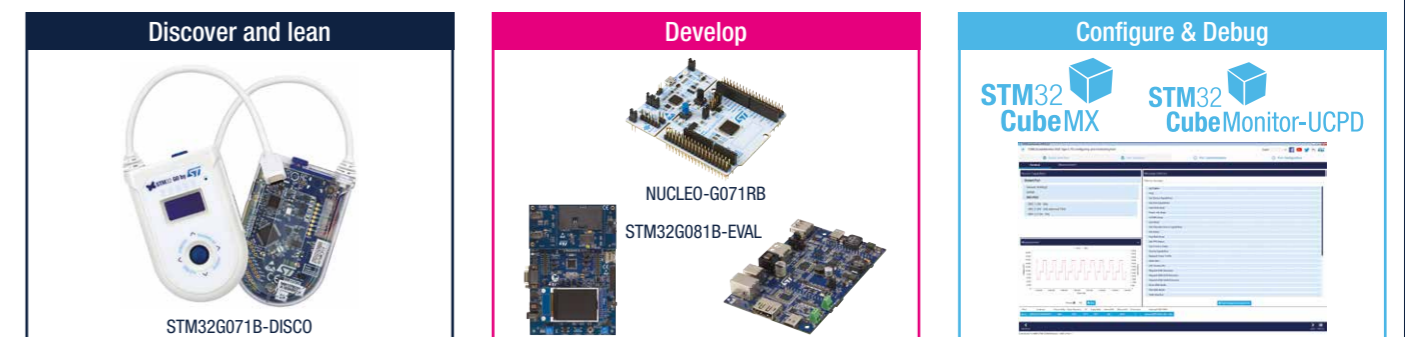
- USB Type-C connector management
- USB Power Delivery 3.0 communication protocol including C-authentication and Programming Power Supply

STM32G0 USB-C Ecosystem: for short time-to-market

Our STM32G071B-DISCO kit enables discovery and display of USB-C power and feature capabilities of any USB-C compliant host. Associated with our professional-grade STM32CubeMonitor-UCPD software GUI, the kit acts as a USB PD analyzer and allows customers to debug, configure, and inject USB PD3.0 packets in a single click while monitoring Vbus voltage and Ibus current between two USB-C devices.

Our well-known STM32 configurator STM32CubeMx supports easy setting of UCPD.

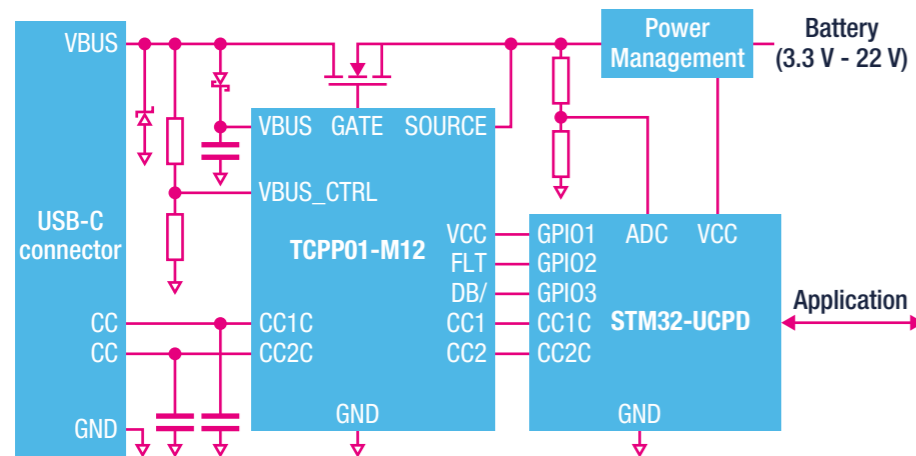
An STM32G081B-eval evaluation board is proposed with two USB-C ports offering 45 W of power with different profiles.



Type-C Port Protection

TCPP01-M12

The **TCPP01-M12** (type-C port protection) is a single chip solution for USB type-C port protection that facilitates the migration from USB legacy connectors type-A or type-B to USB type-C connectors. The TCPP01-M12 features 22 V tolerant ESD protection as per IEC61000-4-2 Level 4 on USB type-C connector communication channel (CC) and VBUS lines. To allow fast certification for USB Power Delivery, the TCPP01-M12 provides overvoltage protection on CC1 and CC2 pins when these pins are subjected to short-circuits with the VBUS pin, which may occur when removing the USB Type-C cable from its receptacle. For sink applications, TCPP01-M12 triggers an externally programmable N-MOSFET overvoltage protection on VBUS pin when a defective power source applies a voltage higher than selected OVP threshold. Also, the TCPP01-M12 integrates a “dead battery” management logic that is compliant with the USB Power Delivery specification. The VBUS N-MOSFET load driver can also be used in source applications.



KEY FEATURES

- ESD protection for CC1, CC2 and VBUS
- Compliant with IEC 61000-4-2 Level 4 (± 8 kV contact discharge, ± 15 kV air discharge)
- Over Voltage Protection on CC lines against short-to-VBUS overvoltage
- Externally programmable Over Voltage Protection on VBUS line
- Integrated VBUS gate driver for external N-MOSFET
- Over Temperature Protection
- Integrated “Dead Battery” management
- Open-drain fault reporting
- Operating junction temperature from -40 °C to 85 °C
- ECOPACK®2 compliant

TCPP03-M20

DRD or DRP applications require careful protection implementation both on the sink power path and the source power path to safely comply with the USB-C Power Delivery specification. **TCPP03-M20** is an MCU companion chip enabling cost-effective USB-C Power Delivery DRD/DRP implementation. It provides protections and functionalities to safely comply with the USB-C Power Delivery specification.

The device drives external N-MOSFETs on VBUS connector pin in the source and sink power path for over-voltage and over-current protection. It provides an analog current sense output accessible for an MCU ADC, thus minimizing system cost.

TCPP03-M20 helps minimize power consumption during DRP toggling states thanks to its three programmable power modes, allowing a power consumption as low as $3 \mu\text{A}$ maximum up to 125 °C, also thanks to enable pin that wakes up the MCU.

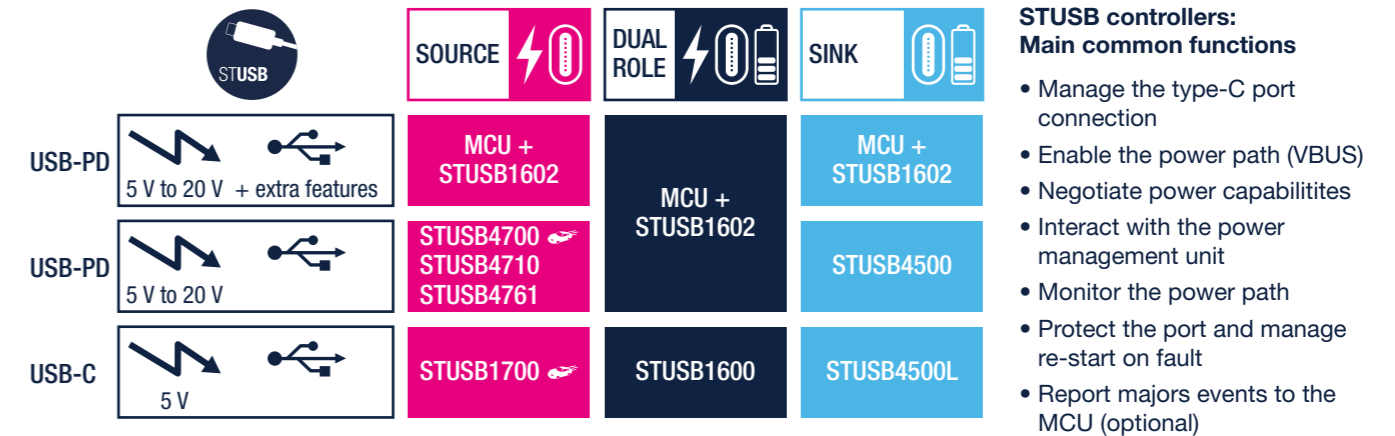
KEY FEATURES

- Externally programmable VBUS OVP (over voltage protection) and OCP (over current protection) for provider and consumer power paths with fast turn-off
- Two integrated N-MOSFETs gate drivers for VBUS OVP and OCP
- Very low power in “unattached” state during DRP toggling: $3 \mu\text{A}$ max. at 125 °C
- Compliant with PPS (programmable power supply) for fast charging, up to 100 W
- Integrated discharge on VBUS and VCONN
- Current sense on VBUS with analog output
- ESD protection for CC1, CC2, compliant with IEC 61000-4-2 Level 4 (± 8 kV contact discharge, ± 15 kV air discharge)
- VCONN OCP and OVP
- Over voltage protection on CC lines against short-to-VBUS
- Over temperature protection (150 °C typ.)



STUSB family of standalone (auto-run) USB-C and Power Delivery controllers

Being designed with ST 20 V process technology, the **STUSB family** is natively compliant with USB PD electrical requirements. STUSB controller ICs are certified and integrate the mandatory protection and application features for autonomous port management, without the need for external circuitry. STUSB controllers are optimized for power path applications ranging from 15 to 100 W, on both SINK and SOURCE sides. Being hardwired, STUSB controllers are fast and predictive to guarantee safety and interoperability, while increasing port robustness and minimizing power consumption. Implementation is fast and easy and requires no deep knowledge of the USB PD standard or advanced software skills. Standalone controllers are powered from VBUS to minimize BOM cost and can fully operate without external MCU support. For more flexibility, an MCU can optionally change main power parameters or read port status with a light software layer.



STUSB47xx

- USB PD SOURCE
- Up to 5 programmable PDOs
- Full hardware solution - no software
- Internal and/or external VBUS discharge path
- Very low power consumption
- E-marked cable identification (for >3 A support)
- Over-temperature protection

STUSB1700

- USB-C 5V SOURCE
- High Voltage protections
- GPIO-controlled current profile (Power sharing, Thermal protection)
- VBUS powered (no LDO needed)
- AEC-Q100 available

STUSB1602

- USB PD SOURCE/SINK/DUAL ROLE
- Perfect MCU companion chip ensuring port protection, power path monitoring and management, role advertisement and detection, PD PHY communication
- Ready-to-use software frameworks for fast prototyping of most common application scenario such as: basic source, sink, DRP, dual port, but also more complex use cases, which include optional features of PD3.0, vendor defined, battery or extended messages.

MCU supported:

- STSW-STUSB010: STM32F072
- STSW-STUSB012: STM32F446
- STSW-STUSB014: STM32G474
- STSW-STUSB015: STM32L4R5

STUSB1600

- USB-C 5V SOURCE/SINK/DUAL ROLE
- High Voltage protections
- Integrated VBUS discharge
- Dead battery support
- Optional interface to MCU (I^2C + IRQ)

STUSB4500

- USB PD SINK
- Dead Battery support
- VBUS powered (ZERO power on VBAT)
- Input Over Voltage protection
- QFN and CSP package available
- SOURCE power profile reporting
- STSW-STUSB002: GUI
- STSW-STUSB003: optional open source software drivers for dynamic power Management
- Mini-dongle: EVAL-SCS001V1

STUSB4500L

- USB-C 5V SINK
- Dead battery support
- VBUS powered (ZERO power on VBAT)
- Input Over Voltage protection
- SOURCE power budget reporting
- QFN and CSP package available
- Mini-dongle: EVAL-SCS002V1

life.augmented



Order code: **BR2211PMGUIDE**

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